











TPS53681

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TPS53681 Dual-Channel (6-Phase + 2-Phase) or (5-Phase + 3-Phase) D-CAP+™ Step-Down Multiphase Controller with NVM and PMBus™

Features

- Conversion Input Voltage Range: 4.5 V to 17 V
- 8-Bit DAC with Selectable 5 mV or 10 mV Resolution and Output Ranges from 0.25 V to 1.52 V or 0.5 to 2.8125 V for Dual Channels
- Phase Configurations
 - Maximum (6-Phase + 2-Phase) or (5-Phase +
 - Minimum (1-Phase + 1-Phase)
- Driverless Configuration for Efficient High-Frequency Switching
- Dynamic Output Voltage Transitions with Programmable Slew Rates via PMBus Interface
- Frequency Selections with Closed-loop Frequency Control: 300 kHz to 1 MHz
- Programmable Internal Loop Compensations
- Configurable with Non-Volatile Memory (NVM) for Low External Component Counts
- Individual Phase Current Calibrations and Reports
- Dynamic Phase Shedding with Programmable Current Threshold for Optimizing Efficiency at Light and Heavy Loads
- Fast Phase-Adding for Undershoot Reduction (USR)
- Fully Compatible with TI NextFET™ Power Stage for High-Density Solutions
- Accurate, Adjustable Voltage Positioning
- Patented AutoBalance™ Phase Balancing
- Selectable, 16-level Per-Phase Current Limit
- PMBus™ System Interface for Telemetry of Voltage, Current, Power, Temperature, and Fault Conditions
- Low Quiescent Current
- 5 mm x 5 mm, 40-Pin, QFN PowerPad™ Package

2 Applications

- ASIC Needs Dual Power Rails
- High-Performance Processor Power
- Networking Processor Power (Broadcom[®], Cavium®)
- High-Current FPGA Power (Intel®, Xilinx®)
- High-Performance ARM Processor Power

3 Description

The TPS53681 is a multiphase step-down controller with dual channels, built-in non-volatile memory (NVM), and PMBus™ interface, and is fully compatible with TI NexFET ™power stage. Advanced control features such as D-CAP+™ architecture with undershoot reduction (USR) provide fast transient response, low output capacitance, and efficiency. The device also provides novel phase interleaving strategy and dynamic phase shedding for efficiency improvement at different loads. The device supports fast dynamic voltage transitions with adjustable slew rate. In addition, the device supports the PMBus communication interface for reporting the telemetry of voltage, current, power, temperature, and fault conditions to the systems. All programmable parameters can be configured by the PMBus interface and can be stored in NVM as the new default values to minimize the external component count.

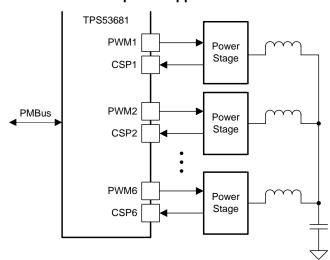
The TPS53681 device is offered in a thermally enhanced 40-pin QFN packaged and is rated to operate from -40°C to 125°C.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|----------|-----------------|
| TPS53681 | QFN (40) | 5 mm × 5 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Application



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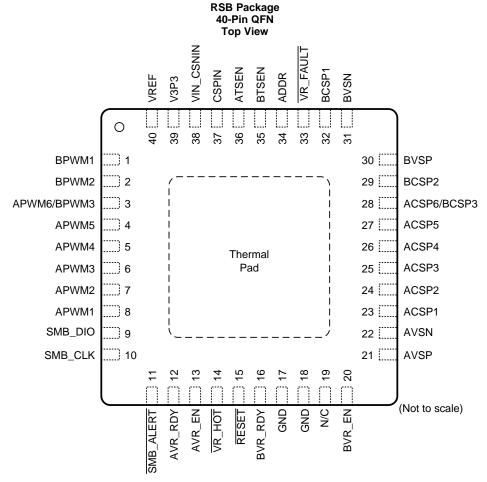
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| DATE | REVISION | NOTES | | |
|-----------|----------|------------------|--|--|
| June 2017 | * | Initial release. | | |

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5 Pin Configuration and Functions



Thermal pad acts as AGND. NC = not connected

Pin Functions

| PIN | | I/O ⁽¹⁾ | DESCRIPTION | | |
|-------------|-----|---|---|--|--|
| NAME | NO. | 1/0 | DESCRIPTION | | |
| ACSP1 | 23 | | | | |
| ACSP2 | 24 | | Current sense input for the channel A. Connect to the IOUT pin of TI smart power stages. Tie the | | |
| ACSP3 25 | | ACSP5, ACSP4, ACSP3, or ACSP2 pin to the V3P3 pin according to Table 1 to disable the | | | |
| ACSP4 | 26 | 1 | corresponding phase. | | |
| ACSP5 | 27 | | | | |
| ACSP6/BCSP3 | 28 | | Current sense inputs for channel A or channel B based on NVM option. Connect to the IOUT pin of smart power stages. Tie ACSP6/BCSP3 to the 3.3-V supply to disable corresponding phase. | | |
| ADDR | 34 | I | Voltage divider to VREF and GND. The voltage level sets the 7-bit PMBus address with an ADC. Address is latched at 3.3-V power up. | | |
| APWM1 | 8 | 0 | PWM signal for phase 1 of channel A. | | |
| APWM2 | 7 | 0 | PWM signal for phase 2 of channel A. | | |
| APWM3 | 6 | 0 | PWM signal for phase 3 of channel A. | | |
| APWM4 | 5 | 0 | PWM signal for phase 4 of channel A. | | |
| APWM5 | 4 | 0 | PWM signal for phase 5 of channel A. | | |

(1) G = ground, I = input, O = output, P = power input

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Pin Functions (continued)

| PIN | | | I in i diletions (continued) | | |
|-------------|----------|--------------------|---|--|--|
| NAME | NO. | I/O ⁽¹⁾ | DESCRIPTION | | |
| APWM6/BPWM3 | 3 | 0 | PWM signal for phase 6 of channel A, or phase 3 of channel B, based on the NVM option. | | |
| ATSEN | 36 | 0 | Connect to TAO pin of TI smart power stages of Channel A to sense the highest temperature of the power stages and to sense the build-in fault signal from power stages | | |
| AVR_EN | 13 | I | Active high enable input for channel A. Asserting the AVR_EN pin activates channel A. | | |
| AVR_RDY | 12 | 0 | Power good open-drain output signal of channel A. This open drain output requires an external pull-up resistor. The AVR_RDY pin is pulled low when a shutdown fault occurs. | | |
| AVSN | 22 | I | Negative input of the remote voltage sense of channel A. | | |
| AVSP | 21 | I | Positive input of the remote voltage sense of channel A. | | |
| BCSP1 | 32 | I | Current sense input for channel B. Connect to the IOUT pins of TI smart power stages. If channel B is not used, then connect the BCSP1 pin to GND. | | |
| BCSP2 | 29 | I | Current sense input for channel B. Connect to the IOUT pins of TI smart power stages. Tie the BCSP2 pin to the V3P3 pin according to Table 1 to disable the corresponding phase. | | |
| BPWM1 | 1 | 0 | PWM signal for phase 1 of channel B | | |
| BPWM2 | 2 | 0 | PWM signal for phase 2of channel B | | |
| BTSEN | 35 | 0 | Connect to TAO pin of TI smart power stages of Channel B to sense the highest temperature of the power stages and to sense the build-in fault signal from power stages | | |
| BVR_EN | 20 | I | Active high enable input for channel B. Asserting the BVR_EN pin activates channel B. Re-cycling BVR_EN pin clears the faults of channel B. | | |
| BVR_RDY | 16 | 0 | Power good open-drain output signal of channel B. This open drain output requires an external pull-up resistor. BVR_RDY is pulled low when a shutdown fault occurs. | | |
| BVSN | 31 | I | Negative input of the remote voltage sense of channel B. If channel B is not used, connect BVSN to GND. | | |
| BVSP | 30 | I | Positive input of the remote voltage sense of channel B. If channel B is not used, connect BVSP to GND. | | |
| CSPIN | 37 | I | Input voltage from the positive terminal connecting to the input current sensing shunt. When input current sensing is not used, short CSPIN to VIN_CSNIN and connect to the converter input voltage (example: 12 V). | | |
| GND | 17 18 | G | Connect to GND | | |
| NC | 19 | _ | No connection. | | |
| RESET | 15 | I/O | Resets the output voltage to BOOT voltage | | |
| SMB_ALERT | 11 | I/O | SMBus or I ² C bi-directional ALERT pin interface. (Open drain) | | |
| SMB_CLK | 10 | I | SMBus or I ² C serial clock interface. (Open drain) | | |
| SMB_DIO | 9 | I/O | SMBus or I ² C bi-directional serial data interface. (Open drain) | | |
| V3P3 | 39 | Р | 3.3-V power input. Bypass to GND with a ceramic capacitor with a value greater than or equal to 1 μ F. Used to power all digital logic circuits. | | |
| VIN_CSNIN | 38 | Р | Input voltage sensing for on-time control and telemetry. Serves as the negative terminal connecting to the input current sensing shunt. When input current sensing is not used, short VIN_CSNIN to CSPIN and connect to the converter input voltage (example: 12 V). | | |
| VR_FAULT | 33 | 0 | VR fault indicator. (Open-drain). The failures include the high-side FETs short, over-voltage, over-temperature, and the input over-current conditions. Use the fault signal on the platform to remove the power source by turning off the AC power supply. When the failure occurs, the VR_FAULT pin is LOW, and put the controller into latch-off mode. One NVM bit is used to select whether or not the faults from channel B asserts the VR_FAULT. pin. | | |
| VREF | 40 | 0 | 1.7-V LDO reference voltage. Bypass to GND with 1-µF ceramic capacitor. Connect the VREF pin to the REFIN pin of the TI smart power stages as the current sense common-mode voltage. | | |
| VR_HOT | 14 | 0 | Active low external temperature indicator. | | |
| Thermal Pad | | G | Analog ground pad. Connect to GND plan with vias. | | |



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Table 1. Current Sense Inputs for Active Phases

| Active Phase Channel | | ACSP1 | ACSP2 | ACSP3 | ACSP4 | ACSP5 | ACSP6 | BSCP1 | BSCP2 |
|----------------------------|---|--------|--------|--------|--------|--------|--------|--------|--------|
| Α | В | | | | | | | | |
| 1 | 0 | AIOUT1 | V3P3 | n/a | n/a | n/a | n/a | GND | V3P3 |
| 2 | 1 | AIOUT1 | AIOUT2 | V3P3 | n/a | n/a | n/a | BIOUT1 | V3P3 |
| 3 | 1 | AIOUT1 | AIOUT2 | AIOUT3 | V3P3 | n/a | n/a | BIOUT1 | V3P3 |
| 4 | 1 | AIOUT1 | AIOUT2 | AIOUT3 | AIOUT4 | V3P3 | n/a | BIOUT1 | V3P3 |
| 5 | 1 | AIOUT1 | AIOUT2 | AIOUT3 | AIOUT4 | AIOUT5 | V3P3 | BIOUT1 | V3P3 |
| 6 ⁽¹⁾ | 1 | AIOUT1 | AIOUT2 | AIOUT3 | AIOUT4 | AIOUT5 | AIOUT6 | BIOUT1 | V3P3 |
| 6 | 2 | AIOUT1 | AIOUT2 | AIOUT3 | AIOUT4 | AIOUT5 | AIOUT6 | BIOUT1 | BIOUT2 |
| 5 | 2 | AIOUT1 | AIOUT2 | AIOUT3 | AIOUT4 | AIOUT5 | V3P3 | BIOUT1 | BIOUT2 |
| 5 ⁽¹⁾ | 3 | AIOUT1 | AIOUT2 | AIOUT3 | AIOUT4 | AIOUT5 | BIOUT3 | BIOUT1 | BIOUT2 |

⁽¹⁾ For *n*+1 or *n*+3 applications, the NVM setting must be changed. See also the *Phase Configuration for Channel B* section.

TEXAS INSTRUMENTS

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|---------------------------------------|---|------|-----|------|
| | CSPIN, VIN_CSNIN | -0.3 | 19 | ٧ |
| Input voltage (1) (2) | ACSP1, ACSP2, ACSP3, ACSP4, ACSP5, ACSP6/BCSP3, ADDR, ATSEN, AVR_EN, AVSP, BCSP1, BCSP2, BTSEN, BVR_EN, BVSP, RESET, SMB_CLK, SMB_DIO, V3P3 | -0.3 | 3.6 | ٧ |
| | AGND, AVSN, BVSN | -0.3 | 0.3 | ٧ |
| Output voltage (1) (2) | APWM1, APWM2, APWM3, APWM4, APWM5, APWM6/BPWM3, BPWM2, AVR_RDY, BPWM1, BVR_RDY, SMB_ALERT, VREF, VR_FAULT, VR_HOT | -0.3 | 3.6 | V |
| Operating junction tem | perating junction temperature, T _J | | 150 | Ô |
| Storage temperature, T _{STG} | | -55 | 150 | Ô |

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the network ground terminal GND unless otherwise noted.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|----------------------------|---|-------|------|
| | Floatrootatio | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±3000 | |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 (2) | ±1500 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

| | | MIN | NOM | MAX | UNIT |
|---------------------|---|--|-----|------|------|
| | CSPIN, VIN_CSNIN | 4.5 | 12 | 17 | |
| | V3P3 | 2.97 | 3.3 | 3.5 | |
| Input voltage | ACSP1, ACSP2, ACSP3, ACSP4, ACSP5, ACSP6/BSCP3, ADDR, ATSEN, AVR_EN, AVSP, BCSP1, BCSP2, BTSEN, BVR_EN, BVSP, RESET, SMB_CLK, SMB_DIO, V3P3 | -0.1 | | 3.5 | V |
| | AGND, AVSN, BVSN | -0.1 | | 0.1 | |
| | VREF | -0.1 | | 1.72 | |
| Output voltage | APWM1, APWM2, APWM3, APWM4, APWM5, APWM6/BPWM3, BPWM2, AVR_RDY, BPWM1, BVR_RDY, SMB_ALERT, VREF, VR_FAULT, VR_HOT | 2.97 3.3 3.5 SCP3, ADDR, VR_EN, BVSP, —0.1 3.5 —0.1 0.1 —0.1 1.72 M6/BPWM3, RT, VREF, —0.1 3.5 | V | | |
| Ambient temperature | e, T _A | -40 | | 125 | °C |

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information

| | | TPS53681 | |
|-----------------------|--|--|------|
| | THERMAL METRIC ⁽¹⁾ | TPS53681 RSB (WQFN) 40 PINS 34.1 16.6 5.8 0.2 5.7 | UNIT |
| | | 40 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 34.1 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 16.6 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 5.8 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 0.2 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 5.7 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | 0.9 | °C/W |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Supply: Currents, UVLO, and Power-On Reset

 $V_{\text{VIN_CSNIN}} = 12.0 \text{ V}, V_{\text{V3P3}} = 3.3 \text{ V}, V_{\text{AVSN}} = \text{GND}, V_{\text{BVSN}} = \text{GND}, V_{\text{AVSP}} = V_{\text{OUTA}}, V_{\text{BVSP}} = V_{\text{OUTB}} \text{ (Unless otherwise noted)}.$

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|------------------------------|---|-------|---------|-------|------|
| Supply: Curr | ents, UVLO, and Power-On Res | et | | | | |
| I _{V3P3} | V3P3 supply current | VDAC < VSP < VDAC + 100m V, ENABLE = 'HI' | | 13 | 18 | mA |
| I _{V3P3SBY} | V3P3 standby current | ENABLE = 'LO ' | | 9 | 13.5 | mA |
| V _{3NORMAL} | V3P3 normal range | Normal operation | 2.97 | | 3.5 | V |
| V _{3UVLOH} | V3P3 UVLO 'OK ' threshold | Ramp up | 2.85 | | 2.95 | V |
| V _{3UVLOL} | V3P3 UVLO fault threshold | Ramp down | 2.65 | | 2.75 | V |
| | | VIN_ON = 0xF010 | 3.75 | 4 | 4.25 | V |
| | | VIN_ON = 0xF015 | 5 | 5.25 | 5.5 | V |
| | | VIN_ON = 0xF019 | 6 | 6.25 | 6.5 | V |
| | | VIN_ON = 0xF01D | 7 | 7.25 | 7.5 | V |
| V_{12ON} | V12 UVLO 'OK ' threshold | VIN_ON = 0xF021 | 8 | 8.25 | 8.5 | V |
| | | VIN_ON = 0xF025 | 9 | 9.25 | 9.5 | V |
| | | VIN_ON = 0xF029 | 10 | 10.25 | 10.5 | V |
| | | VIN_ON = 0xF02D | 11 | 11.25 | 11.5 | V |
| | | VIN_ON = others | | invalid | | |
| | | VIN_UV_FAULT_LIMIT = 0xF011 | 4 | 4.25 | 4.48 | V |
| | | VIN_UV_FAULT_LIMIT = 0xF80B | 5.25 | 5.5 | 5.78 | V |
| | | VIN_UV_FAULT_LIMIT = 0xF80D | 6.25 | 6.5 | 6.78 | V |
| | | VIN_UV_FAULT_LIMIT = 0xF80F | 7.25 | 7.5 | 7.78 | V |
| V _{12UVF} | V12 UVLO fault threshold | VIN_UV_FAULT_LIMIT = 0xF811 | 8.25 | 8.5 | 8.78 | V |
| | | VIN_UV_FAULT_LIMIT = 0xF813 | 9.25 | 9.5 | 9.78 | V |
| | | VIN_UV_FAULT_LIMIT = 0xF815 | 10.25 | 10.5 | 10.78 | V |
| | | VIN_UV_FAULT_LIMIT = 0xF817 | 11.25 | 11.5 | 11.8 | V |
| | | VIN_UV_FAULT_LIMIT = others | | invalid | | |

TEXAS INSTRUMENTS

6.6 References: DAC and VREF

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------|-------------------------------|--|--------|-------|--------|------|
| \/ | VID aton size | 10 mV DAC: Change VID0 HI to LO to HI | | 10 | | mV |
| V_{VIDSTP} | VID step size | 5 mV DAC: Change VID0 HI to LO to HI | | 5 | | mV |
| V _{DAC0} | VSP tolerance | 10 mV DAC : $0.50 \le V_{VSP} \le 0.99 \text{ V}$, $I_{CORE} = 0 \text{ A}$ | -10 | | 10 | mV |
| V | VSP tolerance | 5 mV DAC: $0.25 \le V_{VSP} \le 0.795 \text{ V}$, $I_{CORE} = 0 \text{ A}$ | 8 | | 8 | mV |
| V _{DAC1} | VSF tolerance | 10 mV DAC: 1.00 V \leq V _{VSP} \leq 1.49 V, I _{CORE} = 0 A | -0 | | 0 | IIIV |
| V _{DAC2} | VSP tolerance | 5 mV DAC: $0.8 \le V_{VSP} \le 0.995 V$, $I_{CORE} = 0 A$ | -5 | | 5 | mV |
| V_{DAC3} | VSP tolerance | 5mV DAC: 1.00V ≤ VSP ≤ 1.52 V, I _{CORE} = 0 A | -0.5 | | 0.5 | % |
| VDAC3 | | 10 mV DAC: 1.50 V \leq V _{VSP} \leq 2.50 V, I _{CORE} = 0 A | | | 0.0 | |
| V_{VREF} | VREF output deeper sleep | $2.97V \le V_{V3P3} \le 3.5 \text{ V}, I_{VREF} = 0 \text{ A}$ | 1.692 | 1.7 | 1.708 | V |
| $V_{VREFSRC}$ | VREF output source | 0 A ≤ I _{VREF} = 2 mA | -8 | | | mV |
| $V_{VREFSNK}$ | VREF output sink | -2 mA ≤ I _{VREF} = 0 A | | | 8 | mV |
| V | Voltage divider ratio | VOUT_SCALE_LOOP = 0xe809, VOUT_SCALE_MONITOR = 0xe809 | | 1.125 | | |
| K _{RATIO} | | VOUT_SCALE_LOOP = 0xe808, VOUT_SCALE_MONITOR = 0xe808 | | 1 | | |
| V _{OUT_TRIML} | V _{OUT} offset LSB | MFR_SPECIFIC_05 = 0x01 | 0 | 1.25 | 2.5 | mV |
| | | MFR_SPECIFIC_05 = 0x1F | 37.5 | 38.75 | 40 | |
| M | V offeet renge | MFR_SPECIFIC_05 = 0xA0 | -43.25 | -40 | -37.75 | m) / |
| V _{OUT_TRIMR} | V _{OUT} offset range | MFR_SPECIFIC_05 = 0x5F | 56.25 | 58.75 | 61.25 | mV |
| | | MFR_SPECIFIC_05 = 0xE0 | -63 | -60 | -57 | |

6.7 Voltage Sense: AVSP and BVSP, AVSN and BVSN

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------|-------------------------|---|------------|-----|-----|------|
| I _{AVSP} | AVSP input bias current | Not in Fault, Disable or UVLO; $V_{VSP} = V_{VDAC}$ = 2.3 V, $V_{VSN} = 0$ V | | | 75 | μΑ |
| I _{AVSN} | AVSN input bias current | Not in Fault, Disable or UVLO; $V_{VSP} = V_{VDAC}$ = 2.3 V, $V_{VSN} = 0$ V | -75 | | | μΑ |
| I _{BVSP} | BVSP input bias current | Not in Fault, Disable or UVLO; $V_{VSP} = V_{VDAC}$ = 1.0 V, $V_{VSN} = 0$ V | | | 75 | μΑ |
| I _{BVSN} | BVSN input bias current | Not in Fault, Disable or UVLO; $V_{VSP} = V_{VDAC}$ = 1.0 V, $V_{VSN} = 0$ V | -75 | | | μΑ |

6.8 Telemetry

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over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP MAX | UNIT |
|------------------------|--|--|--------|---------|------|
| V _{READ_VOUT} | MFR_READ_VOUT Accuracy | 5 mV DAC : $0.25 \text{ V} \le \text{V}_{\text{VSP}} \le 1.52 \text{ V}$ 10 mV DAC: $0.5 \le \text{V}_{\text{VSP}} \le 2.4 \text{ V}$ | -12 | 12 | mV |
| V _{READ_VIN} | READ_VIN Accuracy | 4.50 V ≤ V _{IN} ≤ 17 V | -2.25% | 2.25% | |
| | | 6-phase, I _{CC(max)} = 228 A, I _{OUT} = 22.8 A | -7.3% | 7.3% | |
| | | 6-phase, I _{CC(max)} = 228 A, I _{OUT} = 45.6 A | -4.2% | 4.2% | |
| I _{MON_ACC} | | 6-phase, I _{CC(max)} = 228 A, I _{OUT} = 68.4 A | -3.1% | 3.1% | |
| | Digital current monitor | 6-phase, I _{CC(max)} = 228 A, I _{OUT} = 91.2 A | -2.5% | 2.5% | |
| | accuracy, Rail A (READ_IOUT) | 6-phase, I _{CC(max)} = 228 A, I _{OUT} = 114 A | -2.3% | 2.3% | |
| | | 6-phase, I _{CC(max)} = 228 A, I _{OUT} = 136.8 A | -2% | 2% | |
| | | 6-phase, I _{CC(max)} = 228 A, I _{OUT} = 228 A | -1.6% | 1.6% | |
| | | 6-phase, I _{CC(max)} = 228 A, I _{OUT} = 255 A | -1.5% | 1.5% | |
| | | 5-phase, I _{CC(max)} = 228 A, I _{OUT} = 22.8 A | -6.4% | 6.4% | |
| | | 5-phase, I _{CC(max)} = 228 A, I _{OUT} = 45.6 A | -3.7% | 3.7% | |
| | | 5-phase, I _{CC(max)} = 228 A, I _{OUT} = 68.4 A | -2.9% | 2.9% | |
| MON_ACC | Digital current monitor accuracy, Rail A (READ_IOUT) | 5-phase, I _{CC(max)} = 228 A, I _{OUT} = 91.2 A | -2.3% | 2.3% | |
| | accuracy, Nam A (NEAD_1001) | 5-phase, I _{CC(max)} = 228 A, I _{OUT} = 114 A | -2.1% | 2.1% | |
| | | 5-phase, I _{CC(max)} = 228 A, I _{OUT} = 136.8 A | -1.9% | 1.9% | |
| | | 5-phase, I _{CC(max)} = 228 A, I _{OUT} = 228 A | -1.5% | 1.5% | |
| | | 4-phase, I _{CC(max)} = 200 A, I _{OUT} = 20 A | -6.5% | 6.5% | |
| | | 4-phase, I _{CC(max)} = 200 A, I _{OUT} = 40 A | -3.7% | 3.7% | |
| | | 4-phase, I _{CC(max)} = 200 A, I _{OUT} = 60 A | -2.8% | 2.8% | |
| MON_ACC | Digital current monitor accuracy, Rail A (READ_IOUT) | 4-phase, I _{CC(max)} = 200 A, I _{OUT} = 80 A | -2.3% | 2.3% | |
| | accuracy, Nail A (NEAD_1001) | 4-phase, I _{CC(max)} = 200 A, I _{OUT} = 100 A | -2.1% | 2.1% | |
| | | 4-phase, I _{CC(max)} = 200 A, I _{OUT} = 120 A | -1.9% | 1.9% | |
| | | 4-phase, I _{CC(max)} = 200 A, I _{OUT} = 200 A | -1.5% | 1.5% | |
| | | 3-phase, I _{CC(max)} = 82 A, I _{OUT} = 8.2 A | -11.4% | 11.4% | |
| | | 3-phase, I _{CC(max)} = 82 A, I _{OUT} = 16.4 A | -6.1% | 6.1% | |
| | | 3-phase, I _{CC(max)} = 82 A, I _{OUT} = 24.6 A | -4.6% | 4.6% | |
| MON_ACC | Digital current monitor accuracy, Rail B (READ_IOUT) | 3-phase, I _{CC(max)} = 82 A, I _{OUT} = 32.8 A | -3.4% | 3.4% | |
| | accuracy, Nam B (NEAD_1001) | 3-phase, I _{CC(max)} = 82 A, I _{OUT} = 41 A | -3% | 3% | |
| | | 3-phase, I _{CC(max)} = 82 A, I _{OUT} = 49.2 A | -2.8% | 2.8% | |
| | | 3-phase, I _{CC(max)} = 82 A, I _{OUT} = 82 A | -2% | 2% | |
| | | 2-phase, I _{CC(max)} = 82 A, I _{OUT} = 8.2 A | -8.7% | 8.7% | |
| | | 2-phase, I _{CC(max)} = 82 A, I _{OUT} = 16.4 A | -4.7% | 4.7% | |
| | | 2-phase, I _{CC(max)} = 82 A, I _{OUT} = 24.6 A | -3.7% | 3.7% | |
| MON_ACC | Digital current monitor accuracy, Rail B (READ_IOUT) | 2-phase, I _{CC(max)} = 82 A, I _{OUT} = 32.8 A | -2.7% | 2.7% | |
| = | accuracy, Nam D (NEAD_1001) | 2-phase, I _{CC(max)} = 82 A, I _{OUT} = 41 A | -2.5% | 2.5% | |
| | | 2-phase, I _{CC(max)} = 82 A, I _{OUT} = 49.2 A | -2.4% | 2.4% | |
| | | 2-phase, I _{CC(max)} = 82 A, I _{OUT} = 82 A | -1.8% | 1.8% | |
| Гетр | READ_TEMP1 | 0.28 V (-40°C) ≤ TSEN ≤ 1.8 V (150°C) | -2 | 0 2 | °C |



TEXAS INSTRUMENTS

6.9 Input Current Sensing

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP MAX | UNIT |
|-----------------|-------------------|--|------|---------|------|
| I _{IN} | | $ (V_{CSPIN} - V_{CSNIN}) = 2.5 \text{ mV}, \ I_{IN} = 5 \text{ A}, \\ R_{SENSE} = 0.5 \text{ m}\Omega $ | -10% | 10% | |
| | READ_IIN accuracy | $ (V_{CSPIN} - V_{CSNIN}) = 5 \text{ mV}, \ I_{IN} = 10 \text{ A}, $ $R_{SENSE} = 0.5 \text{ m}\Omega $ | -6% | 6% | |
| | | $ \begin{aligned} &(V_{CSPIN} - V_{CSNIN}) = 15 \text{ mV}, \ I_{IN} = 30 \text{ A}, \\ &R_{SENSE} = 0.5 \text{ m}\Omega \end{aligned} $ | -3% | 3% | |



6.10 Programmable Loadline Settings

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------|--------------------------|---------------------|--------|--------|--------|-----------|
| | | VOUT_DROOP = 0xD000 | | 0 | | $m\Omega$ |
| | | VOUT_DROOP = 0xD008 | 0.1125 | 0.125 | 0.1395 | $m\Omega$ |
| | | VOUT_DROOP = 0xD010 | 0.2412 | 0.25 | 0.2587 | $m\Omega$ |
| | | VOUT_DROOP = 0xD014 | 0.3031 | 0.3125 | 0.3218 | mΩ |
| | | VOUT_DROOP = 0xD018 | 0.3637 | 0.375 | 0.3872 | $m\Omega$ |
| | | VOUT_DROOP = 0xD01C | 0.4265 | 0.4375 | 0.4484 | $m\Omega$ |
| | | VOUT_DROOP = 0xD020 | 0.4875 | 0.5 | 0.5125 | $m\Omega$ |
| | | VOUT_DROOP = 0xD024 | 0.5484 | 0.5625 | 0.5765 | $m\Omega$ |
| | | VOUT_DROOP = 0xD028 | 0.6093 | 0.625 | 0.6406 | $m\Omega$ |
| | | VOUT_DROOP = 0xD030 | 0.6855 | 0.7031 | 0.7207 | $m\Omega$ |
| | | VOUT_DROOP = 0xD033 | 0.7769 | 0.7969 | 0.8168 | $m\Omega$ |
| | | VOUT_DROOP = 0xD034 | 0.7921 | 0.8125 | 0.8328 | $m\Omega$ |
| | | VOUT_DROOP = 0xD035 | 0.8073 | 0.8281 | 0.8488 | $m\Omega$ |
| | | VOUT_DROOP = 0xD036 | 0.8227 | 0.8438 | 0.8648 | $m\Omega$ |
| | | VOUT_DROOP = 0xD037 | 0.8379 | 0.8594 | 0.8808 | $m\Omega$ |
| | | VOUT_DROOP = 0xD038 | 0.8531 | 0.875 | 0.8968 | $m\Omega$ |
| | | VOUT_DROOP = 0xD039 | 0.8683 | 0.8906 | 0.9128 | $m\Omega$ |
| | | VOUT_DROOP = 0xD03A | 0.8836 | 0.9063 | 0.9289 | $m\Omega$ |
| | | VOUT_DROOP = 0xD03B | 0.8988 | 0.9219 | 0.9449 | $m\Omega$ |
| | | VOUT_DROOP = 0xD03C | 0.9140 | 0.9375 | 0.9609 | $m\Omega$ |
| | | VOUT_DROOP = 0xD03D | 0.9292 | 0.9531 | 0.9769 | $m\Omega$ |
| CI | DC loadline settings for | VOUT_DROOP = 0xD03E | 0.9445 | 0.9688 | 0.9930 | $m\Omega$ |
| CLL _{Channel A} | Channel A | VOUT_DROOP = 0xD03F | 0.9597 | 0.9844 | 1.0090 | $m\Omega$ |
| | | VOUT_DROOP = 0xD040 | 0.975 | 1 | 1.025 | $m\Omega$ |
| | | VOUT_DROOP = 0xD041 | 0.9902 | 1.0156 | 1.0409 | $m\Omega$ |
| | | VOUT_DROOP = 0xD042 | 1.0055 | 1.0313 | 1.0570 | $m\Omega$ |
| | | VOUT_DROOP = 0xD043 | 1.0207 | 1.0469 | 1.0730 | $m\Omega$ |
| | | VOUT_DROOP = 0xD044 | 1.0359 | 1.0625 | 1.0890 | $m\Omega$ |
| | | VOUT_DROOP = 0xD048 | 1.0968 | 1.125 | 1.1531 | $m\Omega$ |
| | | VOUT_DROOP = 0xD050 | 1.2187 | 1.25 | 1.2812 | $m\Omega$ |
| | | VOUT_DROOP = 0xD058 | 1.3406 | 1.375 | 1.4093 | $m\Omega$ |
| | | VOUT_DROOP = 0xD060 | 1.4625 | 1.5 | 1.5375 | $m\Omega$ |
| | | VOUT_DROOP = 0xD068 | 1.5843 | 1.625 | 1.6656 | $m\Omega$ |
| | | VOUT_DROOP = 0xD070 | 1.7062 | 1.75 | 1.7937 | $m\Omega$ |
| | | VOUT_DROOP = 0xD078 | 1.8281 | 1.875 | 1.9218 | $m\Omega$ |
| | | VOUT_DROOP = 0xD07C | 1.8890 | 1.9375 | 1.9859 | $m\Omega$ |
| | | VOUT_DROOP = 0xD080 | 1.95 | 2 | 2.05 | mΩ |
| | | VOUT_DROOP = 0xD084 | 2.0109 | 2.0625 | 2.1141 | mΩ |
| | | VOUT_DROOP = 0xD088 | 2.0718 | 2.125 | 2.1781 | mΩ |
| | | VOUT_DROOP = 0xD08C | 2.1328 | 2.1875 | 2.2421 | mΩ |
| | | VOUT_DROOP = 0xD090 | 2.1937 | 2.25 | 2.3062 | mΩ |
| | | VOUT_DROOP = 0xD098 | 2.2698 | 2.328 | 2.3862 | mΩ |
| | | VOUT_DROOP = 0xD09B | 2.3612 | 2.4218 | 2.4823 | mΩ |
| | | VOUT_DROOP = 0xD09C | 2.3765 | 2.4375 | 2.4984 | mΩ |





Programmable Loadline Settings (continued)

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|--------------------------|---------------------|--------|--------|--------|-----------|
| | | VOUT_DROOP = 0xD09D | 2.3917 | 2.4531 | 2.5144 | mΩ |
| | | VOUT_DROOP = 0xD09E | 2.4069 | 2.4687 | 2.5304 | mΩ |
| | | VOUT_DROOP = 0xD09F | 2.4221 | 2.4843 | 2.5464 | mΩ |
| | | VOUT_DROOP = 0xD0A0 | 2.4375 | 2.5 | 2.5625 | mΩ |
| | | VOUT_DROOP = 0xD0A1 | 2.4527 | 2.5156 | 2.5784 | mΩ |
| | | VOUT_DROOP = 0xD0A2 | 2.4679 | 2.5312 | 2.5944 | mΩ |
| | | VOUT_DROOP = 0xD0A3 | 2.4831 | 2.5468 | 2.6104 | mΩ |
| | | VOUT_DROOP = 0xD0A4 | 2.4984 | 2.5625 | 2.6265 | mΩ |
| | | VOUT_DROOP = 0xD0A5 | 2.5136 | 2.5781 | 2.6425 | mΩ |
| DCLI | DC loadline settings for | VOUT_DROOP = 0xD0A6 | 2.5288 | 2.5937 | 2.6585 | mΩ |
| DCLL _{Channel A} | Channel A | VOUT_DROOP = 0xD0A7 | 2.5437 | 2.609 | 2.6742 | mΩ |
| | | VOUT_DROOP = 0xD0A8 | 2.5593 | 2.625 | 2.6906 | mΩ |
| | | VOUT_DROOP = 0xD0A9 | 2.5745 | 2.6406 | 2.7066 | mΩ |
| | | VOUT_DROOP = 0xD0AA | 2.5897 | 2.6562 | 2.7226 | mΩ |
| | | VOUT_DROOP = 0xD0AB | 2.6050 | 2.6718 | 2.7385 | mΩ |
| | | VOUT_DROOP = 0xD0AC | 2.6203 | 2.6875 | 2.7546 | mΩ |
| | | VOUT_DROOP = 0xD0B0 | 2.6812 | 2.75 | 2.8187 | mΩ |
| | | VOUT_DROOP = 0xD0B8 | 2.8031 | 2.875 | 2.9468 | mΩ |
| | | VOUT_DROOP = 0xD0C0 | 2.925 | 3 | 3.075 | mΩ |
| | | VOUT_DROOP = 0xD0C8 | 3.0468 | 3.125 | 3.2031 | mΩ |
| | | VOUT_DROOP = 0xD000 | | 0 | | $m\Omega$ |
| | | VOUT_DROOP = 0xD008 | 0.1125 | 0.125 | 0.1395 | $m\Omega$ |
| | | VOUT_DROOP = 0xD010 | 0.2355 | 0.25 | 0.2625 | $m\Omega$ |
| | | VOUT_DROOP = 0xD014 | 0.297 | 0.3125 | 0.3234 | $m\Omega$ |
| | | VOUT_DROOP = 0xD018 | 0.3637 | 0.375 | 0.395 | mΩ |
| | | VOUT_DROOP = 0xD01C | 0.4244 | 0.4375 | 0.454 | mΩ |
| | | VOUT_DROOP = 0xD020 | 0.4875 | 0.5 | 0.517 | mΩ |
| DCLI | DC Loadline settings for | VOUT_DROOP = 0xD024 | 0.5464 | 0.5625 | 0.5786 | $m\Omega$ |
| DCLL _{Channel B} | Channel B | VOUT_DROOP = 0xD028 | 0.6093 | 0.625 | 0.648 | $m\Omega$ |
| | | VOUT_DROOP = 0xD030 | 0.6855 | 0.7031 | 0.7207 | mΩ |
| | | VOUT_DROOP = 0xD033 | 0.7769 | 0.7969 | 0.8168 | mΩ |
| | | VOUT_DROOP = 0xD034 | 0.7921 | 0.8125 | 0.8335 | mΩ |
| | | VOUT_DROOP = 0xD035 | 0.8073 | 0.8281 | 0.852 | mΩ |
| | | VOUT_DROOP = 0xD036 | 0.8227 | 0.8438 | 0.8648 | mΩ |
| | | VOUT_DROOP = 0xD037 | 0.8379 | 0.8594 | 0.8815 | mΩ |
| | | VOUT_DROOP = 0xD038 | 0.8531 | 0.875 | 0.8968 | mΩ |



Programmable Loadline Settings (continued)

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------|---|------------------------|--------|--------|--------|-----------|
| | | MFR_SPECIFIC_07 = 0x00 | | 0 | | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x01 | 0.1125 | 0.125 | 0.1395 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x02 | 0.2412 | 0.25 | 0.2587 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x03 | 0.3031 | 0.3125 | 0.3218 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x04 | 0.3637 | 0.375 | 0.3862 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x05 | 0.4265 | 0.4375 | 0.4484 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x06 | 0.4875 | 0.5 | 0.5125 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x07 | 0.5484 | 0.5625 | 0.5765 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x08 | 0.6093 | 0.625 | 0.6406 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x09 | 0.7312 | 0.75 | 0.7687 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x0A | 0.7769 | 0.7969 | 0.8168 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x0B | 0.7921 | 0.8125 | 0.8328 | mΩ |
| | | MFR_SPECIFIC_07 = 0x0C | 0.8073 | 0.8281 | 0.8488 | mΩ |
| | | MFR_SPECIFIC_07 = 0x0D | 0.8227 | 0.8438 | 0.8648 | mΩ |
| | | MFR_SPECIFIC_07 = 0x0E | 0.8379 | 0.8594 | 0.8808 | mΩ |
| | | MFR_SPECIFIC_07 = 0x0F | 0.8531 | 0.875 | 0.8968 | mΩ |
| | | MFR_SPECIFIC_07 = 0x10 | 0.8683 | 0.8906 | 0.9128 | mΩ |
| | | MFR_SPECIFIC_07 = 0x11 | 0.8836 | 0.9063 | 0.9289 | mΩ |
| | | MFR_SPECIFIC_07 = 0x12 | 0.8988 | 0.9219 | 0.9449 | mΩ |
| | | MFR_SPECIFIC_07 = 0x13 | 0.9140 | 0.9375 | 0.9609 | mΩ |
| | | MFR_SPECIFIC_07 = 0x14 | 0.9292 | 0.9531 | 0.9769 | mΩ |
| 4011 | AC Loadline settings for | MFR_SPECIFIC_07 = 0x15 | 0.9445 | 0.9688 | 0.9930 | mΩ |
| ACLL | both Channel A and Channel B ⁽¹⁾ | MFR_SPECIFIC_07 = 0x16 | 0.9597 | 0.9844 | 1.0090 | mΩ |
| | | MFR_SPECIFIC_07 = 0x17 | 0.975 | 1 | 1.025 | mΩ |
| | | MFR_SPECIFIC_07 = 0x18 | 0.9902 | 1.0156 | 1.0409 | mΩ |
| | | MFR_SPECIFIC_07 = 0x19 | 1.0055 | 1.0313 | 1.0570 | mΩ |
| | | MFR_SPECIFIC_07 = 0x1A | 1.0207 | 1.0469 | 1.0730 | mΩ |
| | | MFR_SPECIFIC_07 = 0x1B | 1.0359 | 1.0625 | 1.0890 | mΩ |
| | | MFR_SPECIFIC_07 = 0x1C | 1.0968 | 1.125 | 1.1531 | mΩ |
| | | MFR_SPECIFIC_07 = 0x1D | 1.2187 | 1.25 | 1.2812 | mΩ |
| | | MFR_SPECIFIC_07 = 0x1E | 1.3406 | 1.375 | 1.4093 | mΩ |
| | | MFR_SPECIFIC_07 = 0x1F | 1.4625 | 1.5 | 1.5375 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x20 | 1.5843 | 1.625 | 1.6656 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x21 | 1.7062 | 1.75 | 1.7937 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x22 | 1.8281 | 1.875 | 1.9218 | mΩ |
| | | MFR_SPECIFIC_07 = 0x23 | 1.8890 | 1.9375 | 1.9859 | mΩ |
| | | MFR_SPECIFIC_07 = 0x24 | 1.95 | 2 | 2.05 | mΩ |
| | | MFR_SPECIFIC_07 = 0x25 | 2.0109 | 2.0625 | 2.1140 | mΩ |
| | | MFR_SPECIFIC_07 = 0x26 | 2.0718 | 2.125 | 2.1781 | mΩ |
| | | MFR_SPECIFIC_07 = 0x27 | 2.1328 | 2.1875 | 2.2421 | mΩ |
| | | MFR_SPECIFIC_07 = 0x28 | 2.1937 | 2.25 | 2.3062 | mΩ |
| | | MFR_SPECIFIC_07 = 0x29 | 2.3156 | 2.375 | 2.4343 | mΩ |
| | | MFR_SPECIFIC_07 = 0x2A | 2.3612 | 2.4218 | 2.4823 | mΩ |
| | | MFR_SPECIFIC_07 = 0x2B | 2.3765 | 2.4375 | 2.4984 | mΩ |

⁽¹⁾ Specified by design. Not production tested.

TEXAS INSTRUMENTS

Programmable Loadline Settings (continued)

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|---|--------------------------|--------|--------|--------|-----------|
| | | MFR_SPECIFIC_07 = 0x2C | 2.3917 | 2.4531 | 2.5144 | mΩ |
| | | MFR_SPECIFIC_07 = 0x2D | 2.4069 | 2.4687 | 2.5304 | mΩ |
| | | MFR_SPECIFIC_07 = 0x2E | 2.4221 | 2.4843 | 2.5464 | mΩ |
| | | MFR_SPECIFIC_07 = 0x2F | 2.4375 | 2.5 | 2.5625 | mΩ |
| | | MFR_SPECIFIC_07 = 0x30 | 2.4527 | 2.5156 | 2.5784 | mΩ |
| | | MFR_SPECIFIC_07 = 0x31 | 2.4679 | 2.5312 | 2.5944 | mΩ |
| | | MFR_SPECIFIC_07 = 0x32 | 2.4831 | 2.5468 | 2.6104 | mΩ |
| | | MFR_SPECIFIC_07 = 0x33 | 2.4984 | 2.5625 | 2.6265 | mΩ |
| | | MFR_SPECIFIC_07 = 0x34 | 2.5136 | 2.5781 | 2.6425 | mΩ |
| ACLI | AC Loadline settings for | MFR_SPECIFIC_07 = 0x35 | 2.5288 | 2.5937 | 2.6585 | mΩ |
| ACLL | both Channel A and Channel B ⁽¹⁾ | MFR_SPECIFIC_07 = 0x36 | 2.5437 | 2.609 | 2.6742 | mΩ |
| | | MFR_SPECIFIC_07 = 0x37 | 2.5593 | 2.625 | 2.6906 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x38 | 2.5745 | 2.6406 | 2.7066 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x39 | 2.5897 | 2.6562 | 2.7226 | $m\Omega$ |
| | | MFR_SPECIFIC_07 = 0x3A | 2.6050 | 2.6718 | 2.7385 | mΩ |
| | | MFR_SPECIFIC_07 = 0x3B | 2.6203 | 2.6875 | 2.7546 | mΩ |
| | | MFR_SPECIFIC_07 = 0x3C | 2.6812 | 2.75 | 2.8187 | mΩ |
| | | MFR_SPECIFIC_07 = 0x3D | 2.8031 | 2.875 | 2.9468 | mΩ |
| | | MFR_SPECIFIC_07 = 0x3E | 2.925 | 3 | 3.075 | mΩ |
| | | MFR_SPECIFIC_07 = 0x3F | 3.0468 | 3.125 | 3.2031 | $m\Omega$ |
| | | MFR_SPEC_7<11:8> = 0000b | | 5 | | μs |
| | | MFR_SPEC_7<11:8> = 0001b | | 10 | | μs |
| | | MFR_SPEC_7<11:8> = 0010b | | 15 | | μs |
| | | MFR_SPEC_7<11:8> = 0011b | | 20 | | μs |
| | | MFR_SPEC_7<11:8> = 0100b | | 25 | | μs |
| | | MFR_SPEC_7<11:8> = 0101b | | 30 | | μs |
| | | MFR_SPEC_7<11:8> = 0110b | | 35 | | μs |
| | Integration time constant ⁽¹⁾ | MFR_SPEC_7<11:8> = 0111b | | 40 | | μs |
| t _{INT} | Integration time constant | MFR_SPEC_7<11:8> = 1000b | | 1 | | μs |
| | | MFR_SPEC_7<11:8> = 1001b | | 2 | | μs |
| | | MFR_SPEC_7<11:8> = 1010b | | 3 | | μs |
| | | MFR_SPEC_7<11:8> = 1011b | | 4 | | μs |
| | | MFR_SPEC_7<11:8> = 1100b | | 5 | | μs |
| | | MFR_SPEC_7<11:8> = 1101b | | 6 | | μs |
| | | MFR_SPEC_7<11:8> = 1110b | | 7 | | μs |
| | | MFR_SPEC_7<11:8> = 1111b | | 8 | | μs |



6.11 Current Sense and Calibration

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------------|---|--|-----|--------|-----|------|
| I _{ACSP1} | ACSP1 leakage current | V _{ACSP1} = 2.5 V | 0 | | 20 | μA |
| I _{ACSP2} | ACSP2 leakage current | V _{ACSP2} = 2.5 V | 0 | | 20 | μΑ |
| I _{ACSP3} | ACSP3 leakage current | V _{ACSP3} = 2.5 V | 0 | | 20 | μA |
| I _{ACSP4} | ACSP4 leakage current | V _{ACSP4} = 2.5 V | 0 | | 20 | μA |
| I _{ACSP5} | ACSP5 leakage current | V _{ACSP5} = 2.5 V | 0 | | 20 | μA |
| I _{ACSP6} | ACSP6 leakage current | V _{ACSP6} = 2.5 V | 0 | | 20 | μΑ |
| I _{BCSP1} | BCSP1 leakage current | V _{BCSP1} = 2.5 V | 0 | | 20 | μΑ |
| I _{BCSP2} | BCSP2 leakage current | V _{BCSP2} = 2.5 V | 0 | | 20 | μA |
| I _{MON_CAL_OF1} | Current monitor calibration offset LSB (per-phase) ⁽¹⁾ | IOUT_CAL_OFFSET resolution (perphase) | | 0.125 | | Α |
| | Current monitor calibration offset | iOUT_CAL_OFFSET = 0xE808 (per- | | Α | | |
| MON_CAL_OF2 | range (per-phase) | IOUT_CAL_OFFSET = 0xEFF9 (per- phase) | - | -0.875 | | Α |
| I _{MON_CAL_OF3} | Current monitor calibration offset LSB (total) ⁽¹⁾ | IOUT_CAL_OFFSET resolution (total) | | 0.25 | | Α |
| | Current monitor calibration offset | IOUT_CAL_OFFSET = 0xE820 (total) | | 4 | | Α |
| IMON_CAL_OF4 | range (total) | IOUT_CAL_OFFSET = 0xEFE2 (total) | | -3.75 | | Α |
| I _{MON_CAL_GA_LSB} | Current monitor calibration gain LSB ⁽¹⁾ | IOUT_CAL_GAIN resolution | 0.3 | 3125% | | |
| | Current monitor calibration gain | IOUT_CAL_GAIN = 0xD131 | 4 | 4.7656 | | mΩ |
| IMON_CAL_GA_RNG | range | IOUT_CAL_GAIN = 0xD150 | | 5.25 | | mΩ |

⁽¹⁾ Specified by design. Not production tested.

6.12 Logic Interface Pins: AVR_EN, AVR_RDY, BVR_EN, BVR_RDY, RESET, VR_FAULT, VR_HOT

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------|-------------------------------------|--|-------|------|------|------|
| R _{RPGDL} | Open-drain pulldown resistance | $V_{AVR_RDY} = V_{BVR_RDY} = V_{\overline{VR_FAULT}} = 0.45 \text{ V}$ | | 36 | 50 | Ω |
| I _{VRTTLK} | Open-drain leakage current | SDIO, VR_HOT, AVR_RDY, BVR_RDY, VR_FAULT, Hi Z Leakage, apply to 3.3-V supply in off state | -2 | 0.2 | 2 | μΑ |
| V _{AENL} | Channel A ENABLE logic low | | | | 0.7 | V |
| V _{AENH} | Channel A ENABLE logic high | | 0.8 | | | V |
| V _{AENHYS} | Channel A ENABLE hysteresis | | 0.028 | 0.05 | 0.07 | V |
| t _{AENDIG} | Channel A ENABLE deglitch (1) | | 0.2 | | | μs |
| I _{AENH} | Channel A I/O 1.1-V leakage | $V_{AVR_EN} = 1.1 \text{ V}$ | | | 25 | μΑ |
| V_{BENL} | Channel B ENABLE logic low | | | | 0.7 | V |
| V _{BENH} | Channel B ENABLE logic high | | 0.8 | | | V |
| V _{BENHYS} | Channel B ENABLE hysteresis | | 0.028 | 0.05 | 0.07 | V |
| t _{BENDIG} | Channel B ENABLE deglitch (1) | | 0.2 | | | μs |
| t _{AENVRRDYF} | Channel A ENABLE low to AVR_RDY low | From AVR_EN low to AVR_RDY low | | | 1.5 | μs |
| I _{BENH} | Channel B I/O 1.1-V leakage | V _{BENH} = 1.1 V | | | 25 | μΑ |
| V _{RSTL} | RESET logic low | | | | 0.8 | V |
| V _{RSTH} | RESET logic high ⁽¹⁾ | | 1.09 | | | V |
| t _{RSTTDLY} | RESET delay time | | | 1 | | μs |

⁽¹⁾ Specified by design. Not production tested.



ISTRUMENTS

6.13 I/O Timing

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------|---------------------------------------|--|-------|---------|-------|------|
| | | $V_{VBOOT} > 0$ V, no faults, $C_{REF} = 1 \mu F$, TON_DELAY = 0xB1EC (PAGE 0) | 0.38 | 0.48 | 0.58 | ms |
| | (4) | TON_DELAY = 0xB396 (PAGE 0) | 0.8 | 0.9 | 1 | ms |
| t _{STARTUPA} | Channel A startup time ⁽¹⁾ | TON_DELAY = 0xBAD1 (PAGE 0) | 1.308 | 1.408 | 1.508 | ms |
| | | TON_DELAY = 0xC26E (PAGE 0) | 2.28 | 2.432 | 2.584 | ms |
| | | TON_DELAY = others | | Invalid | | |
| | | $V_{VBOOT} > 0$ V, no faults, $C_{REF} = 1 \mu F$, TON_DELAY = 0xB1EC (PAGE 1) | 0.38 | 0.48 | 0.58 | ms |
| | (2) | TON_DELAY = 0xB396 (PAGE 1) | 0.8 | 0.9 | 1 | ms |
| t _{STARTUPB} | Channel B startup time (2) | TON_DELAY = 0xBAD1 (PAGE 1) | 1.308 | 1.408 | 1.508 | ms |
| | | TON_DELAY = 0xC26E (PAGE 1) | 2.28 | 2.432 | 2.584 | ms |
| | | TON_DELAY = others | | Invalid | | |
| t_{VCCVID} | VID change to VSP change (3) | ACK of SetVID_x command to start of voltage ramp | | | 500 | ns |
| t _{VRTDGLT} | VR_HOT update time | Temperature data update time | | 0.3 | 0.5 | ms |
| | | MFR_SPEC_09<8:6> = 000b | 53 | 72 | 92 | ns |
| | | MFR_SPEC_09<8:6> = 001b | 58 | 78 | 98 | ns |
| | | MFR_SPEC_09<8:6> = 010b | 66 | 86 | 108 | ns |
| | Dising adds blanking time (3) | MFR_SPEC_09<8:6> = 011b | 70 | 92 | 114 | ns |
| ^t on_blank | Rising-edge blanking time (3) | MFR_SPEC_09<8:6> = 100b | 78 | 100 | 125 | ns |
| | | MFR_SPEC_09<8:6> = 101b | 82 | 108 | 132 | ns |
| | | MFR_SPEC_09<8:6> = 110b | 88 | 114 | 139 | ns |
| | | MFR_SPEC_09<8:6> = 111b | 91 | 120 | 145 | ns |

⁽¹⁾ Time from AVR_EN to output voltage ramp up to target voltage.

⁽²⁾ Time from AVR_EN or BVR_EN to output v(3) Specified by design. Not production tested. Time from AVR_EN or BVR_EN to output voltage ramp up to target voltage.



6.14 PMBus Address Setting

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN TYP M | AX | UNIT |
|-------------------|---------------------------|---|---------------|----|------|
| | | V _{ADDR} ≤ 0.039 V | 1011000 (B0h) | | Bin |
| | | V _{ADDR} = 0.073 V with ±15 mV tolerance | 1011001 (B2h) | | Bin |
| | | V _{ADDR} = 0.122 V with ±15 mV tolerance | 1011010 (B4h) | | Bin |
| | | V _{ADDR} = 0.171 V with ±15 mV tolerance | 1011011 (B6h) | | Bin |
| | | V _{ADDR} = 0.219 V with ±15 mV tolerance | 1011100 (B8h) | | Bin |
| | | V _{ADDR} = 0.268 V with ±15 mV tolerance | 1011101 (BAh) | | Bin |
| | | V _{ADDR} = 0.317 V with ±15 mV tolerance | 1011110 (BCh) | | Bin |
| | | V _{ADDR} = 0.366 V with ±15 mV tolerance | 1011111 (BEh) | | Bin |
| | | V _{ADDR} = 0.415 V with ±15 mV tolerance | 1100000 (C0h) | | Bin |
| | | V _{ADDR} = 0.464 V with ±15 mV tolerance | 1100001 (C2h) | | Bin |
| | | V _{ADDR} = 0.513 V with ±15 mV tolerance | 1100010 (C4h) | | Bin |
| | | V _{ADDR} = 0.562 V with ±15 mV tolerance | 1100011 (C6h) | | Bin |
| | | V _{ADDR} = 0.610 V with ±15 mV tolerance | 1100100 (C8h) | | Bin |
| | | V _{ADDR} = 0.660 V with ±15 mV tolerance | 1100101 (CAh) | | Bin |
| | | V _{ADDR} = 0.708 V with ±15 mV tolerance | 1100110 (CCh) | | Bin |
| D | PMBus address bits (7-bit | V _{ADDR} = 0.757 V with ±15 mV tolerance | 1100111 (CEh) | | Bin |
| P _{ADDR} | format) | V _{ADDR} = 0.806 V with ±15 mV tolerance | 1101000 (D0h) | | Bin |
| | | V _{ADDR} = 0.854 V with ±15 mV tolerance | 1101001 (D2h) | | Bin |
| | | V _{ADDR} = 0.903 V with ±15 mV tolerance | 1101010 (D4h) | | Bin |
| | | V _{ADDR} = 0.952 V with ±15 mV tolerance | 1101011 (D6h) | | Bin |
| | | V _{ADDR} = 1.000 V with ±15 mV tolerance | 1101100 (D8h) | | Bin |
| | | V _{ADDR} = 1.050 V with ±15 mV tolerance | 1101101 (DAh) | | Bin |
| | | V _{ADDR} = 1.098 V with ±15 mV tolerance | 1101110 (DCh) | | Bin |
| | | V _{ADDR} = 1.147 V with ±15 mV tolerance | 1101111 (DEh) | | Bin |
| | | V _{ADDR} = 1.196 V with ±15 mV tolerance | 1110000 (E0h) | | Bin |
| | | V _{ADDR} = 1.245 V with ±15 mV tolerance | 1110001 (E2h) | | Bin |
| | | V _{ADDR} = 1.294 V with ±15 mV tolerance | 1110010 (E4h) | | Bin |
| | | V _{ADDR} = 1.343 V with ±15 mV tolerance | 1110011 (E6h) | | Bin |
| | | V _{ADDR} = 1.392 V with ±15 mV tolerance | 1110100 (E8h) | | Bin |
| | | V _{ADDR} = 1.440 V with ±15 mV tolerance | 1110101 (EAh) | | Bin |
| | | V _{ADDR} = 1.489 V with ±15 mV tolerance | 1110110 (ECh) | | Bin |
| | | V _{ADDR} = 1.540 V with ±15 mV tolerance | 1110111 (EEh) | | Bin |

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6.15 Overcurrent Limit Thresholds

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------|------------------------------------|-----------------------------------|------|------|------|------|
| | | MFR_SPEC_00<3:0>, (PAGE0) = 0000b | 12.5 | 14.5 | 16.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 0001b | 16.5 | 18.5 | 20.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 0010b | 20.5 | 22.5 | 24.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 0011b | 24.5 | 26.5 | 28.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 0100b | 28.5 | 30.5 | 32.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 0101b | 32.5 | 34.5 | 36.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 0110b | 36.5 | 38.5 | 40.5 | Α |
| | Phase OCL levels for Channel A | MFR_SPEC_00<3:0>, (PAGE0) = 0111b | 40.5 | 42.5 | 44.5 | Α |
| I _{OCLAx} | (ACSPx-VREF), valley current limit | MFR_SPEC_00<3:0>, (PAGE0) = 1000b | 44.5 | 46.5 | 48.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 1001b | 48.5 | 50.5 | 52.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 1010b | 52.5 | 54.5 | 56.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 1011b | 56.5 | 58.5 | 60.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 1100b | 60.5 | 62.5 | 64.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 1101b | 64.5 | 66.5 | 68.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 1110b | 68.5 | 70.5 | 72.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE0) = 1111b | 72.5 | 74.5 | 76.5 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 0000b | 12 | 14 | 16 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 0001b | 16 | 18 | 20 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 0010b | 20 | 22 | 24 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 0011b | 24 | 26 | 28 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 0100b | 28 | 30 | 32 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 0101b | 32 | 34 | 36 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 0110b | 36 | 38 | 40 | Α |
| | Phase OCL levels for Channel B | MFR_SPEC_00<3:0>, (PAGE1) = 0111b | 40 | 42 | 44 | Α |
| I _{OCLBx} | (BCSPx-VREF), valley current limit | MFR_SPEC_00<3:0>, (PAGE1) = 1000b | 44 | 46 | 48 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 1001b | 48 | 50 | 52 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 1010b | 52 | 54 | 56 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 1011b | 56 | 58 | 60 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 1100b | 60 | 62 | 64 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 1101b | 64 | 66 | 68 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 1110b | 68 | 70 | 72 | Α |
| | | MFR_SPEC_00<3:0>, (PAGE1) = 1111b | 72 | 74 | 76 | Α |



6.16 Switching Frequency

 V_{IN} = 12 V, V_{AVSP} = 1.0 V, V_{BVSP} = 0.8 V, T_A = 25°C

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----|----------------------|---------------------------|-----|---------|------|------|
| | | FREQUENCY_SWITCH = 0x012C | 270 | 300 | 330 | kHz |
| | | FREQUENCY_SWITCH = 0x015E | 315 | 350 | 385 | kHz |
| | | FREQUENCY_SWITCH = 0x0190 | 360 | 400 | 440 | kHz |
| | | FREQUENCY_SWITCH = 0x01C2 | 405 | 450 | 495 | kHz |
| | | FREQUENCY_SWITCH = 0x01F4 | 450 | 500 | 550 | kHz |
| | | FREQUENCY_SWITCH = 0x0226 | 500 | 550 | 600 | kHz |
| | | FREQUENCY_SWITCH = 0x0258 | 540 | 600 | 660 | kHz |
| | Custohing from Long. | FREQUENCY_SWITCH = 0x028A | 585 | 650 | 715 | kHz |
| sw | Switching frequency | FREQUENCY_SWITCH = 0x02BC | 630 | 700 | 770 | kHz |
| | | FREQUENCY_SWITCH = 0x02EE | 675 | 750 | 825 | kHz |
| | | FREQUENCY_SWITCH = 0x0320 | 720 | 800 | 880 | kHz |
| | | FREQUENCY_SWITCH = 0x0352 | 765 | 850 | 935 | kHz |
| | | FREQUENCY_SWITCH = 0x0384 | 810 | 900 | 990 | kHz |
| | | FREQUENCY_SWITCH = 0x03B6 | 855 | 950 | 1045 | kHz |
| | | FREQUENCY_SWITCH = 0x03E8 | 900 | 1000 | 1100 | kHz |
| | | FREQUENCY_SWITCH = others | | Invalid | | kHz |

6.17 Slew Rate Settings

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------------------|-------------------------------------|-------------------------------|--------|------------------------|-----|-------|
| | | VOUT_TRANSITION_RATE = 0xE050 | 5 | 6 | 7 | mV/µs |
| | | VOUT_TRANSITION_RATE = 0xE0A0 | 10 | 12 | 14 | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE0F0 | 15 | 18 | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE140 | 20 | 24 | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE190 | 25 | 30 | | mV/μs |
| SL _{SET} Slew rate setting | | VOUT_TRANSITION_RATE = 0xE1E0 | 30 | 36 | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE230 | 35 | 42 | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE280 | 40 | 48 | | mV/μs |
| | Slew rate setting | VOUT_TRANSITION_RATE = 0xE005 | 0.3125 | | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE00A | 0.625 | | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE00F | 0.9375 | | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE014 | 1.25 | | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE019 | 1.5625 | | | mV/µs |
| | | VOUT_TRANSITION_RATE = 0xE01E | 1.875 | | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE023 | 2.1875 | | | mV/μs |
| | | VOUT_TRANSITION_RATE = 0xE028 | 2.5 | | | mV/μs |
| | | VOUT_TRANSITION_RATE = others | | Invalid data | | mV/μs |
| SL _F | AVSP and BVSP slew rate SetVID_Fast | | | SL _{SET} | | mV/µs |
| CI | AVCD and DVCD along my and a share | | | SL _{SET} / 4 | | mV/µs |
| SL _{S1} | AVSP and BVSP slew rate slow | | | SL _{SET} / 2 | | mV/μs |
| CI | AVSP and BVSP slew rate slew | MFR_SPEC_13<8> = 0b | | SL _{SET} / 4 | | mV/µs |
| rate soft-start | | MFR_SPEC_13<8> = 1b | | SL _{SET} / 16 | | mV/μs |

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6.18 Ramp Selections

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------|--------------|-------------------------|-----|-----|-----|------|
| | | MFR_SPEC_14<2:0> = 000b | 30 | 40 | 55 | mV |
| | | MFR_SPEC_14<2:0> = 001b | 70 | 80 | 95 | mV |
| | | MFR_SPEC_14<2:0> = 010b | 110 | 120 | 135 | mV |
| V | DAMD Cotting | MFR_SPEC_14<2:0> = 011b | 150 | 160 | 175 | mV |
| V_{RAMP} | RAMP Setting | MFR_SPEC_14<2:0> = 100b | 190 | 200 | 215 | mV |
| | | MFR_SPEC_14<2:0> = 101b | 230 | 240 | 255 | mV |
| | | MFR_SPEC_14<2:0> = 110b | 270 | 280 | 300 | mV |
| | | MFR_SPEC_14<2:0> = 111b | 305 | 320 | 335 | mV |

6.19 Dynamic Integration and Undershoot Reduction

 $T_A = 25^{\circ}C$ (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------|------------------------------|----------------------------|-----|-----|-----|------|
| | | MFR_SPEC_12<10:8> = 000b; | 90 | 100 | 116 | mV |
| | | MFR_SPEC_12<10:8> = 001b; | 135 | 150 | 175 | mV |
| VDVAL | | MFR_SPEC_12<10:8> = 010b; | 175 | 200 | 230 | mV |
| | Dynamic integration voltage | MFR_SPEC_12<10:8> = 011b; | 225 | 250 | 285 | mV |
| | setting | MFR_SPEC_12<10:8> = 100b; | 270 | 300 | 345 | mV |
| | | MFR_SPEC_12<10:8> = 101b; | 315 | 350 | 400 | mV |
| | | MFR_SPEC_12<10:8> = 110b; | 360 | 400 | 455 | mV |
| | | MFR_SPEC_12<10:8> = 111b; | | OFF | | mV |
| | | MFR_SPEC_12<7:4> = 0000b; | | 1 | | μs |
| | MFR_SPEC_12<7:4> = 0001b; | | 2 | | μs | |
| | MFR_SPEC_12<7:4> = 0010b; | | 3 | | μs | |
| | | MFR_SPEC_12<7:4> = 0011b; | | 4 | | μs |
| | | MFR_SPEC_12<7:4> = 0100b; | | 5 | | μs |
| | | MFR_SPEC_12<7:4> = 0101b; | | 6 | | μs |
| | | MFR_SPEC_12<7:4> = 0110b; | | 7 | | μs |
| | Dynamic integration time | MFR_SPEC_12<7:4> = 0111b; | | 8 | | μs |
| t _{DINT} | constant ⁽¹⁾ | MFR_SPEC_12<7:4> = 1000b; | | 12 | | μs |
| | | MFR_SPEC_12<7:4> = 1001b; | | 13 | | μs |
| | | MFR_SPEC_12<7:4> = 1010b; | | 14 | | μs |
| | | MFR_SPEC_12<7:4> = 1011b; | | 15 | | μs |
| | | MFR_SPEC_12<7:4> = 1100b; | | 16 | | μs |
| | | MFR_SPEC_12<7:4> = 1101b; | | 17 | | μs |
| | | MFR_SPEC_12<7:4> = 1110b; | | 18 | | μs |
| | | MFR_SPEC_12<7:4> = 1111b; | | 19 | | μs |
| | | MFR_SPEC_09<14:12> = 000b; | 120 | 140 | 160 | mV |
| | | MFR_SPEC_09<14:12> = 001b; | 155 | 180 | 205 | mV |
| | | MFR_SPEC_09<14:12> = 010b; | 190 | 220 | 245 | mV |
| 17 | LICE level 2 valtage cetting | MFR_SPEC_09<14:12> = 011b; | 230 | 260 | 290 | mV |
| V_{USR2} | USR level 2 voltage setting | MFR_SPEC_09<14:12> = 100b; | 265 | 300 | 335 | mV |
| | | MFR_SPEC_09<14:12> = 101b; | 300 | 340 | 375 | mV |
| | | MFR_SPEC_09<14:12> = 110b; | 335 | 380 | 420 | mV |
| | | MFR_SPEC_09<14:12> = 111b; | | OFF | | mV |

⁽¹⁾ Specified by design. Not production tested.



Dynamic Integration and Undershoot Reduction (continued)

 $T_A = 25$ °C (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---------------------------------|--------------------------|-----|-----|-----|--------|
| | | MFR_SPEC_09<2:0> = 000b; | 70 | 90 | 110 | mV |
| | | MFR_SPEC_09<2:0> = 001b; | 100 | 120 | 140 | mV |
| | | MFR_SPEC_09<2:0> = 010b; | 130 | 150 | 170 | mV |
| | LICE level 4 velters setting | MFR_SPEC_09<2:0> = 011b; | 160 | 180 | 205 | mV |
| V _{USR1} | USR level 1 voltage setting | MFR_SPEC_09<2:0> = 100b; | 185 | 210 | 240 | mV |
| | | MFR_SPEC_09<2:0> = 101b; | 215 | 240 | 270 | mV |
| | | MFR_SPEC_09<2:0> = 110b; | 240 | 270 | 305 | mV |
| | | MFR_SPEC_09<2:0> = 111b; | | OFF | | mV |
| DLI | Maximum phase added in USR | MFR_SPEC_09<5> = 0b; | | 3 | | phases |
| PH _{USR1} | level 1 ⁽¹⁾ | MFR_SPEC_09<5> = 1b; | | 4 | | phases |
| | | MFR_SPEC_09<4:3> = 00b; | 2 | 5 | 9 | mV |
| V _{OUSRHYS} | Dynamic integration/USR voltage | MFR_SPEC_09<4:3> = 01b; | 5 | 10 | 15 | mV |
| | hysteresis | MFR_SPEC_09<4:3> = 10b; | 10 | 15 | 20 | mV |
| | | MFR_SPEC_09<4:3> = 11b; | 15 | 20 | 25 | mV |

6.20 Boot Voltage and TMAX Settings

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN TYP I | MAX UNIT |
|-------------------|-----------------------------|-------------------------|-----------|----------|
| | | MFR_SPEC_12<2:0> = 000b | 90 | °C |
| T _{MAX} | | MFR_SPEC_12<2:0> = 001b | 95 | °C |
| | | MFR_SPEC_12<2:0> = 010b | 100 | °C |
| | Maximum tamparatura aatting | MFR_SPEC_12<2:0> = 011b | 105 | °C |
| | Maximum temperature setting | MFR_SPEC_12<2:0> = 100b | 110 | °C |
| | | MFR_SPEC_12<2:0> = 101b | 115 | °C |
| | | MFR_SPEC_12<2:0> = 110b | 120 | °C |
| | | MFR_SPEC_12<2:0> = 111b | 125 | °C |
| | | MFR_SPEC_11<7:0> = 00h | 0 | V |
| | BOOT voltage setting (10-mV | MFR_SPEC_11<7:0> = 74h | 1.65 | V |
| | DAC) | MFR_SPEC_11<7:0> = 79h | 1.7 | V |
| ., | | MFR_SPEC_11<7:0> = 7Eh | 1.75 | V |
| V _{BOOT} | | MFR_SPEC_11<7:0> = 00h | 0 | V |
| | BOOT voltage setting (5-mV | MFR_SPEC_11<7:0> = 83h | 0.9 | V |
| | DAC) | MFR_SPEC_11<7:0> = 97h | 1 | V |
| | | MFR_SPEC_11<7:0> = BFh | 1.2 | V |



6.21 Protections: OVP and UVP

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------|---|--|------|-----|--------------------|------|
| V_{RDYH5} | Tracking OVP | Measured at the VSP pin wrt VID code. Device latches OFF. | 330 | | 400 | mV |
| V_{RDYH0} | Tracking OVP | Measured at the VSP pin wrt VID code. Device latches OFF. | 140 | | 200 | mV |
| t _{RDYDGLTO} | VR_RDY deglitch time ⁽¹⁾ | | | | ⁽²⁾ 2.5 | μs |
| t _{RDYDGLTU} | VR_RDY deglitch time ⁽¹⁾ | f _{SW} = 500 kHz | | 4 | | μs |
| V _{RDYL} | Undervoltage protection (3) | (V _{VSP} + V _{DROOP}) with respect to VID | 370 | 400 | 430 | mV |
| V _{OVPA} | Fixed overvoltage protection, Channel A ⁽³⁾ | V_{AVSP} > V_{OVP} for 1 μ s, ENABLE = HI or LO, PWM to LO | 2.75 | 2.8 | 2.86 | V |
| V _{OVPB} | Fixed overvoltage protection, Channel B ⁽³⁾ | $V_{BVSP} > V_{OVP}$ for 1 μs , ENABLE = HI or LO, PWM to LO | 1.85 | 1.9 | 1.95 | V |

Specified by design. Not production tested.

Time from VSP out of +200 or +400 mV VDAC boundary to VR_RDY low. Can be programmed with different configurations.

6.22 Protections: ATSEN and BTSEN Pin Voltage Levels and Fault

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------|---------------------------------|----------------------------|-----|-----|-----|------|
| | | V _{TSEN} = 0.28 V | -42 | -40 | -38 | °C |
| | | V _{TSEN} = 0.8 V | 23 | 25 | 27 | °C |
| | The area of sections and Golden | V _{TSEN} = 1.2 V | 73 | 75 | 77 | °C |
| TSEN | Thermal voltage definition | V _{TSEN} = 1.4 V | 98 | 100 | 102 | °C |
| | | V _{TSEN} = 1.6 V | 123 | 125 | 127 | °C |
| | | V _{TSEN} = 1.8 V | 148 | 150 | 152 | °C |
| I _{TSEN} | TSEN leakage current | | -3 | | 3 | μΑ |

Product Folder Links: TPS53681

STRUMENTS



6.23 PWM: I/O Voltage and Current

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|-------------------------------|---|-----|------|-----|------|
| V_{PWML} | PWMx output low-level | $I_{LOAD} = 0.5 \text{ mA}$ | | 0.15 | 0.3 | V |
| V_{PWMH} | PWMx output high-level | $I_{LOAD} = -0.5 \text{ mA}; V_{V3P3} = 2.97 \text{ V}$ | 2.8 | | | V |
| V _{PW-SKLK} | PWMx tri-state | $I_{LOAD} = \pm 100 \mu A$ | 1.6 | 1.7 | 1.8 | V |
| t _{P-S_H-L} | PWMx H-L transition time (1) | C_{LOAD} = 10 pF, I_{LOAD} = ± 100 μ A, 10% to 90% both edges | | | 10 | ns |
| t _{P-S_TRI} | PWMx tri-state transition (1) | C_{LOAD} = 10 pF, I_{LOAD} = ± 100 μ A, 10% or 90% to tri-state, both edges | | | 10 | ns |

⁽¹⁾ Specified by design. Not production tested.



TEXAS INSTRUMENTS

6.24 Dynamic Phase Add and Drop

over recommended operating conditions (unless otherwise noted)

| Р | ARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--------------------------------------|--|-----|-----|-----|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 2 A; (MFR_SPECIFIC_15<4:3> = 00b); V _{RIPPLE} ≈ 18 A (estimation) | 21 | 23 | 25 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 4 A; (MFR_SPECIFIC_15<4:3> = 01b); $V_{RIPPLE} \approx 18 \text{ A (estimation)}$ | 23 | 25 | 27 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 6 A; (MFR_SPECIFIC_15<4:3> = 10b); V _{RIPPLE} ≈ 18 A (estimation) | 25 | 27 | 29 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 8 A; (MFR_SPECIFIC_15<4:3> = 11b); V _{RIPPLE} ≈ 18 A (estimation) | 27 | 29 | 31 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 2 A; (MFR_SPECIFIC_15<4:3> = 00b); V _{RIPPLE} ≈ 18 A (estimation) | 23 | 25 | 27 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 4 A; (MFR_SPECIFIC_15<4:3> = 01b); V _{RIPPLE} ≈ 18 A (estimation) | 25 | 27 | 29 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 6 A; (MFR_SPECIFIC_15<4:3> = 10b); $V_{RIPPLE} \approx 18$ A (estimation) | 27 | 29 | 31 | Α |
| V _{DPSTHA1} | Dynamic phase adding threshold, 1 to | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 8 A; (MFR_SPECIFIC_15<4:3> = 11b); $V_{RIPPLE} \approx 18$ A (estimation) | 29 | 31 | 33 | Α |
| VDPSTHA1 | 2 Phases (Peak Current) | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 2 A; (MFR_SPECIFIC_15<4:3> = 00b); V _{RIPPLE} ≈ 18 A (estimation) | 25 | 27 | 29 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 4 A; (MFR_SPECIFIC_15<4:3> = 01b); V _{RIPPLE} ≈ 18 A (estimation) | 27 | 29 | 31 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 6 A; (MFR_SPECIFIC_15<4:3> = 10b); $V_{RIPPLE} \approx 18$ A (estimation) | 29 | 31 | 33 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 8 A; (MFR_SPECIFIC_15<4:3> = 11b); V _{RIPPLE} ≈ 18 A (estimation) | 31 | 33 | 35 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 2 A; (MFR_SPECIFIC_15<4:3> = 00b); V _{RIPPLE} ≈ 18 A (estimation) | 27 | 29 | 31 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 4 A; (MFR_SPECIFIC_15<4:3> = 01b); V _{RIPPLE} ≈ 18 A (estimation) | 29 | 31 | 33 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 6 A; (MFR_SPECIFIC_15<4:3> = 10b); $V_{RIPPLE} \approx 18$ A (estimation) | 31 | 33 | 35 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 8 A; (MFR_SPECIFIC_15<4:3> = 11b); V _{RIPPLE} ≈ 18 A (estimation) | 33 | 35 | 37 | Α |



Dynamic Phase Add and Drop (continued)

over recommended operating conditions (unless otherwise noted)

| P | ARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|---|-----|-----|-----|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = -6 A; (MFR_SPECIFIC_15<14:13> = 00b) | 4 | 6 | 8 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = -4 A; (MFR_SPECIFIC_15<14:13> = 01b) | 6 | 8 | 10 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = -2 A; (MFR_SPECIFIC_15<14:13> = 10b) | 8 | 10 | 12 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 0 A; (MFR_SPECIFIC_15<14:13> = 11b) | 10 | 12 | 14 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = -6 A; (MFR_SPECIFIC_15<14:13> = 00b) | 6 | 8 | 10 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = -4 A; (MFR_SPECIFIC_15<14:13> = 01b) | 8 | 10 | 12 | А |
| | Dynamic phase shedding threshold, 2 to 1 phase (average current) | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = -2 A; (MFR_SPECIFIC_15<14:13> = 10b) | 10 | 12 | 14 | А |
| V | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 0 A; (MFR_SPECIFIC_15<14:13> = 11b) | 12 | 14 | 16 | Α |
| V _{DPSTHS1} | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = -6 A; (MFR_SPECIFIC_15<14:13> = 00b) | 8 | 10 | 12 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = -4 A; (MFR_SPECIFIC_15<14:13> = 01b) | 10 | 12 | 14 | А |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = -2 A; (MFR_SPECIFIC_15<14:13> = 10b) | 12 | 14 | 16 | А |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 0 A; (MFR_SPECIFIC_15<14:13> = 11b) | 14 | 16 | 18 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = -6 A; (MFR_SPECIFIC_15<14:13> = 00b) | 10 | 12 | 14 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = -4 A; (MFR_SPECIFIC_15<14:13> = 01b) | 12 | 14 | 16 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = -2 A; (MFR_SPECIFIC_15<14:13> = 10b) | 14 | 16 | 18 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 0 A; (MFR_SPECIFIC_15<14:13> = 11b) | 16 | 18 | 20 | А |





Dynamic Phase Add and Drop (continued)

over recommended operating conditions (unless otherwise noted)

| Р | ARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--------------------------------------|--|------|-----|------|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 4 A; (MFR_SPECIFIC_15<6:5> = 00b); VRIPPLE = 14 A (estimation) | 32.5 | 35 | 37.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 6 A; (MFR_SPECIFIC_15<6:5> = 01b); V _{RIPPLE} = 14 A (estimation) | 34.5 | 37 | 39.5 | А |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 8 A; (MFR_SPECIFIC_15<6:5> = 10b); V _{RIPPLE} = 14 A (estimation) | 36.5 | 39 | 41.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 10 A; (MFR_SPECIFIC_15<6:5> = 11b); V _{RIPPLE} = 14 A (estimation) | 38.5 | 41 | 43.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 4 A; (MFR_SPECIFIC_15<6:5> = 00b); V _{RIPPLE} = 14 A (estimation) | 36.5 | 39 | 41.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 6 A; (MFR_SPECIFIC_15<6:5> = 01b); V _{RIPPLE} = 14 A (estimation) | 38.5 | 41 | 43.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 8 A; (MFR_SPECIFIC_15<6:5> = 10b); VRIPPLE = 14 A (estimation) | 40.5 | 43 | 45.5 | Α |
| V | Dynamic phase adding threshold, 2 to | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 10 A; (MFR_SPECIFIC_15<6:5> = 11b); VRIPPLE = 14 A (estimation) | 42.5 | 45 | 47.5 | Α |
| V _{DPSTHA2} | 3 phases (Peak Current) | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 4 A; (MFR_SPECIFIC_15<6:5> = 00b); V _{RIPPLE} = 14 A (estimation) | 40.5 | 43 | 45.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 6 A; (MFR_SPECIFIC_15<6:5> = 01b); V _{RIPPLE} = 14 A (estimation) | 42.5 | 45 | 47.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 8 A; (MFR_SPECIFIC_15<6:5> = 10b); V _{RIPPLE} = 14 A (estimation) | 44.5 | 47 | 49.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 10 A; (MFR_SPECIFIC_15<6:5> = 11b); VRIPPLE = 14 A (estimation) | 46.5 | 49 | 51.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 4 A; (MFR_SPECIFIC_15<6:5> = 00b); V _{RIPPLE} = 14 A (estimation) | 44.5 | 47 | 49.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 6 A; (MFR_SPECIFIC_15<6:5> = 01b); V _{RIPPLE} = 14 A (estimation) | 46.5 | 49 | 51.5 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 8 A; (MFR_SPECIFIC_15<6:5> = 10b); VRIPPLE = 14 A (estimation) | 48.5 | 51 | 53.5 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 10 A; (MFR_SPECIFIC_15<6:5> = 11b); VRIPPLE = 14 A (estimation) | 50.5 | 53 | 55.5 | А |



Dynamic Phase Add and Drop (continued)

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|-------------------------------------|---|------|---------|------|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = -4 A; (MFR_SPECIFIC_14<9:8> = 00b) | 17.5 | 20 | 22.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = -2 A; (MFR_SPECIFIC_14<9:8> = 01b) | 19.5 | 22 | 24.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 0 A; (MFR_SPECIFIC_14<9:8> = 10b) | 21.5 | 24 | 26.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 2 A; (MFR_SPECIFIC_14<9:8> = 11b) | 23.5 | 26 | 28.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = -4 A; (MFR_SPECIFIC_14<9:8> = 00b) | 21.5 | 24 | 26.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = -2 A; (MFR_SPECIFIC_14<9:8> = 01b) | 23.5 | 26 | 28.5 | Α |
| | Dynamic phase shedding threshold, 3 | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 0 A; (MFR_SPECIFIC_14<9:8> = 10b) | 25.5 | 28 | 30.5 | Α |
| V | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 2 A; (MFR_SPECIFIC_14<9:8> = 11b) | 27.5 | 30 | 32.5 | Α |
| V _{DPSTHS2} | to 2 phases (average current) | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = -4 A; (MFR_SPECIFIC_14<9:8> = 00b) | 25.5 | 28 | 30.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = -2 A; (MFR_SPECIFIC_14<9:8> = 01b) | 27.5 | 30 | 32.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 0 A; (MFR_SPECIFIC_14<9:8> = 10b) | 29.5 | 32 | 34.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 2 A; (MFR_SPECIFIC_14<9:8> = 11b) | 31.5 | 31.5 34 | 36.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = -4 A; (MFR_SPECIFIC_14<9:8> = 00b) | 29.5 | 32 | 34.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = -2 A; (MFR_SPECIFIC_14<9:8> = 01b) | 31.5 | 34 | 36.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 0 A; (MFR_SPECIFIC_14<9:8> = 10b) | 33.5 | 36 | 38.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 2 A; (MFR_SPECIFIC_14<9:8> = 11b) | 35.5 | 38 | 40.5 | А |





Dynamic Phase Add and Drop (continued)

over recommended operating conditions (unless otherwise noted)

| Р | ARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|--|-----|-----|-----|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 6 A; (MFR_SPECIFIC_15<8:7> = 00b); V _{RIPPLE} = 10 A (estimation) | 44 | 47 | 50 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 8 A; (MFR_SPECIFIC_15<8:7> = 01b); V _{RIPPLE} = 10 A (estimation) | 46 | 49 | 52 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 10 A; (MFR_SPECIFIC_15<8:7> = 10b); V _{RIPPLE} = 10 A (estimation) | 48 | 51 | 54 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 12 A; (MFR_SPECIFIC_15<8:7> = 11b); V _{RIPPLE} = 10 A (estimation) | 50 | 53 | 56 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 6 A; (MFR_SPECIFIC_15<8:7> = 00b); V _{RIPPLE} = 10 A (estimation) | 50 | 53 | 56 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 8 A; (MFR_SPECIFIC_15<8:7> = 01b); V _{RIPPLE} = 10 A (estimation) | 52 | 55 | 58 | Α |
| | Dynamic phase adding threshold, 3 to 4 Phases (Peak Current) | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 10 A; (MFR_SPECIFIC_15<8:7> = 10b); V _{RIPPLE} = 10 A (estimation) | 54 | 57 | 60 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 12 A; (MFR_SPECIFIC_15<8:7> = 11b); V _{RIPPLE} = 10 A (estimation) | 56 | 59 | 62 | Α |
| V _{DPSTHA3} | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 6 A; (MFR_SPECIFIC_15<8:7> = 00b); V _{RIPPLE} = 10 A (estimation) | 56 | 59 | 62 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 8 A; (MFR_SPECIFIC_15<8:7> = 01b); V _{RIPPLE} = 10 A (estimation) | 58 | 61 | 64 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 10 A; (MFR_SPECIFIC_15<8:7> = 10b); V _{RIPPLE} = 10 A (estimation) | 60 | 63 | 66 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 12 A; (MFR_SPECIFIC_15<8:7> = 11b); V _{RIPPLE} = 10 A (estimation) | 62 | 65 | 68 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 6 A; (MFR_SPECIFIC_15<8:7> = 00b); V _{RIPPLE} = 10 A (estimation) | 62 | 65 | 68 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 8 A; (MFR_SPECIFIC_15<8:7> = 01b); V _{RIPPLE} = 10 A (estimation) | 64 | 67 | 70 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 10 A; (MFR_SPECIFIC_15<8:7> = 10b); V _{RIPPLE} = 10 A (estimation) | 66 | 69 | 72 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 12 A; (MFR_SPECIFIC_15<8:7> = 11b); V _{RIPPLE} = 10 A (estimation) | 68 | 71 | 74 | Α |



Dynamic Phase Add and Drop (continued)

over recommended operating conditions (unless otherwise noted)

| P | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|---|-----|-----|----------------------|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = -2 A; (MFR_SPECIFIC_14<11:10> = 00b) | 31 | 34 | 37 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 0 A; (MFR_SPECIFIC_14<11:10> = 01b) | 33 | 36 | 39 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 2 A; (MFR_SPECIFIC_14<11:10> = 10b) | 35 | 38 | 41 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 4 A; (MFR_SPECIFIC_14<11:10> = 11b) | 37 | 40 | 43 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = -2 A; (MFR_SPECIFIC_14<11:10> = 00b) | 37 | 40 | 43 | Α |
| | Dynamic phase shedding threshold, 4 to 3 phases (average current) | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 0 A; (MFR_SPECIFIC_14<11:10> = 01b) | 39 | 42 | 45 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 2 A; (MFR_SPECIFIC_14<11:10> = 10b) | 41 | 44 | 47 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 4 A; (MFR_SPECIFIC_14<11:10> = 11b) | 43 | 46 | 49 | Α |
| V _{DPSTHS3} | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = -2 A; (MFR_SPECIFIC_14<11:10> = 00b) | 43 | 46 | 49 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 0 A; (MFR_SPECIFIC_14<11:10> = 01b) | 45 | 48 | 51 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 2 A; (MFR_SPECIFIC_14<11:10> = 10b) | 47 | 50 | 53 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 4 A; (MFR_SPECIFIC_14<11:10> = 11b) | 49 | 52 | 47 49 49 51 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = -2 A; (MFR_SPECIFIC_14<11:10> = 00b) | 49 | 52 | 55 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 0 A; (MFR_SPECIFIC_14<11:10> = 01b) | 51 | 54 | 57 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 2 A; (MFR_SPECIFIC_14<11:10> = 10b) | 53 | 56 | 59 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 4 A; (MFR_SPECIFIC_14<11:10> = 11b) | 55 | 58 | 61 | Α |





Dynamic Phase Add and Drop (continued)

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|--|------|------|------|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 6 A; (MFR_SPECIFIC_15<10:9> = 00b); V _{RIPPLE} = 8 A (estimation) | 54.5 | 58 | 61.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 8 A; (MFR_SPECIFIC_15<10:9> = 01b); V _{RIPPLE} = 8 A (estimation) | 56.5 | 60 | 63.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 10 A; (MFR_SPECIFIC_15<10:9> = 10b); V _{RIPPLE} = 8 A (estimation) | 58.5 | 62 | 65.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 12 A; (MFR_SPECIFIC_15<10:9> = 11b); V _{RIPPLE} = 8 A (estimation) | 60.5 | 64 | 67.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 6 A; (MFR_SPECIFIC_15<10:9> = 00b); V _{RIPPLE} = 8 A (estimation) | 62.5 | 66 | 69.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 8 A; (MFR_SPECIFIC_15<10:9> = 01b); V _{RIPPLE} = 8 A (estimation) | 64.5 | 68 | 71.5 | Α |
| | Dynamic phase adding threshold, 4 to 5 Phases (Peak Current) | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 10 A; (MFR_SPECIFIC_15<10:9> = 10b); V _{RIPPLE} = 8 A (estimation) | 66.5 | 70 | 73.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 12 A; (MFR_SPECIFIC_15<10:9> = 11b); V _{RIPPLE} = 8 A (estimation) | 68.5 | 72 | 75.5 | Α |
| V _{DPSTHA4} | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 6 A; (MFR_SPECIFIC_15<10:9> = 00b); V _{RIPPLE} = 8 A (estimation) | 70.5 | 74 | 77.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 8 A; (MFR_SPECIFIC_15<10:9> = 01b); V _{RIPPLE} = 8 A (estimation) | 72.5 | 76 | 79.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 10 A; (MFR_SPECIFIC_15<10:9> = 10b); V _{RIPPLE} = 8 A (estimation) | 74.5 | 78 | 81.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 12 A; (MFR_SPECIFIC_15<10:9> = 11b); V _{RIPPLE} = 8 A (estimation) | 76.5 | 80 | 83.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 6 A; (MFR_SPECIFIC_15<10:9> = 00b); VRIPPLE = 8 A (estimation) 78.5 | 82 | 85.5 | Α | |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 8 A; (MFR_SPECIFIC_15<10:9> = 01b); V _{RIPPLE} = 8 A (estimation) | 80.5 | 84 | 87.5 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 10 A; (MFR_SPECIFIC_15<10:9> = 10b); V _{RIPPLE} = 8 A (estimation) | 82.5 | 86 | 89.5 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 12 A; (MFR_SPECIFIC_15<10:9> = 11b); V _{RIPPLE} = 8 A (estimation) | 84.5 | 88 | 91.5 | А |



Dynamic Phase Add and Drop (continued)

over recommended operating conditions (unless otherwise noted)

| P | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|-------------------------------------|---|------|-----|------|--------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = -2 A; (MFR_SPECIFIC_14<13:12> = 00b) | 42.5 | 46 | 49.5 | А |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 0 A; (MFR_SPECIFIC_14<13:12> = 01b) | 44.5 | 48 | 51.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 2 A; (MFR_SPECIFIC_14<13:12> = 10b) | 46.5 | 50 | 53.5 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 4 A; (MFR_SPECIFIC_14<13:12> = 11b) | 48.5 | 52 | 55.5 | A A |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = -2 A; (MFR_SPECIFIC_14<13:12> = 00b) | 50.5 | 54 | 57.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 0 A; (MFR_SPECIFIC_14<13:12> = 01b) | 52.5 | 56 | 59.5 | Α |
| | Dynamic phase shedding threshold, 5 | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 2 A; (MFR_SPECIFIC_14<13:12> = 10b) | 54.5 | 58 | 61.5 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 4 A; (MFR_SPECIFIC_14<13:12> = 11b) | 56.5 | 60 | 63.5 | Α |
| V _{DPSTHS4} | to 4 phases (average current) | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = -2 A; (MFR_SPECIFIC_14<13:12> = 00b) | 58.5 | 62 | 65.5 | А |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 0 A; (MFR_SPECIFIC_14<13:12> = 01b) | 60.5 | 64 | 67.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 2 A; (MFR_SPECIFIC_14<13:12> = 10b) | 62.5 | 66 | 69.5 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 4 A; (MFR_SPECIFIC_14<13:12> = 11b) | 64.5 | 68 | 71.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = -2 A; (MFR_SPECIFIC_14<13:12> = 00b) | 66.5 | 70 | 73.5 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 0 A; (MFR_SPECIFIC_14<13:12> = 01b) | 68.5 | 72 | 75.5 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 2 A; (MFR_SPECIFIC_14<13:12> = 10b) | 70.5 | 74 | 77.5 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 4 A; (MFR_SPECIFIC_14<13:12> = 11b) | 72.5 | 76 | 79.5 | Α |





Dynamic Phase Add and Drop (continued)

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|---|-----|-----|-----|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 6 A; (MFR_SPECIFIC_15<12:11> = 00b); V _{RIPPLE} = 6 A (estimation) | 65 | 69 | 73 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 8 A; (MFR_SPECIFIC_15<12:11> = 01b); V _{RIPPLE} = 6 A (estimation) | 67 | 71 | 75 | А |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 10 A; (MFR_SPECIFIC_15<12:11> = 10b); V _{RIPPLE} = 6 A (estimation) | 69 | 73 | 77 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 12 A; (MFR_SPECIFIC_15<12:11> = 11b); V _{RIPPLE} = 6 A (estimation) | 71 | 75 | 79 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 6 A; (MFR_SPECIFIC_15<12:11> = 00b); V _{RIPPLE} = 6 A (estimation) | 75 | 79 | 83 | А |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 8 A; (MFR_SPECIFIC_15<12:11> = 01b); V _{RIPPLE} = 6 A (estimation) | 77 | 81 | 85 | Α |
| | Dynamic phase adding threshold, 5 to 6 Phases (Peak Current) | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 10 A; (MFR_SPECIFIC_15<12:11> = 10b); V _{RIPPLE} = 6 A (estimation) | 79 | 83 | 87 | Α |
| V | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 12 A; (MFR_SPECIFIC_15<12:11> = 11b); V _{RIPPLE} = 6 A (estimation) | 81 | 85 | 89 | Α |
| V _{DPSTHA5} | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 6 A; (MFR_SPECIFIC_15<12:11> = 00b); V _{RIPPLE} = 6 A (estimation) | 85 | 89 | 93 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 8 A; (MFR_SPECIFIC_15<12:11> = 01b); V _{RIPPLE} = 6 A (estimation) | 87 | 91 | 95 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 10 A; (MFR_SPECIFIC_15<12:11> = 10b); V _{RIPPLE} = 6 A (estimation) | 89 | 93 | 97 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 12 A; (MFR_SPECIFIC_15<12:11> = 11b); V _{RIPPLE} = 6 A (estimation) | | 99 | Α | |
| | 11b); Offset = 6 A; (MFR_SPECIFIC_15<1 00b); V _{RIPPLE} = 6 A (estimation) Peak Efficiency = 18 A; (MFR_SPECIFIC_ | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 6 A; (MFR_SPECIFIC_15<12:11> = 00b); V _{RIPPLE} = 6 A (estimation) | 95 | 99 | 103 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 8 A; (MFR_SPECIFIC_15<12:11> = 01b); V _{RIPPLE} = 6 A (estimation) | 97 | 101 | 105 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 10 A; (MFR_SPECIFIC_15<12:11> = 10b); V _{RIPPLE} = 6 A (estimation) | 99 | 103 | 107 | А |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 12 A; (MFR_SPECIFIC_15<12:11> = 11b); V _{RIPPLE} = 6 A (estimation) | 101 | 105 | 109 | Α |



Dynamic Phase Add and Drop (continued)

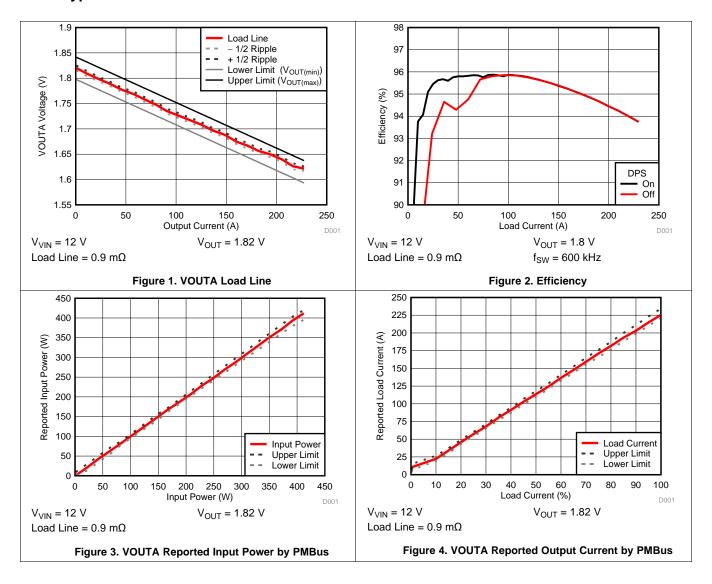
over recommended operating conditions (unless otherwise noted)

| P | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|---|-----|-----|-----|------|
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = -2 A; (MFR_SPECIFIC_14<15:14> = 00b) | 54 | 58 | 62 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 0 A; (MFR_SPECIFIC_14<15:14> = 01b) | 56 | 60 | 64 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 2 A; (MFR_SPECIFIC_14<15:14> = 10b) | 58 | 62 | 66 | Α |
| | | Peak Efficiency = 12 A; (MFR_SPECIFIC_15<1:0> = 00b); Offset = 4 A; (MFR_SPECIFIC_14<15:14> = 11b) | 60 | 64 | 68 | А |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = -2 A; (MFR_SPECIFIC_14<15:14> = 00b) | 64 | 68 | 72 | Α |
| | Dynamic phase shedding threshold, 6 to 5 phases (average current) | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 0 A; (MFR_SPECIFIC_14<15:14> = 01b) | 66 | 70 | 74 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 2 A; (MFR_SPECIFIC_14<15:14> = 10b) | 68 | 72 | 76 | Α |
| | | Peak Efficiency = 14 A; (MFR_SPECIFIC_15<1:0> = 01b); Offset = 4 A; (MFR_SPECIFIC_14<15:14> = 11b) | 70 | 74 | 78 | Α |
| V _{DPSTHS5} | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = -2 A; (MFR_SPECIFIC_14<15:14> = 00b) | 74 | 78 | 82 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 0 A; (MFR_SPECIFIC_14<15:14> = 01b) | 76 | 80 | 84 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 2 A; (MFR_SPECIFIC_14<15:14> = 10b) | 78 | 82 | 86 | Α |
| | | Peak Efficiency = 16 A; (MFR_SPECIFIC_15<1:0> = 10b); Offset = 4 A; (MFR_SPECIFIC_14<15:14> = 11b) | 80 | 84 | 88 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = -2 A; (MFR_SPECIFIC_14<15:14> = 00b) | 84 | 88 | 92 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 0 A; (MFR_SPECIFIC_14<15:14> = 01b) | 86 | 90 | 94 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 2 A; (MFR_SPECIFIC_14<15:14> = 10b) | 88 | 92 | 96 | Α |
| | | Peak Efficiency = 18 A; (MFR_SPECIFIC_15<1:0> = 11b); Offset = 4 A; (MFR_SPECIFIC_14<15:14> = 11b) | 90 | 94 | 98 | А |

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TEXAS INSTRUMENTS

6.25 Typical Characteristics





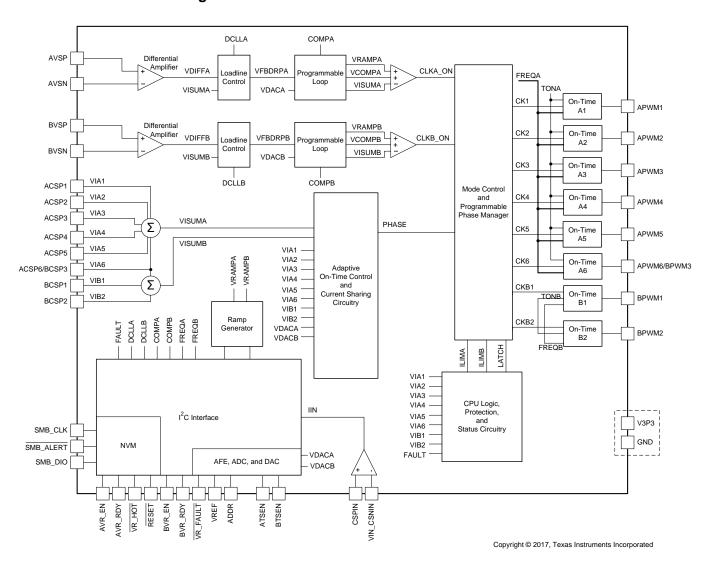
7 Detailed Description

7.1 Overview

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The TPS53681 is a multiphase step-down controller with dual channels, built-in non-volatile memory (NVM), and PMBus[™] interface, and is fully compatible with TI NexFET [™] power stages. Advanced control features such as D-CAP+[™] architecture with undershoot reduction (USR) provide transient response,

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Phase Interleaving and PWM Operation

As shown in the *Overview* section, in 8-phase continuous conduction mode, the device operates as described in Figure 5.

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TEXAS INSTRUMENTS

Feature Description (continued)

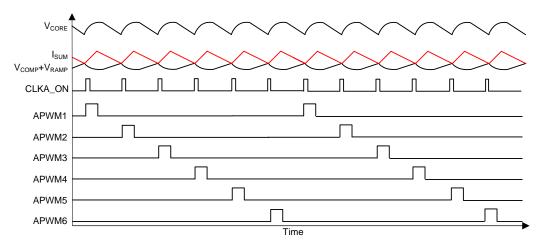


Figure 5. D-CAP+ Mode Basic Waveforms

Starting with the condition that the high-side FETs are off and the low-side FETs are on, the summed current feedback (V_{ISUM}) is higher than the summed error amplifier output (V_{COMP}) and the internal ramp signal (V_{RAMP}). I_{SUM} falls until it hits $V_{COMP}+V_{RAMP}$, which contains a component of the output ripple voltage. The PWM comparator senses where the two waveforms cross and triggers the on-time generator. This generates the internal CLKA_ON signal. Each CLKA_ON signal corresponds to one switching ON pulse for one phase.

In case of single-phase operation, every CLKA_ON signal generates a switching pulse on the same phase. Also, V_{ISUM} corresponds to just a single-phase inductor current.

In case of multi-phase operation, the CLKA_ON signal gets distributed to each of the phases in a cycle. This approach of using the summed inductor current and cyclically distributing the ON pulses to each phase automatically gives the required interleaving of 360 / n, where n is the number of phases.

7.3.1.1 Setting the Load-Line (DROOP)

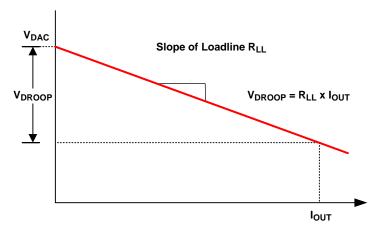


Figure 6. Load Line

The loadline can be set with VOUT_DROOP register via PMBus. The programmable range for channel A is between 0 m Ω and 3.125 m Ω with 64 options, and the range for channel B is between 0 m Ω and 0.875 m Ω with 16 options to fulfill the requirements for different applications.



Feature Description (continued)

7.3.1.2 Load Transitions

When there is a sudden load increase, the output voltage immediately drops. The TPS53681 device reacts to this drop in a rising voltage on the COMP pin. This rise forces the PWM pulses to come in sooner and more frequently which causes the inductor current to rapidly increase. As the inductor current reaches the new load current, the device reaches a steady-state operating condition and the PWM switching resumes the steady-state frequency.

When there is a sudden load release, the output voltage flies high. The TPS53681 device reacts to this rise in a falling voltage on the COMP pin. This drop forces the PWM pulses to be delayed until the inductor current reaches the new load current. At that point, the switching resumes and steady-state switching continues.

Please note in Figure 7 and Figure 8, the ripples on V_{OUT} , V_{RAMP} , and V_{COMP} voltages are not shown for simplicity.

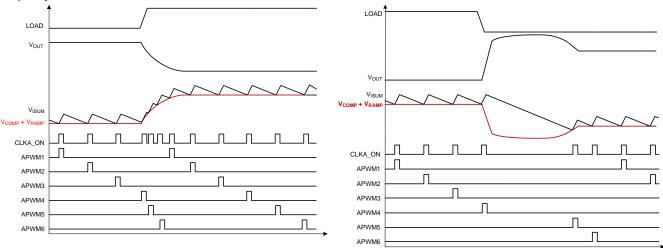


Figure 7. Load Insertion

Figure 8. Load Release

The TPS53681 achieves fast load transient performance using the inherent variable switching frequency characteristics. Figure 7 illustrates the load insertion behavior that the PWM pulses can be generated with faster frequency than the steady-state frequency to provide more energy to improve the undershoot performance. Figure 8 illustrates the load release behavior that PWM pulses can be gated to avoid charging extra energy to the load until the output voltage reaches the peak overshoot.

7.3.1.2.1 VID Table

The DAC voltage V_{DAC} can be changed via PMBus according to Table 2 .



Table 2. VID Table

DAC STEP **VID Hex DAC STEP VALUE** (5 mV) (10 mV) 00 0 0 0.25 0.50 01 0.255 0.51 02 0.26 0.52 03 04 0.265 0.53 05 0.27 0.54 06 0.275 0.55 0.28 0.56 07 0.285 0.57 80 09 0.29 0.58 0A 0.295 0.59 0B 0.30 0.60 0.305 0.61 0C 0D 0.31 0.62 0E 0.315 0.63 0F 0.32 0.64 0.65 10 0.325 11 0.33 0.66 12 0.335 0.67 13 0.34 0.68 14 0.345 0.69 15 0.35 0.70 0.355 0.71 16 0.36 17 0.72 18 0.365 0.73 19 0.37 0.74 1A 0.375 0.75 0.38 0.76 1B 0.385 0.77 1C 1D 0.39 0.78 0.395 0.79 1E 0.40 1F 0.80 0.405 0.81 20 0.41 21 0.82 22 0.415 0.83 23 0.42 0.84 24 0.425 0.85 0.43 25 0.86 26 0.435 0.87 27 0.44 0.88 28 0.445 0.89 0.45 29 0.90 2A 0.455 0.91 0.46 2B 0.92 2C 0.465 0.93 2D 0.47 0.94 0.95 2E 0.475

Table 2. VID Table (continued)

| | bie 2. VID Table (CC | - |
|------------------|----------------------|---------------------|
| VID Hex VALUE | DAC STEP (5 mV) | DAC STEP (10 mV) |
| 2F | 0.48 | 0.96 |
| 30 | 0.485 | 0.97 |
| 31 | 0.49 | 0.98 |
| 32 | 0.495 | 0.99 |
| 33 | 0.50 | 1.00 |
| 34 | 0.505 | 1.01 |
| 35 | 0.51 | 1.02 |
| 36 | 0.515 | 1.03 |
| 37 | 0.52 | 1.04 |
| 38 | 0.525 | 1.05 |
| 39 | 0.53 | 1.06 |
| 3A | 0.535 | 1.07 |
| 3B | 0.54 | 1.08 |
| 3C | 0.545 | 1.09 |
| 3D | 0.55 | 1.10 |
| 3E | 0.555 | 1.11 |
| 3F | 0.56 | 1.12 |
| 40 | 0.565 | 1.13 |
| 41 | 0.57 | 1.14 |
| 42 | 0.575 | 1.15 |
| 43 | 0.58 | 1.16 |
| 44 | 0.585 | 1.17 |
| 45 | 0.59 | 1.18 |
| 46 | 0.595 | 1.19 |
| 47 | 0.60 | 1.20 |
| 48 | 0.605 | 1.21 |
| 49 | 0.61 | 1.22 |
| 4A | 0.615 | 1.23 |
| 4B | 0.62 | 1.24 |
| 4C | 0.625 | 1.25 |
| 4D | 0.63 | 1.26 |
| 4E | 0.635 | 1.27 |
| 4F | 0.64 | 1.28 |
| 50 | 0.645 | 1.29 |
| 51 | 0.65 | 1.30 |
| 52 | 0.655 | 1.31 |
| 53 | 0.66 | 1.32 |
| 54 | 0.665 | 1.33 |
| 55 | 0.67 | 1.34 |
| 56 | 0.675 | 1.35 |
| 57 | 0.68 | 1.36 |
| 58 | 0.685 | 1.37 |
| 59 | 0.69 | 1.38 |
| 5A | 0.695 | 1.39 |
| 5B | 0.70 | 1.40 |
| 5C | 0.705 | 1.41 |
| 5D | 0.71 | 1.42 |

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77

78

79 7A

7B

7C

7D

7E 7F

80

81

82 83

84

85

86

87

88 89

8A 8B

8C



Table 2. VID Table (continued)

VID Hex DAC STEP DAC STEP VALUE (5 mV) (10 mV) 0.715 1.43 5E 1.44 5F 0.72 60 0.725 1.45 0.73 61 1.46 1.47 0.735 62 0.74 1.48 63 0.745 64 1.49 0.75 1.50 65 66 0.755 1.51 0.76 1.52 67 0.765 68 1.53 0.77 1.54 69 6A 0.775 1.55 0.78 6B 1.56 6C 0.785 1.57 0.79 1.58 6D 0.795 1.59 6E 6F 0.80 1.60 70 0.805 1.61 0.81 1.62 71 72 0.815 1.63 0.82 1.64 73 74 0.825 1.65 75 0.83 1.66 76 0.835 1.67

0.84

0.845

0.85

0.855

0.86 0.865

0.87

0.875

0.88

0.885

0.89

0.895

0.90

0.905

0.91

0.915

0.92

0.925

0.93

0.935

0.94

1.68

1.69 1.70

1.71 1.72

1.73

1.74

1.75

1.76

1.77

1.78

1.79

1.80

1.81

1.82

1.83

1.84

1.85

1.86

1.87

1.88

1.89

Table 2. VID Table (continued)

| | DIE Z. VID TABLE (CC | |
|------------------|----------------------|---------------------|
| VID Hex VALUE | DAC STEP (5 mV) | DAC STEP (10 mV) |
| 8D | 0.95 | 1.90 |
| 8E | 0.955 | 1.91 |
| 8F | 0.96 | 1.92 |
| 90 | 0.965 | 1.93 |
| 91 | 0.97 | 1.94 |
| 92 | 0.975 | 1.95 |
| 93 | 0.98 | 1.96 |
| 94 | 0.985 | 1.97 |
| 95 | 0.99 | 1.98 |
| 96 | 0.995 | 1.99 |
| 97 | 1.00 | 2.00 |
| 98 | 1.005 | 2.01 |
| 99 | 1.01 | 2.02 |
| 9A | 1.015 | 2.03 |
| 9B | 1.02 | 2.04 |
| 9C | 1.025 | 2.05 |
| 9D | 1.03 | 2.06 |
| 9E | 1.035 | 2.07 |
| 9F | 1.04 | 2.08 |
| A0 | 1.045 | 2.09 |
| A1 | 1.05 | 2.10 |
| A2 | 1.055 | 2.11 |
| A3 | 1.06 | 2.12 |
| A4 | 1.065 | 2.13 |
| A5 | 1.07 | 2.14 |
| A6 | 1.075 | 2.15 |
| A7 | 1.08 | 2.16 |
| A8 | 1.085 | 2.17 |
| A9 | 1.09 | 2.18 |
| AA | 1.095 | 2.19 |
| AB | 1.10 | 2.20 |
| AC | 1.105 | 2.21 |
| AD | 1.11 | 2.22 |
| AE | 1.115 | 2.23 |
| AF | 1.12 | 2.24 |
| В0 | 1.125 | 2.25 |
| B1 | 1.13 | 2.26 |
| B2 | 1.135 | 2.27 |
| B3 | 1.14 | 2.28 |
| B4 | 1.145 | 2.29 |
| B5 | 1.15 | 2.30 |
| B6 | 1.155 | 2.31 |
| В7 | 1.16 | 2.32 |
| B8 | 1.165 | 2.33 |
| B9 | 1.17 | 2.34 |
| BA | 1.175 | 2.35 |
| BB | 1.18 | 2.36 |
| | | |

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Table 2. VID Table (continued)

VID Hex VALUE DAC STEP DAC STEP (5 mV) (10 mV) ВС 1.185 2.37 BD 1.19 2.38 ΒE 1.195 2.39 1.20 BF 2.40 1.205 2.41 C0 C1 1.21 2.42 1.215 2.43 C2 1.22 C3 2.44 1.225 C4 2.45 C5 1.23 2.46 1.235 C6 2.47 C7 1.24 2.48 C8 1.245 2.49 1.25 C9 2.50 1.255 CA n/a 1.26 СВ n/a CC 1.265 n/a CD 1.27 n/a CE 1.275 n/a 1.28 CF n/a D0 1.285 n/a 1.29 D1 n/a 1.295 D2 n/a 1.30 D3 n/a D4 1.305 n/a 1.31 D5 n/a D6 1.315 n/a D7 1.32 n/a D8 1.325 n/a D9 1.33 n/a 1.335 DA n/a 1.34 DB n/a DC 1.345 n/a 1.35 DD n/a

Table 2. VID Table (continued)

| VID Hex VALUE | DAC STEP (5 mV) | DAC STEP (10 mV) |
|------------------|--------------------|---------------------|
| DE | 1.355 | n/a |
| DF | 1.36 | n/a |
| E0 | 1.365 | n/a |
| E1 | 1.37 | n/a |
| E2 | 1.375 | n/a |
| E3 | 1.38 | n/a |
| E4 | 1.385 | n/a |
| E5 | 1.39 | n/a |
| E6 | 1.395 | n/a |
| E7 | 1.40 | n/a |
| E8 | 1.405 | n/a |
| E9 | 1.41 | n/a |
| EA | 1.415 | n/a |
| EB | 1.42 | n/a |
| EC | 1.425 | n/a |
| ED | 1.43 | n/a |
| EE | 1.435 | n/a |
| EF | 1.44 | n/a |
| F0 | 1.445 | n/a |
| F1 | 1.45 | n/a |
| F2 | 1.455 | n/a |
| F3 | 1.46 | n/a |
| F4 | 1.465 | n/a |
| F5 | 1.47 | n/a |
| F6 | 1.475 | n/a |
| F7 | 1.48 | n/a |
| F8 | 1.485 | n/a |
| F9 | 1.49 | n/a |
| FA | 1.495 | n/a |
| FB | 1.50 | n/a |
| FC | 1.505 | n/a |
| FD | 1.51 | n/a |
| FE | 1.515 | n/a |
| FF | 1.52 | n/a |

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7.3.1.3 Temperature and Fault Sensing

TI smart power stage senses the die temperature and sends out the temperature information as a voltage through the TAO pin. In a multi-phase application, the TAO pin of the TI smart power stages are connected and then tied to the ATSEN and BTSEN pins of the TPS53681 device. In this case, the device reports the temperature of the hottest power stage. The reported temperature can be calculated as shown in Equation 1.

$$TEMP = \frac{(V_{TSEN} - 0.6)}{0.008}$$

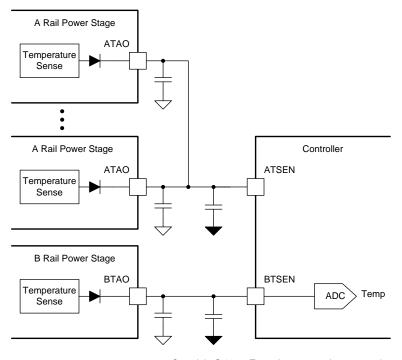
where

- TEMP is the sensed temperature in °C
- V_{TSEN} is the voltage at ATSEN and BTSEN pins

(1)

TSEN signal is also used as an indicator for power stage fault. When an internal fault occurs in the TI smart power stage, the power stage pulls the xTAO pins high. If the TSEN voltage is higher than 2.5 V, the TPS53681 device senses the fault and turns off both the high-side and the low-side MOSFETS.

The TSEN signal is also used to indicate hand-shaking between the controller and the power stages. If the power stages are not powered, the TAO pin is pulled down to prevent switching, even if the controller is enabled.



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Figure 9. Temperature Sense

7.3.1.4 AutoBalance™ Current Sharing

The basic mechanism for current sharing is to sense the average phase current, then adjust the pulse width of each phase to equalize the current in each phase as shown in Figure 10. The PWM comparator (not shown) starts a pulse when the feedback voltage meets the reference. The V_{IN} voltage charges $C_{t(on)}$ through $R_{t(on)}$. The pulse terminates when the voltage at Ct(on) matches the on-time reference, which normally equals the DAC voltage (V_{DAC}).

The circuit operates in the following fashion. First assume that the 1-µs averaged value from each phase current are equal. In this case, the PWM modulator terminates at V_{DAC}, and the normal pulse width is delivered to the system. If instead, $I1 > I_{AVG}$, then an offset is subtracted from V_{DAC} , and the pulse width for Phase 1 is shortened to reduce the phase current in Phase 1 for balancing. If $I1 < I_{AVG}$, then a longer pulse is generated to increase the phase current in Phase 1 to achieve current balancing.



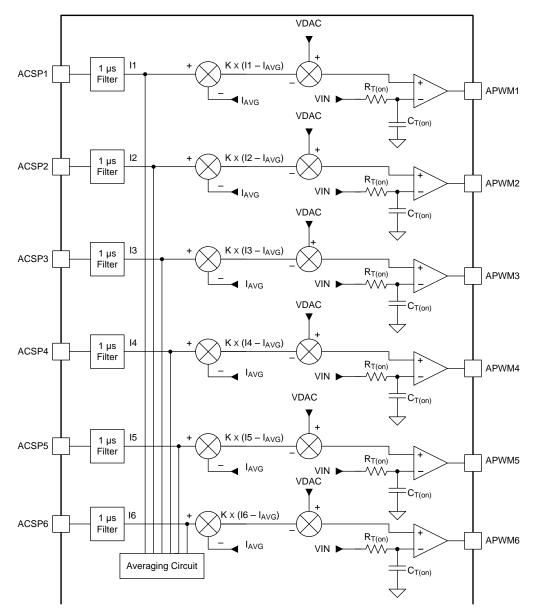


Figure 10. AutoBalance Current Sharing Circuit Detail

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7.3.1.5 Phase Configuration for Channel B

By default, the second rail of the TPS53681 is configured for two-phase operation. Two NVM bits, CHB_2PH and CHB_3PH control the number of phases available to channel B. The CHB_2PH bit is found in MFR_SPECIFIC_13 (bit 12), and the CHB_3PH bit is found in USER_DATA_11. See Table 3 below, which describes these bit settings, versus phase configuration for channel B. Refer to the accompanying *Technical Reference Manual* for a register map of MFR_SPECIFIC_13 and USER_DATA_11. Refer to Current Sense Inputs for Active Phases for information about pin configuration of CSP signals for various channel B phase configuration settings.

| 5 to 1 to | | | | | | |
|---|---|-----------------------------------|--|--|--|--|
| Channel B Phases | CHB_2PH MFR_SPECIFIC_13[PAGE0][12] USER_DATA_11[PAGE0][9] | CHB_3PH USER_DATA_11[PAGE0][9] | | | | |
| 1 | 1b | 0b | | | | |
| 2 | 0b | 0b | | | | |
| 3 | 0b | 1b | | | | |

Table 3. Channel B Phase Configuration

7.3.1.6 RESET Function

During adaptive voltage scaling (AVS) operation, the voltage may become falsely adjusted to be out of ASIC operating range. The RESET function returns the voltage to the VBOOT voltage. When the voltage is out of ASIC operating range, the ASIC issues a RESET signal to the TPS53681 device, as shown in Figure 11. The device senses this signal and after a delay of greater than 1 µs, it sets an internal RESET_FAULT signal and sets VOUT_COMMAND to VBOOT. The device pulls the output voltage to the VBOOT level with the slew rate set by VOUT_TRANSITION_RATE command, as shown in Figure 12.

When the RESET pin signal goes high, the internal RESET FAULT signal goes low.

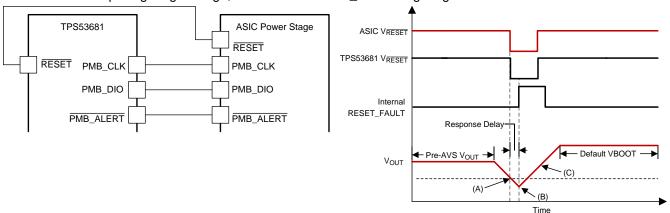


Figure 11. RESET Pin Connection

Figure 12. Reset Function

7.4 Device Functional Modes

7.5 Programming

7.5.1 PMBus Connections

The TPS53681 device can support either 100kHz class, 400 kHz class or 1 MHz class operation, with 1.8-V or 3.3-V logic levels. Connection for the PMBus interface should follow the DC specifications given in *Section 4.3 of the System Management Bus (SMBus) Specification V3.0*. The complete SMBus specification is available from the SMBus website, smbus.org.

7.5.2 PMBus Address Selection

The PMBus slave addresses for TPS53681 are selected with a resistor divider from VREF to ADDR.

TEXAS INSTRUMENTS

Programming (continued)

The PMBus slave address is set by the voltage on the ADDR pin. Refer to Table 4. With the desired PMBus address, and R_{ADDRL} selected, calculate the R_{ADDRH} using Equation 2.

Note that TPS53681 uses 7 bit addressing, per the SMBus specification. Users communicating to the device using generic I^2C drivers should be aware that these 7 bits occupy the most significant bits of the first byte in each transaction, with the least significant bit being the data direction bit (0 for write operations, 1 for read operations). That is, for read transactions, the address byte is $A_6A_5A_4A_3A_2A_1A_01$ and for write operations the address byte is $A_6A_5A_4A_3A_2A_1A_00$. Refer to the SMBus specification for more information.

The general procedure for selecting these resistors is as follows:

- 1. Determine the desired PMBus slave addresses, per system requirements
- 2. Select an R_{ADDRI} value of 10 $k\Omega$ or 20 $k\Omega$
- 3. Using the desired PMBus address, refer to Table 4 for the desired address pin voltage
- 4. Use Equation 2 to calculate R_{ADDRH}

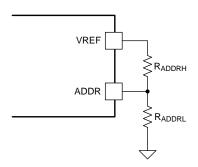


Figure 13. PMBus Address Selection

Contact your local Texas Instruments representative for a copy of the PMBus address setting design tool spreadsheet.

$$R_{ADDRH} \; = R_{ADDRL} \; \Big(\frac{V_{REF}}{V_{ADDR}} - 1 \Big)$$

(2)

Table 4 PMRus Slave Address Selection

| Table 4. FMBus Slave Address Selection | | | | | | | |
|--|---|----------------------------------|--|---|--|--|--|
| V _{ADDR} (V) | PMBus Address (7 bit binary) A ₆ A ₅ A ₄ A ₃ A ₂ A ₁ A ₀ | PMBus Address (7-bit decimal) | I ² C Address Byte (Write Operation) | I ² C Address Byte (Read Operation) | | | |
| ≤ 0.039 V | 1011000b | 88d | B0h | B1h | | | |
| 0.073 V ± 15 mV | 1011001b | 89d | B2h | B3h | | | |
| 0.122 V ± 15 mV | 1011010b | 90d | B4h | B5h | | | |
| 0.171 V ± 15 mV | 1011011b | 91d | B6h | B7h | | | |
| 0.219 V ± 15 mV | 1011100b | 92d | B8h | B9h | | | |
| 0.268 V ± 15 mV | 1011101b | 93d | BAh | BBh | | | |
| 0.317 V ± 15 mV | 1011110b | 94d | BCh | BDh | | | |
| 0.366 V ± 15 mV | 1011111b | 95d | BEh | BFh | | | |
| 0.415 V ± 15 mV | 1100000b | 96d | C0h | C1h | | | |
| 0.464 V ± 15 mV | 1100001b | 97d | C2h | C3h | | | |
| 0.513 V ± 15 mV | 1100010b | 98d | C4h | C5h | | | |
| 0.562 V ± 15 mV | 1100011b | 99d | C6h | C7h | | | |
| 0.610 V ± 15 mV | 1100100b | 100d | C8h | C9h | | | |
| 0.660 V ± 15 mV | 1100101b | 101d | CAh | CBh | | | |
| 0.708 V ± 15 mV | 1100110b | 102d | CCh | CDh | | | |

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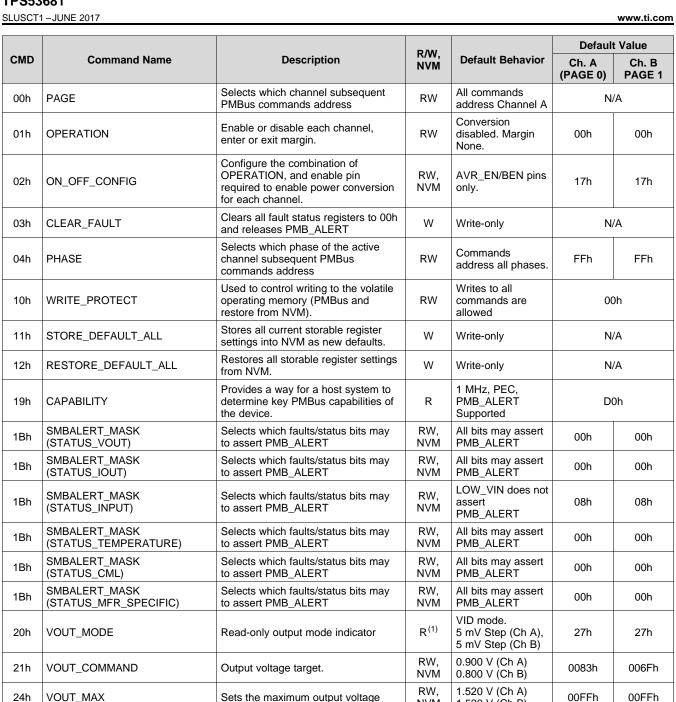


Table 4. PMBus Slave Address Selection (continued)

| V _{ADDR} (V) | PMBus Address (7 bit binary) A ₆ A ₅ A ₄ A ₃ A ₂ A ₁ A ₀ | PMBus Address (7-bit decimal) | I ² C Address Byte (Write Operation) | I ² C Address Byte (Read Operation) |
|-----------------------|---|----------------------------------|--|---|
| 0.757 V ± 15 mV | 1100111b | 103d | CEh | CFh |
| 0.806 V ± 15 mV | 1101000b | 104d | D0h | D1h |
| 0.854 V ± 15 mV | 1101001b | 105d | D2h | D3h |
| 0.903 V ± 15 mV | 1101010b | 106d | D4h | D5h |
| 0.952 V ± 15 mV | 1101011b | 107d | D6h | D7h |
| 1.000 V ± 15 mV | 1101100b | 108d | D8h | D9h |
| 1.050 V ± 15 mV | 1101101b | 109d | DAh | DBh |
| 1.098 V ± 15 mV | 1101110b | 110d | DCh | DDh |
| 1.147 V ± 15 mV | 1101111b | 111d | DEh | DFh |
| 1.196 V ± 15 mV | 1110000b | 112d | E0h | E1h |
| 1.245 V ± 15 mV | 1110001b | 113d | E2h | E3h |
| 1.294 V ± 15 mV | 1110010b | 114d | E4h | E5h |
| 1.343 V ± 15 mV | 1110011b | 115d | E6h | E7h |
| 1.392 V ± 15 mV | 1110100b | 116d | E8h | E9h |
| 1.440 V ± 15 mV | 1110101b | 117d | EAh | EBh |
| 1.489 V ± 15 mV | 1110110b | 118d | ECh | EDh |
| 1.540 V ± 15 mV | 1110111b | 119d | EEh | EFh |

7.5.3 Supported Commands

The table below summarizes the PMBus commands supported by the TPS53681. Only selected commands, which are most commonly used during device configuration and usage are reproduced in this document. For a full set of register maps for this device, refer to the accompanying *Technical Reference Manual*.



Load the unit with the voltage to

Load the unit with the voltage to which the output is to be changed

Used to set slew rate settings for

to "Margin High".

to "Margin Low".

output voltage updates

which the output is to be changed

when OPERATION command is set

when OPERATION command is set

NVM

RW

RW

RW.

NVM

1.520 V (Ch B)

0.000 V (CH A)

0.000 V (Ch B)

0.000 V (CH A)

0.000 V (Ch B)

10 mV/µs (Ch A)

10 mV/µs (Ch B)

Product Folder Links: TPS53681

VOUT_MARGIN_HIGH

VOUT_MARGIN_LOW

VOUT_TRANSITION_RATE

0000h

0000h

E0A0h

0000h

0000h

E0A0h

ISTRUMENTS

25h

26h

27h

⁽¹⁾ NVM-backed bits in the MFR_SPECIFIC or USER_DATA commands affect the reset value of these commands. Refer to the individual register maps for more detail.



| | | | D.644 | | Default | t Value |
|-----|------------------------|---|---------------------------|---|-------------------|-----------------|
| CMD | Command Name | Description | R/W, NVM | Default Behavior | Ch. A (PAGE 0) | Ch. B PAGE 1 |
| 28h | VOUT_DROOP | The VOUT_DROOP sets the rate, in mV/A (m Ω) at which the output voltage decreases (or increases) with increasing (or decreasing) output current for use with Adaptive Voltage Positioning | RW, NVM | 0.000 mΩ (Ch A) 0.000 mΩ (Ch B) | D000h | D000h |
| 29h | VOUT_SCALE_LOOP | Used for scaling the VID code | RW, NVM | 1.000 (Ch A) 1.000 (Ch B) | E808h | E808h |
| 2Ah | VOUT_SCALE_MONITOR | Used for scaling output voltage telemetry | RW, NVM | 1.000 (Ch A) 1.000 (Ch B) | E808h | E808h |
| 2Bh | VOUT_MIN | Sets the minimum output voltage | RW, NVM | 0.000 V (Ch A) 0.000 V (Ch B) | 0000h | 0000h |
| 33h | FREQUENCY_SWITCH | Sets the switching frequency | RW, NVM | 500 kHz (Ch A) 500 kHz (Ch B) | 01F4h | 01F4h |
| 35h | VIN_ON | Sets value of input voltage at which the device should start power conversion. | RW, NVM | 10.25 V | F02 | 29h |
| 38h | IOUT_CAL_GAIN | Sets the ratio of voltage at the current sense pins to the sensed current. | RW, NVM | 5.000 m Ω (Ch A) 5.000 m Ω (Ch B) | D140h | D140h |
| 39h | IOUT_CAL_OFFSET | Used to null offsets in the output current sensing circuit | RW, NVM | 0.000 A (Ch A) 0.000 A (Ch B) (All Phases) | E800h | E800h |
| 40h | VOUT_OV_FAULT_LIMIT | Sets the value of the sensed output voltage which triggers an output overvoltage fault | R | 1.520 V (Ch A) 1.520 V (Ch B) | 00FFh | 00FFh |
| 41h | VOUT_OV_FAULT_RESPONSE | Sets the converter response to an output overvoltage event | R | Shutdown, do not restart | 80h | 80h |
| 44h | VOUT_UV_FAULT_LIMIT | Sets the value of the sensed output voltage which triggers an output undervoltage fault | R | 0.000 V (Ch A) 0.000 V (Ch B) | 0000h | 0000h |
| 45h | VOUT_UV_FAULT_RESPONSE | Sets the converter response to an output undervoltage event | RW, NVM | Shutdown, do not restart | 80h | 80h |
| 46h | IOUT_OC_FAULT_LIMIT | Sets the output Over Current fault limit | RW, NVM ⁽¹⁾ | 382 A (Ch A) 135 A (Ch B) | 017Eh | 0087h |
| 47h | IOUT_OC_FAULT_RESPONSE | Define the over-current fault response. | RW, NVM | Shutdown, do not restart | C0h | C0h |
| 4Ah | IOUT_OC_WARN_LIMIT | Sets the value of the output current that causes the over current detector to indicate an over current warning. | RW, NVM ⁽¹⁾ | 255 A (Ch A) 90 A (Ch B) | 00FFh | 005Ah |
| 4Fh | OT_FAULT_LIMIT | Sets the temperature, in degrees Celsius, of the unit at which it should indicate an Over temperature Fault. | RW, NVM ⁽¹⁾ | 115 °C (Ch A) 115 °C (Ch B) | 0073h | 0073h |
| 50h | OT_FAULT_RESPONSE | Sets the converter response to an over temperature fault. | RW, NVM | Shutdown, do not restart | 80h | 80h |
| 51h | OT_WARN_LIMIT | Sets the temperature, in degrees Celsius, of the unit at which it should indicate an Over temperature warning. | RW | 105 °C (Ch A) 105 °C (Ch B) | 0069h 0069h | |
| 55h | VIN_OV_FAULT_LIMIT | Set the voltage, in volts, of the unit at which it should indicate a Vin Overvoltage Fault. | RW, NVM | 17.000 V | 0011h | |
| 56h | VIN_OV_FAULT_RESPONSE | Instructs the device on what action to take in response to an input overvoltage fault. | R | Continue Uninterrupted | 00 |)h |
| 59h | VIN_UV_FAULT_LIMIT | Sets the value of the input voltage that causes an Input Under voltage Fault | RW, NVM | 9.500 V | F81 | 13h |
| 5Ah | VIN_UV_FAULT_RESPONSE | Sets the converter response to an input undervoltage event | R | Shutdown, do not restart | C | Oh |



| J i3 | Texas |
|-------------|-------------|
| ·A | Instruments |

| | | | | | Default V | /alue |
|-----|-----------------------|---|-------------|------------------------------------|----------------------|-----------------|
| CMD | Command Name | Description | R/W, NVM | Default Behavior | Ch. A (PAGE 0) | Ch. B PAGE 1 |
| 5Bh | IIN_OC_FAULT_LIMIT | Sets the value in amperes that causes the over current fault condition of the input current | RW, NVM | 63.5 A | F87F | h |
| 5Ch | IIN_OC_FAULT_RESPONSE | Sets the converter response to input overcurrent events | R | Shutdown, do not restart | C0h | |
| 5Dh | IIN_OC_WARN_LIMIT | Sets the value in amperes that causes the over current warning condition of the input current | RW, NVM | 56.0 A | F870 | h |
| 60h | TON_DELAY | Sets the time, in milliseconds, from when a start condition is received (as programmed by the ON_OFF_CONFIG command) until the output voltage starts to rise. | RW, NVM | 0.480 ms (Ch A) 0.896 ms (Ch B) | B1ECh | B396h |
| 6Bh | PIN_OP_WARN_LIMIT | The PIN_OP_WARN_LIMIT command sets the value of the input power, in watts, that causes a warning that the input power is high | RW | 450 W | 08E1 | h |
| 78h | STATUS_BYTE | PMBus read-only status and flag bits. | RW | Current Status | N/A | N/A |
| 79h | STATUS_WORD | PMBus read-only status and flag bits. | RW | Current Status | N/A | N/A |
| 7Ah | STATUS_VOUT | PMBus read-only status and flag bits. | RW | Current Status | N/A | N/A |
| 7Bh | STATUS_IOUT | PMBus read-only status and flag bits. | RW | Current Status | N/A | N/A |
| 7Ch | STATUS_INPUT | PMBus read-only status and flag bits. | RW | Current Status | N/A | |
| 7Dh | STATUS_TEMPERATURE | PMBus read-only status and flag bits. | RW | Current Status | N/A | N/A |
| 7Eh | STATUS_CML | PMBus read-only status and flag bits. | RW | Current Status | N/A | |
| 80h | STATUS_MFR_SPECIFIC | PMBus read-only status and flag bits. | RW | Current Status | N/A | N/A |
| 88h | READ_VIN | Returns the input voltage in volts | R | Current Status | N/A | |
| 89h | READ_IIN | Returns the input current in amperes | R | Current Status | N/A | |
| 8Bh | READ_VOUT | Returns the output voltage in VID format | R | Current Status | N/A | N/A |
| 8Ch | READ_IOUT | Returns the output current in amperes | R | Current Status | N/A | N/A |
| 8Dh | READ_TEMPERATURE_1 | Returns the highest power stage temperature in °C | R | Current Status | N/A | N/A |
| 96h | READ_POUT | Returns the output power in Watts | R | Current Status | N/A | N/A |
| 97h | READ_PIN | Returns the input power in Watts | R | Current Status | N/A | |
| 98h | PMBUS_REVISION | Returns the version of the PMBus specification to which this device complies | R | PMBus 1.3 Part I, Part II | 33h | |
| 99h | MFR_ID | Loads the unit with bits that contain the manufacturer's ID | RW, NVM | Arbitrary NVM for user | 0000 | h |
| 9Ah | MFR_MODEL | Loads the unit with bits that contain the manufacturer's model number | RW, NVM | Arbitrary NVM for user | 0000 | h |
| 9Bh | MFR_REVISION | Loads the unit with bits that contain the manufacturer's model revision | RW, NVM | Arbitrary NVM for user | 0400h | |
| 9Dh | MFR_DATE | Loads the unit with bits that contain the manufacture date | RW, NVM | March 2017 | 1103h | |
| 9Eh | MFR_SERIAL | NVM Checksum | R | NVM checksum | 679E8B7Dh | |
| ADh | IC_DEVICE_ID | Returns a number indicating the part number of the device | R | TPS53681 | 81h | |
| AEh | IC_DEVICE_REV | Returns a number indicating the device revision | R | Rev 1.0 | 00h | |
| B0h | USER_DATA_00 | Used for batch NVM programming. | RW NVM | Current configuration | Factory D Setting | |
| B1h | USER_DATA_01 | Used for batch NVM programming. | RW NVM | Current configuration | Factory D Setting | |

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| | | | B 0.1. | | Defaul | Value |
|-----|-----------------|--|---------------|---|-----------------------------|-----------------|
| CMD | Command Name | Description | R/W, NVM | Default Behavior | Ch. A (PAGE 0) | Ch. B PAGE 1 |
| B2h | USER_DATA_02 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| B3h | USER_DATA_03 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| B4h | USER_DATA_04 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| B5h | USER_DATA_05 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| B6h | USER_DATA_06 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| B7h | USER_DATA_07 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| B8h | USER_DATA_08 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| B9h | USER_DATA_09 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | Default ings |
| BAh | USER_DATA_10 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| BBh | USER_DATA_11 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Sett | |
| BCh | USER_DATA_12 | Used for batch NVM programming. | RW NVM | Current configuration | Factory Default Settings | |
| D0h | MFR_SPECIFIC_00 | Configures per-phase overcurrent levels, current share thresholds, and other miscellaneous settings. | RW NVM | Misc. configuration, See register maps | 003Eh | 203Dh |
| D3h | MFR_SPECIFIC_03 | Returns information regarding current imbalance warnings for each phase | R | Current status | N/A | N/A |
| D4h | MFR_SPECIFIC_04 | Returns the output voltage for the active channel, in linear format | R | Current status | N/A | N/A |
| D5h | MFR_SPECIFIC_05 | Used to trim the output voltage of the active channel, by applying an offset to the currently selected VID code. | RW NVM | 0 mV offset (Ch A and Ch B) | 00h | 00h |
| D6h | MFR_SPECIFIC_06 | Configures dynamic load line options for both channels, and selects Auto-DCM operation. | RW NVM | Misc. configuration, See register maps | 0605h | 1000h |
| D7h | MFR_SPECIFIC_07 | Configures the internal loop compensation for both channels. | RW NVM | Misc. configuration, See to register maps | 0886h | 0186h |
| D8h | MFR_SPECIFIC_08 | Used to identify catastrophic faults which occur first, and store this information to NVM | RW NVM | Current status | 00h | 00h |
| D9h | MFR_SPECIFIC_09 | Used to configure non-linear transient performance enhancements such as undershoot reduction (USR) | RW NVM | Misc. configuration, See register maps | 46C5h | 00C7h |
| DAh | MFR_SPECIFIC_10 | Used to configure input current sensing, and set the maximum output current | RW NVM | Misc. configuration, See register maps | C8FFh | 005Ah |
| DBh | MFR_SPECIFIC_11 | Boot-up VID code for each channel | RW NVM | VID 131d (Ch A) VID 111d (Ch B) | 83h | 6Fh |
| DCh | MFR_SPECIFIC_12 | Used to configure input current sensing and other miscellaneous settings | RW NVM | Misc. configuration, See register maps | D570h | 07F0 |
| DDh | MFR_SPECIFIC_13 | Used to configure output voltage slew rates, DAC stepsize, and other miscellaneous settings. | RW NVM | Misc. configuration, See register maps | 84E5h | 00E5h |

FAh

MFR_SPECIFIC_42



| | | | DAM | | Default Value | |
|-----|-----------------|--|-------------|---|-------------------|-----------------|
| CMD | Command Name | Command Name Description NVM | R/W, NVM | Default Behavior | Ch. A (PAGE 0) | Ch. B PAGE 1 |
| DEh | MFR_SPECIFIC_14 | Used to configure dynamic phase shedding, and compensation ramp amplitude, and dynamic ramp amplitude during USR, and different power states | RW NVM | Misc. configuration, See register maps | 0004h | 0004h |
| DFh | MFR_SPECIFIC_15 | Used to configure dynamic phase shedding. | RW NVM | Misc. configuration, See register maps | 1FFAh | 0000h |
| E4h | MFR_SPECIFIC_20 | Used to set the maximum operational phase number, on-the-fly. | RW NVM | Misc. configuration, See register maps | Hardware | Configured |
| F0h | MFR_SPECIFIC_32 | Used to set the input over-power warning | RW | 450 W | 000 | =1h |

NVM Security

RW NVM

NVM Security Key

Product Folder Links: TPS53681

Texas Instruments

0000h



7.5.4 Commonly Used PMBus Commands

The following sections describe the most commonly used PMBus commands and their usage in the configuration, operation and testing of TPS53681 power solutions:

- Voltage, Current, Power, and Temperature Readings
- Input Current Sense and Calibration
- Output Current Sense and Calibration
- Output Voltage Margin Testing
- Loop Compensation
- Converter Protection and Response
- Dynamic Phase Shedding
- NVM Programming
- NVM Security
- · Black Box Fault Recording
- Board Identification and Inventory Tracking
- Status Reporting

TEXAS INSTRUMENTS

7.5.5 Voltage, Current, Power, and Temperature Readings

Using an internal ADC, the TPS53681 provides a full set of telemetry capabilities, allowing the user to read back critical information about the converter's input voltage, input current, input power, output voltage, output current, output power and temperature. The table below summarizes the available commands and their formats. Register maps for each command are included.

Table 5. Telemetry Functions

| Command | Description | Format | Units | Channel/Phase |
|--------------------|--|--------|----------|---|
| READ_VIN | Input voltage telemetry | Linear | V | Shared, Channel A and B |
| READ_IIN | Input current telemetry | Linear | Α | Shared, Channel A and B |
| READ_VOUT | Output voltage telemetry (VID format) | VID | VID Code | Per Channel |
| READ_IOUT | Output current telemetry | Linear | Α | Per Channel and Per Phase |
| READ_TEMPERATURE_1 | Power stage temperature telemetry | Linear | °C | Per Channel, Highest phase temperature only |
| READ_POUT | Output power telemetry | Linear | W | Per Channel |
| READ_PIN | Input power telemetry | Linear | W | Shared, Channel A and B |
| MFR_SPECIFIC_04 | Output voltage telemetry (linear format) | Linear | V | Per Channel |

7.5.5.1 (88h) READ_VIN

The READ_VIN command returns the input voltage in volts. The two data bytes are formatted in the Linear Data format. The refresh rate is 1200 µs. This command should be accessed through Read Word transactions, and is shared between channel A and channel B.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | |
|----|--------------|--------------|----|----|----|---|---|--|--|
| R | R | R | R | R | R | R | R | | |
| | | READ_VIN_MAN | | | | | | | |
| 7 | 2 | 1 | 0 | | | | | | |
| R | R | R | R | R | R | | | | |
| | READ_VIN_MAN | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

READ_VIN

Table 6. READ_VIN Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|--------------|------|-------------------|--|
| 15:11 | READ_VIN_EXP | R | Current Status | Linear two's complement format exponent. |
| 10:0 | READ_VIN_MAN | R | Current Status | Linear two's complement format mantissa. |

7.5.5.2 (89h) READ_IIN

The READ_IIN command returns the input current in amperes. The refresh rate is 100 µs. The two data bytes are formatted in the Linear Data format. This command should be accessed through Read Word transactions, and is shared between channel A and channel B.



| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | |
|--------------|----|--------------|--------------|----|----|---|---|--|
| R | R | R | R | R | R | R | R | |
| | | READ_IIN_EXP | READ_IIN_MAN | | | | | |
| 7 6 5 4 3 | | | | | 2 | 1 | 0 | |
| R | R | R | R | R | R | | | |
| READ_IIN_MAN | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

READ IIN

Table 7. READ_IIN Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|--------------|------|-------------------|--|
| 15:11 | READ_IIN_EXP | R | Current Status | Linear two's complement format exponent. |
| 10:0 | READ_IIN_MAN | R | Current Status | Linear two's complement format mantissa. |

7.5.5.3 (8Bh) READ_VOUT

The READ_VOUT command returns the actual, measured output voltage. The two data bytes are formatted in the VID Data format, and the refresh rate is 1200 us. This command should be accessed through Read Word transactions. READ_VOUT is a paged register. In order to access READ_VOUT command for channel A, PAGE must be set to 00h. In order to access READ_VOUT register for channel B, PAGE must be set to 01h.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | | |
|----|---------------|----|----|----|----|---|---|--|--|--|
| R | R | R | R | R | R | R | R | | | |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | |
| R | R | R | R | R | R | R | R | | | |
| | READ_VOUT_VID | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

READ_VOUT

Table 8. READ_VOUT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|---------------|------|-------------------|----------------------------|
| 7:0 | READ_VOUT_VID | R | Current Status | Output voltage, VID format |

7.5.5.4 (8Ch) READ_IOUT

The READ_IOUT command returns the output current in amperes.

READ IOUT is a linear format command.

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READ_IOUT is a paged register. In order to access READ_IOUT for channel A, PAGE must be set to 00h. In order to access the READ_IOUT register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh. READ_IOUT is also a phased register. Depending on the configuration of the design, for channel A, PHASE must be set to 00h to access Phase 1, 01h to access Phase 2, etc... PHASE must be set to FFh to access all phases simultaneously. PHASE may also be set to 80h to readack the total phase current (sum of all active phase currents for the active channel) measurement, as described in Output Current Sense and Calibration. Note that READ_IOUT is only a phased command for Channel A (PAGE 0).

The READ IOUT command must be accessed through Read Word transactions.



| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|-----------|----|---------------|---------------|---------|----|---|---|
| R | R | R | R | R | R | R | R |
| | | READ_IOUT_EXF | READ_IOUT_MAN | | | | |
| 7 6 5 4 3 | | | | | 2 | 1 | 0 |
| R | R | R | R | R | R | | |
| | | | READ_IC | DUT_MAN | | | |

LEGEND: R/W = Read/Write; R = Read only

READ_IOUT

Table 9. READ_IOUT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|---------------|------|-------------------|--|
| 15:11 | READ_IOUT_EXP | R | Current Status | Linear two's complement format exponent. |
| 10:0 | READ_IOUT_MAN | R | Current Status | Linear two's complement format mantissa. |

Attempts to write to this command results in invalid transactions. The device ignores the invalid data, sets the appropriate flags in STATUS_CML and STATUS_WORD, and asserts the PMB_ALERT signal to notify the system host of an invalid transaction.

7.5.5.5 (8Dh) READ_TEMPERATURE_1

The READ_TEMPERATURE_1 command returns the temperature in degree Celsius. The two data bytes are formatted in the Linear Data format. The refresh rate is 1200 us.

READ TEMPERATURE 1 is a linear format command.

READ_TEMPERATURE_1 is a paged register. In order to access OPERATION command for channel A, READ_TEMPERATURE_1 must be set to 00h. In order to access READ_TEMPERATURE_1 register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

The READ_TEMPERATURE_1 command must be accessed through Read Word transactions.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | |
|----|---------------|---------------|----|----|----|---|---|--|--|
| R | R | R | R | R | R | R | R | | |
| | F | READ_TEMP_MAN | | | | | | | |
| 7 | 2 | 1 | 0 | | | | | | |
| R | R | R | R | R | | | | | |
| | READ_TEMP_MAN | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

READ_TEMPERATURE_1

Table 10. READ_TEMPERATURE_1 Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|---------------|------|-------------------|--|
| 15:11 | READ_TEMP_EXP | R | Current Status | Linear two's complement format exponent. |
| 10:0 | READ_TEMP_MAN | R | Current Status | Linear two's complement format mantissa. |

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Attempts to write to this command results in invalid transactions. The device ignores the invalid data, sets the appropriate flags in STATUS_CML and STATUS_WORD, and asserts the PMB_ALERT signal to notify the system host of an invalid transaction

7.5.5.6 (96h) READ POUT

The READ_POUT command returns the calculated output power, in watts for the active channel. The refresh rate is 1200 µs.

READ POUT is a linear format command.

READ_POUT is a paged register. In order to access READ_POUT command for channel A, PAGE must be set to 00h. In order to access READ_POUT register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

The READ_POUT command must be accessed through Read Word transactions.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|-----|----|---------------|----|----|----|---|---|
| R | R | R | R | R | R | R | R |
| | ſ | READ_POUT_MAN | | | | | |
| 7 | 2 | 1 | 0 | | | | |
| P | P | R | R | R | R | | |
| IX. | 11 | 11 | | | | | |

LEGEND: R/W = Read/Write; R = Read only

READ POUT

Table 11. READ_POUT Register Field Descriptions

| Bit | Field | Type Reset Description | | Description |
|-------|---------------|------------------------|-------------------|--|
| 15:11 | READ_POUT_EXP | R | Current Status | Linear two's complement format exponent. |
| 10:0 | READ_POUT_MAN | R | Current Status | Linear two's complement format mantissa. |

Attempts to write to this command results in invalid transactions. The device ignores the invalid data, sets the appropriate flags in STATUS_CML and STATUS_WORD, and asserts the PMB_ALERT signal to notify the system host of an invalid transaction

7.5.5.7 (97h) READ_PIN

The READ_PIN command returns the calculated input power. The refresh rate is 1200 µs.

READ PIN is a linear format command.

The READ PIN command must be accessed through Read Word transactions.

The READ_PIN command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|----|----|--------------|----|--------------|----|---|---|
| R | R | R | R | R | R | R | R |
| | | READ_PIN_EXP | | READ_PIN_MAN | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| | | _ | | _ | _ | | _ |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only



READ PIN

Table 12. READ_PIN Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|--------------|------|-------------------|--|
| 15:11 | READ_PIN_EXP | R | Current Status | Linear two's complement format exponent. |
| 10:0 | READ_PIN_MAN | R | Current Status | Linear two's complement format mantissa. |

7.5.5.8 (D4h) MFR_SPECIFIC_04

The MFR_SPECIFIC_04 command is used to return the output voltage for the active channel, in the **linear** format (READ_VOUT uses VID format).

The MFR_SPECIFIC_04 command must be accessed through Read Word transactions.

MFR_SPECIFIC_04 is a Linear format command.

MFR_SPECIFIC_04 is a paged register. In order to access MFR_SPECIFIC_04 command for channel A, PAGE must be set to 00h. In order to access the MFR_SPECIFIC_04 register for channel B, PAGE must be set to 01h.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|-----|-----|--------------|----|--------------|----|----|----|
| R | R | R | R | R | R | R | R |
| | | VOUT_LIN_EXP | | VOUT_LIN_MAN | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| D | D | D | R | R | R | R | R |
| IX. | IX. | IX. | 11 | 1. | 1. | 11 | 1. |

LEGEND: R/W = Read/Write; R = Read only

MFR_SPECIFIC_04

Table 13. MFR_SPECIFIC_04 Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|--------------|------|-------------------|--|
| 15:11 | VOUT_LIN_EXP | R | Current Status | Linear format two's complement exponent. |
| 10:0 | VOUT_LIN_MAN | R | Current Status | Linear format two's complement mantissa. |

7.5.6 Input Current Sense and Calibration

The READ_IIN command reports the total input current to both channels. TPS53681 supports shunt or inductor DCR sensing. The section below describes how to calibrate the gain and offset of the sensed signal for accurate input current reporting. When input current sensing is not used, the CSPIN and VIN_CSNIN pins should be shorted together and connected to the power input voltage.

7.5.6.1 Measured Input Current Calibration

The TPS53681 reports input current via an integrated current sense interface on the CSPIN and VIN_CSNIN pins. A conceptual block diagram is shown in Figure 14. This circuit must be calibrated to the value of the sense element, R_{SENSE} (e.g. shunt resistance or DCR), chosen. The values of A_{IIN} , IIN_MAX and IIN_OFS may be used to calibrate input current sensing. These settings are programmed using the MFR_SPECIFIC_10 and MFR_SPECIFIC_12 commands.

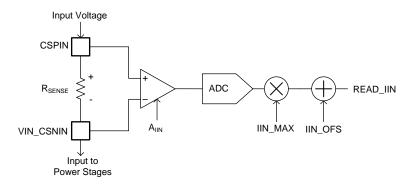


Figure 14. Measured Input Current Interface

The IIN_RGAIN bits in MFR_SPECIFIC_12, and the IIN_GAIN_CTRL bit in MFR_SPECIFIC_10 select A_{IIN} , the gain of the analog input current sense interface. Refer to Table 18 for a table of supported A_{IIN} values. Note that the analog gain setting also corresponds to maximum allowed signal level and measured input current according to Table 14.

| IIN_GAIN_CTRL (MFR_SPECIFIC_10) | IIN_RGAIN (MFR_SPECIFIC_12) | Effective A _{IIN} | Maximum Supported (CSPIN-VIN_CSNIN) Voltage | Maximum Supported Input Current Measurement |
|----------------------------------|------------------------------|----------------------------|---|---|
| 0b | 00b | $0.15~\text{m}\Omega$ | 7.5 mV | 50.0 A |
| 0b | 01b | $0.25~\text{m}\Omega$ | 12.5 mV | 50.0 A |
| 0b | 10b | $0.3~\text{m}\Omega$ | 15.0 mV | 50.0 A |
| 0b | 11b | $0.5~\text{m}\Omega$ | 25.0 mV | 50.0 A |
| 1b | 00b | 1.2 m Ω | 7.5 mV | 6.25 A |
| 1b | 01b | 2.0 mΩ | 12.5 mV | 6.25 A |
| 1b | 10b | 2.4 mΩ | 15.0 mV | 6.25 A |
| 1b | 11b | 4.0~mΩ | 25.0 mV | 6.25 A |

Table 14. A_{IIN}, Input Current Sense Analog Gain

The IIN_MAX bits in MFR_SPECIFIC_10 may also be used to digitally calibrate the gain of the input current reporting. Changing IIN_MAX allows the user to achieve fine gain calibration of the input current sense circuit, as well as support sense element resistor values other than those directly supported using A_{IIN} .

The nominal value of IIN_MAX is 50d. When the sense element resistance and A_{IIN} are equal, IIN_MAX should remain set to 50d. Changing IIN_MAX adjusts the current sense gain ratiometrically with respect to the nominal value of 50d. For example, changing IIN_MAX to 25d, reduces the effective gain by a factor of 2, and changing IIN_MAX to 10d, reduces the effective gain by a factor of 5. IIN_MAX has a maximum value of 64d. When using a sense element R_{SENSE} not equal to one of the supported A_{IIN} values, the IIN_MAX register must be adjusted according to Equation 3 to achieve accurate gain calibration.

$$IIN_MAX = 50d \times \frac{A_{IIN}}{R_{SENSE}}$$

(3)

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The IIN OFS bits in MFR SPECIFIC 10 may also be used to apply an offset to the sensed current in amperes.

Example #1: 0.5 m Ω R_{SENSE}

With a 0.5 m Ω sense element value, for example, (V_{CSPIN} - V_{VIN_CSNIN}) = 10 mV corresponds to 20 A current. Select the analog interface gain, A_{IIN} =0.5 m Ω , since this selection is available in Table 18, and do not apply any scaling via IIN_MAX (set it to 50d).

- 1. Select the value of A_{IIN} that most closely matches the target sense resistance. In this case, A_{IIN} = 0.5 m Ω is available, which gives IIN_RGAIN = 11b, and IIN_GAIN_CTRL = 0b.
- 2. Set IIN_MAX = $50d \times (0.5 \text{ m}\Omega / 0.5 \text{ m}\Omega) = 50d$
- 3. Set IIN_OFS = 0 A to start with, and tune as needed based on measurements.

Example #2: 1.0 m Ω R_{SENSE}

With a 1.0 m Ω sense element value, for example, (V_{CSPIN} - V_{VIN_CSNIN}) = 10 mV corresponds to 10 A current. With the analog interface gain, A_{IIN} set to 0.5 m Ω , 10 mV would be interpreted as 20 A. Therefore apply IIN_MAX = 50*(0.5 m Ω / 1 m Ω) to reduce the effective gain by a factor of 2, so 10 mV is interpreted as 10 A.

- 1. Select the value of A_{IIN} that most closely matches the target sense resistance. In this case, 1.0 m Ω is not directly available. Select $A_{IIN}=0.5$ m Ω , which gives IIN_RGAIN = 11b, and IIN_GAIN_CTRL = 0b.
- 2. Set IIN_MAX = $50d \times (0.5 \text{ m}\Omega / 1.0 \text{ m}\Omega) = 25d$
- 3. Set IIN_OFS = 0 A to start with, and tune as needed based on measurements.

7.5.6.2 (DAh) MFR_SPECIFIC_10

The MFR_SPECIFIC_10 command is used to configure input current sensing, and set the maximum output current. These values are used for input current and output current telemetry.

The MFR_SPECIFIC_10 command must be accessed through Write Word/Read Word transactions. MFR_SPECIFIC_10 is a paged register. In order to access MFR_SPECIFIC_10 command for channel A, PAGE must be set to 00h. In order to access the MFR_SPECIFIC_10 register for channel B, PAGE must be set to 01h. Note that input current calibration is shared across both channels, but the configuration makes use of both PAGEs.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|--|----|----|--------------|---------------|----|----|---|
| RW RW RW | | | R | RW | RW | RW | |
| IIN_MAX (PAGE 0, bits 15:8) IIN_GAIN_CTRL (PAGE 1, bit 13) IIN_OFS (PAGE 1, bits 12:8) | | | | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| RW RW RW RW RW | | | | RW | RW | | |
| | | | IOUT_MAX (PA | GE 0, PAGE 1) | | | |

LEGEND: R/W = Read/Write; R = Read only

MFR SPECIFIC 10

Table 15. MFR_SPECIFIC_10 Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|------|------------------------|------|-------|---|
| 15:8 | IIN_MAX (PAGE 0) | RW | NVM | Maximum IIN setting. LSB = 0.25 A. Valid values range from 0 A to 63.75 A. |
| 13 | IIN_GAIN_CTRL (PAGE 1) | RW | NVM | Used to increase the effective IIN_RGAIN. See MFR_SPECIFIC_12 for more information. |
| 12:8 | IIN_OFS (PAGE 1) | RW | NVM | Input current sense offset calibration. See Table 16. |
| 7:0 | IOUT_MAX | RW | NVM | Sets the maximum output current for each channel (PAGE 0 for channel A, PAGE 1 for channel B). LSB = 1 A. |



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Table 16. Input Current Offset Calibration Settings

| IIN_OFS (hex) | IIN Offset (A) |
|---------------|----------------|
| 00h | 0 |
| 01h | 0.1 |
| 02h | 0.2 |
| 03h | 0.3 |
| 04h | 0.4 |
| 05h | 0.5 |
| 06h | 0.6 |
| 07h | 0.7 |
| 08h | 0.8 |
| 09h | 0.9 |
| 0Ah | 1.0 |
| 0Bh | 1.1 |
| 0Ch | 1.2 |
| 0Dh | 1.3 |
| 0Eh | 1.4 |
| 0Fh | 1.5 |
| 10h | -1.6 |
| 11h | -1.5 |
| 12h | -1.4 |
| 13h | -1.3 |
| 14h | -1.2 |
| 15h | -1.1 |
| 16h | -1.0 |
| 17h | -0.9 |
| 18h | -0.8 |
| 19h | -0.7 |
| 1Ah | -0.6 |
| 1Bh | -0.5 |
| 1Ch | -0.4 |
| 1Dh | -0.3 |
| 1Eh | -0.2 |
| 1Fh | -0.1 |

7.5.6.3 (DCh) MFR_SPECIFIC_12

The MFR_SPECIFIC_12 command is used to configure input current sensing.

The MFR_SPECIFIC_12 command must be accessed through Write Word/Read Word transactions. MFR_SPECIFIC_12 is a paged register, but all relevant configuration bits are associated with PAGE 0. PAGE should be set to 00h when accessing MFR_SPECIFIC_12.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | |
|---------|---------|----|----|----|-------------|------------|----|--|
| RW | RW | R | RW | RW | RW | RW | RW | |
| IIN_F | RGAIN | 0 | | | TI_INTERNAL | I_INTERNAL | | |
| | | _ | | 0 | 0 | 4 | 0 | |
| 7 | 6 | 5 | 4 | 3 | 2 | | U | |
| 7 RW | 6 RW | RW | RW | RW | RW | RW | RW | |

LEGEND: R/W = Read/Write; R = Read only

MFR_SPECIFIC_12

Table 17. MFR_SPECIFIC_12 Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-------------------------|------|-------|---|
| 15:14 | IIN_RGAIN (PAGE 0 only) | RW | NVM | Input shunt resistance value. Combined with IIN_RGAIN, IIN_OFS, IIN_MAX to calibrate measured input current sensing. Note that finer adjustments can be made using IIN_MAX. |
| 12:0 | TI_INTERNAL | RW | NVM | TI Internal bits. These bits are writeable, but should not be modified from their factory default setting. |

Table 18. A_{IIN} , Input Current Sense Analog Gain⁽¹⁾

| IIN_GAIN_CTRL (MFR_SPECIFIC_10) | IIN_RGAIN (MFR_SPECIFIC_12) | Effective A _{IIN} |
|----------------------------------|---------------------------------|----------------------------|
| 0b | 00b | $0.15~\text{m}\Omega$ |
| 0b | 01b | $0.25~\text{m}\Omega$ |
| 0b | 10b | $0.3~\text{m}\Omega$ |
| 0b | 11b | $0.5~\text{m}\Omega$ |
| 1b | 00b | 1.2 m Ω |
| 1b | 01b | $2.0~\text{m}\Omega$ |
| 1b | 10b | 2.4 mΩ |
| 1b | 11b | 4.0~mΩ |

(1) See Also Table 14

Table 19. Maximum Temperature Settings

| TMAX (binary) | Maximum Temperature (°C) |
|---------------|--------------------------|
| 000b | 90 |
| 001b | 95 |
| 010b | 100 |
| 011b | 105 |
| 100b | 110 |
| 101b | 115 |
| 110b | 120 |
| 111b | 125 |

Product Folder Links: TPS53681

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7.5.7 Output Current Sense and Calibration

The READ IOUT command may be used to read the individual phase currents, and the total channel current.

7.5.7.1 Reading Individual Phase Currents

Using the PAGE and PHASE commands, the TPS53681 can be configured to return output current information for each individual phase. The examples below demonstrate this process:

Example #1: Read back the output current of Channel A, First Phase

- 1. Select Channel A. Write PAGE to 00h
- 2. Select first phase. Write PHASE to 00h
- 3. Read READ IOUT

Example #2: Read back the output current of Channel B, Second Phase

- Select Channel B. Write PAGE to 01h
- 2. Select second phase. Write PHASE to 01h
- 3. Read READ_IOUT

7.5.7.1.1 Reading Total Current

When the PHASE command is set to 80h, the TPS53681 device is configured to return the total channel current (sum of individual phase currents) in response to the READ_IOUT command.

Example: Read the Total Output Current of Channel A

- 1. Select Channel A. Write PAGE to 00h
- 2. Select total current measurement. Write PHASE to 80h
- 3. Read READ IOUT

7.5.7.1.2 Calibrating Current Measurements

The IOUT_CAL_GAIN and IOUT_CAL_OFFSET commands are available to allow the user to fine-tune current measurements. Setting the PHASE command to 80h also allows the total current measurement to be calibrated in a similar manner. The TI power stage devices supply current information to the controller device, using the CSPx and CSNx pins, with a scale of 5 mV/A. The IOUT_CAL_GAIN command may be used to fine-tune the scaling inside the controller to account for any gain mismatch. Likewise, the IOUT_CAL_OFFSET command may be used to apply an offset to the controller current measurements, to null offset errors.

Example: Calibrating Total Output Current Measurement

- 1. Select Channel A. Write PAGE to 00h
- 2. Select the total current. Write PHASE to 80h
- 3. First read back READ_IOUT under two known output currents:
 - (a) For this example, apply a load of 60 A
 - (b) Read back READ_IOUT, record the value. For this example, consider that READ_IOUT gives 59.0 A.
 - (c) For this example, apply a load of 120 A
 - (d) Read back READ IOUT, record the value. For this example, consider that READ IOUT gives 119.6 A
- 4. Calculate the gain error:
 - (a) The current reading increased (119.6 A 59.0 A) = 60.6 A for a 60 A current step
 - (b) Hence, the current reading gain is (60.6 A / 60 A) = 1.01.
 - (c) Ideally, the current reading gain is 1.00, so the readings show a +1% gain error.
- 5. Apply IOUT_CAL_GAIN to correct the gain error:
 - (a) The gain error is +1%, and the nominal current sense gain is 5 m Ω , so the current sense gain must be lowered by 1%.
 - (b) Hence, the IOUT_CAL_GAIN should be programmed to 5 m Ω x (1-1%) = 4.95 m Ω
 - (c) Referring to Table 21 the closest acceptable value is 4.953125 mΩ, or D13Dh.
 - (d) Write IOUT_CAL_GAIN to D13Dh.
- 6. Determine the offset error at a given point:
 - (a) Apply a known load. In this example, 90 A.



- (b) Read back READ_IOUT. For this example, consider that READ_IOUT gives 89 A.
- (c) Hence, the offset error is (89 A 90 A) = -1 A.
- 7. Apply IOUT CAL OFFSET to correct the gain error
 - (a) The offset error is -1 A, so an offset of +1 A must be applied.
 - (b) Refer to Table 24, the closest available value of IOUT CAL OFFSET is +1.0 A or E808h
 - (c) Write IOUT_CAL_OFFSET to E808h.
- 8. Issue STORE_DEFAULT_ALL to commit the calibration values to NVM.

7.5.7.2 (38h) IOUT_CAL_GAIN

The IOUT_CAL_GAIN command is used to set the ratio of the voltage at the current sense pins to the sensed current, in $m\Omega$.

IOUT_CAL_GAIN is a linear format command. The IOUT_CAL_GAIN command must be accessed through Read Word/Write Word transactions.

IOUT_CAL_GAIN is a paged register. In order to access IOUT_CAL_GAIN for channel A, PAGE must be set to 00h. In order to access the IOUT_CAL_GAIN register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh. IOUT_CAL_GAIN is also a phased register. Depending on the configuration of the design, for channel A, PHASE must be set to 00h to access Phase 1, 01h to access Phase 2, etc... PHASE must be set to FFh to access all phases simultaneously. PHASE may also be set to 80h to apply IOUT_CAL_GAIN to the total phase current (sum of all active phases for the current channel) measurement, as described in Output Current Sense and Calibration.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|----|----|----------|----------|----|----|-----|----|
| R | R | R | R | R | RW | RW | RW |
| | | IOCG_EXP | IOCG_MAN | | | | |
| 7 | • | | 4 | 2 | 2 | 4 | 0 |
| / | 6 | 5 | 4 | 3 | 2 | l l | U |
| RW | RW | RW | RW | RW | RW | RW | RW |

LEGEND: R/W = Read/Write; R = Read only

IOUT CAL GAIN

Table 20. IOUT_CAL_GAIN Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|----------|------|--------|---|
| 15:11 | IOCG_EXP | R | 11010b | Linear two's complement exponent, –6. LSB = 0.015625 m Ω |
| 10:0 | IOCG_MAN | RW | NVM | Linear two's complement mantissa. See the table of acceptable values below. |

Table 21. Acceptable Values of IOUT_CAL_GAIN

| IOUT_CAL_GAIN (hex) | Current Sense Gain (mΩ) |
|---------------------|-------------------------|
| D131h | 4.765625 |
| D132h | 4.78125 |
| D133h | 4.796875 |
| D134h | 4.8125 |
| D135h | 4.828125 |
| D136h | 4.84375 |
| D137h | 4.859375 |
| D138h | 4.875 |
| D139h | 4.890625 |
| D13Ah | 4.90625 |
| D13Bh | 4.921875 |
| D13Ch | 4.9375 |
| D13Dh | 4.953125 |

Table 21. Acceptable Values of IOUT CAL GAIN (continued)

| IOUT_CAL_GAIN (hex) | Current Sense Gain (m Ω) | | | | |
|---------------------|----------------------------------|--|--|--|--|
| D13Eh | 4.96875 | | | | |
| D13Fh | 4.984375 | | | | |
| D140h | 5 | | | | |
| D141h | 5.015625 | | | | |
| D142h | 5.03125 | | | | |
| D143h | 5.046875 | | | | |
| D144h | 5.0625 | | | | |
| D145h | 5.078125 | | | | |
| D146h | 5.09375 5.109375 | | | | |
| D147h | | | | | |
| D148h | 5.125 | | | | |
| D149h | 5.140625 | | | | |
| D14Ah | 5.15625 | | | | |
| D14Bh | 5.171875 | | | | |
| D14Ch | 5.1875 | | | | |
| D14Dh | 5.203125 | | | | |
| D14Eh | 5.21875 | | | | |
| D14Fh | 5.234375 | | | | |
| D150h | 5.25 | | | | |

Attempts to write any value other than those specified above results in invalid transactions. The device ignores the invalid data, sets the appropriate flags in STATUS CML and STATUS WORD, and asserts the PMB ALERT signal to notify the system host of an invalid transaction.

7.5.7.3 (39h) IOUT_CAL_OFFSET

The IOUT CAL OFFSET command is used to compensate for offset errors in the READ IOUT command, in Amperes.

IOUT_CAL_OFFSET is a linear format command. The IOUT_CAL_OFFSET command must be accessed through Read Word/Write Word transactions

IOUT CAL OFFSET is a paged register. In order to access IOUT CAL OFFSET for channel A, PAGE must be set to 00h. In order to access the IOUT_CAL_OFFSET register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh. IOUT CAL OFFSET is also a phased register. Depending on the configuration of the design, for channel A, PHASE must be set to 00h to access Phase 1, 01h to access Phase 2, etc... PHASE must be set to FFh to access all phases simultaneously. PHASE may also be set to 80h to apply IOUT CAL OFFSET to the total phase current (sum of all active phases for the current channel) measurement, as described in Output Current Sense and Calibration.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|----|----|-----------|-----------|----|----|----|----|
| R | R | R | R | R | RW | RW | RW |
| | | IOCOS_EXP | IOCOS_MAN | | | | |
| 7 | 6 | E | 1 | 2 | 2 | 1 | Λ |
| | U | 5 | 4 | 3 | 2 | | U |
| RW | RW | RW | RW | RW | RW | RW | RW |

LEGEND: R/W = Read/Write; R = Read only

IOUT CAL OFFSET

Table 22. IOUT_CAL_OFFSET Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-----------|------|--------|---|
| 15:11 | IOCOS_EXP | R | 11101b | Linear two's complement exponent, −3. LSB = 0.125 A |
| 10:0 | IOCOS_MAN | RW | NVM | Linear two's complement mantissa. See the table of acceptable values below. Note that there is a different set of acceptable values for individual phases (e.g. PHASE = 00h - 05h, and FFh) vs. the total current telemetry function (e.g. PHASE = 80h). See Output Current Sense and Calibration for more information. |

Table 23. Acceptable Values of IOUT_CAL_OFFSET (Individual Phases, PHASE \neq 80h)

| IOUT_CAL_OFFSET (hex) | Current Sense Offset (A) |
|-----------------------|--------------------------|
| E800h | 0.00 |
| E801h | 0.125 |
| E802h | 0.25 |
| E803h | 0.375 |
| E804h | 0.5 |
| E805h | 0.625 |
| E806h | 0.75 |
| E807h | 0.875 |
| E808h | 1.0 |
| EFF9h | -0.875 |
| EFFAh | -0.75 |
| EFFBh | -0.625 |
| EFFCh | -0.5 |
| EFFDh | -0.375 |
| EFFEh | -0.25 |
| EFFFh | -0.125 |

Table 24. Acceptable Values of IOUT_CAL_OFFSET (Total Current, PHASE = 80h)

| IOUT_CAL_OFFSET (hex) | Current Sense Offset (A) | | | |
|-----------------------|--------------------------|--|--|--|
| E800h | 0.00 | | | |
| E802h | 0.25 | | | |
| E804h | 0.5 | | | |
| E806h | 0.75 | | | |
| E808h | 1.0 | | | |
| E80Ah | 1.25 | | | |
| E80Ch | 1.5 | | | |
| E80Eh | 1.75 | | | |
| E810h | 2.0 | | | |
| E812h | 2.25 | | | |
| E814h | 2.5 | | | |
| E816h | 2.75 | | | |
| E818h | 3.0 | | | |
| E81Ah | 3.25 | | | |
| E81Ch | 3.5 | | | |
| E81Eh | 3.75 | | | |
| E820h | 4.0 | | | |

Table 24. Acceptable Values of IOUT_CAL_OFFSET (Total Current, PHASE = 80h) (continued)

| IOUT_CAL_OFFSET (hex) | Current Sense Offset (A) |
|-----------------------|--------------------------|
| EFE2h | -3.75 |
| EFE4h | -3.5 |
| EFE6h | -3.25 |
| EFE8h | -3.0 |
| EFEAh | -2.75 |
| EFECh | -2.5 |
| EFEEh | -2.25 |
| EFF0h | -2.0 |
| EFF2h | -1.75 |
| EFF4h | -1.5 |
| EFF6h | -1.25 |
| EFF8h | -1.0 |
| EFFAh | -0.75 |
| EFFCh | -0.5 |
| EFFEh | -0.25 |

Attempts to write any value other than those specified above results in invalid transactions. The device ignores the invalid data, sets the appropriate flags in STATUS_CML and STATUS_WORD, and asserts the PMB_ALERT signal to notify the system host of an invalid transaction.

TEXAS INSTRUMENTS

7.5.8 Output Voltage Margin Testing

The TPS53681 provides several commands to enable voltage margin testing.

The upper two MARGIN bits in the OPERATION command can be used to toggle the active channel between three states:

- 1. Margin None (MARGIN = 0000b). The output voltage target is equal to VOUT_COMMAND.
- 2. Margin Low (MARGIN = 01xxb). The output voltage target is equal to VOUT_MARGIN_LOW.
- 3. Margin High (MARGIN = 10xxb). The output voltage target is equal to VOUT_MARGIN_HIGH.

In order to use OPERATION, the active channel must be configured for to respect the OPERATION command, via ON_OFF_CONFIG. Output voltage transitions will occur at the slew rate defined by VOUT TRANSITION RATE.

The lower two MARGIN bits in the OPERATION command select overvoltage/undervoltage fault handling during margin testing:

- 1. **Ignore Faults (MARGIN = xx01b)**. Overvoltage/Undervoltage faults will not trigger during margin tests.
- 2. Act on Faults (MARGIN = xx10b). Overvoltage/Undervoltage faults will trigger during margin tests.

Example: Output Voltage Margin Testing (Ignore Faults)

- 1. Write to the PAGE command to select the desired channel (E.g. PAGE = 00h for channel A).
- 2. Write VOUT_COMMAND to the desired VID code during Margin None operation.
- 3. Write VOUT_MARGIN_LOW to the desired VID code during Margin Low operation.
- 4. Write VOUT_MARGIN_HIGH to the desired VID code during Margin High operation.
- 5. Write MFR_SPECIFIC_02 to 01h to ensure that the PMBus interface has control of the output voltage.
- 6. Set the CMD bit in OPERATION to 1b to ensure the device is configured to respect the OPERATION command.
- 7. Margin None. Write OPERATION to 80h.
- 8. Margin Low. Write OPERATION to 94h.
- 9. Margin High. Write OPERATION to A4h.

7.5.8.1 (01h) OPERATION

The OPERATION command is used to turn the device output on or off in conjunction with the input from the AVR_EN pin for channel A, and BEN pin for channel B, acc ording to the configuration of the ON_OFF_CONFIG command. It is also used to set the output voltage to the upper or lower MARGIN levels.

OPERATION is a paged register. In order to access OPERATION command for channel A, PAGE must be set to 00h. In order to access OPERATION register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

The OPERATION command must be accessed through Read Byte/Write Byte transactions.

| 7 | 6 | 5 4 | | 3 | 2 | 1 | 0 |
|----|---|-----|-----|----|----|----|----|
| RW | R | RW | RW | RW | RW | RW | RW |
| ON | 0 | | MAF | 0 | 0 | | |

LEGEND: R/W = Read/Write; R = Read only

OPERATION



Table 25. OPERATION Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|--------|------|-------|--|
| 7 | ON | RW | 0b | Enable/disable power conversion for the currently selected channel(s) according to the PAGE command, when the ON_OFF_CONFIG command is configured to require input from the ON bit for output control. Note that there may be several other requirements that must be satisfied before the currently selected channel(s) can begin converting power (e.g. input voltages above UVLO thresholds, AVR_EN/BEN pins high if required by ON_OFF_CONFIG, etc) 0b: Disable power conversion 1b: Enable power conversion |
| 5:2 | MARGIN | RW | 0000b | Set the output voltage to either the value selected by the VOUT_MARGIN_HIGH or MARGIN_LOW commands, for the currently selected channel(s), according to the PAGE command. 0000b: Margin Off. Output voltage is set to the value of VOUT_COMMAND 0101b: Margin Low (Ignore Fault). Output voltage is set to the value of VOUT_MARGIN_LOW. 0110b: Margin Low (Act on Fault). Output voltage is set to the value of VOUT_MARGIN_LOW. 1001b: Margin High (Ignore Fault). Output voltage is set to the value of VOUT_MARGIN_HIGH 1010b: Margin High (Act on Fault). Output voltage is set to the value of VOUT_MARGIN_HIGH. |
| 1:0 | 0 | RW | 00b | These bits are writeable but should always be set to 00b. |

Note that the VOUT_MAX_WARN bit in STATUS_VOUT can be caused by a margin operation, if "Act on Fault" is selected, and the VOUT_MARGIN_HIGH/VOUT_MARGIN_LOW value loaded by the margin operation exceeds the value of VOUT_COMMAND.

7.5.8.2 (26h) VOUT_MARGIN_LOW

The VOUT_MARGIN_LOW command loads the unit with the voltage to which the output is to be changed when the OPERATION command is set to "Margin Low".

VOUT MARGIN LOW is a VID format command. The VOUT MARGIN LOW command must be accessed through Read Word/Write Word transactions.

VOUT_MARGIN_LOW is a paged register. In order to access VOUT_MARGIN_LOW for channel A, PAGE must be set to 00h. In order to access the VOUT_MARGIN_LOW register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | |
|----|----------------|----|----|----|----|----|----|--|--|
| R | R | R | R | R | R | R | R | | |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | |
| RW | RW | RW | RW | RW | RW | RW | RW | | |
| | VOUT_MARGL_VID | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

VOUT_MARGIN_LOW

Table 26. VOUT MARGIN LOW Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|----------------|------|-------|---|
| 7:0 | VOUT_MARGL_VID | RW | 00h | Used to set the output voltage to be loaded when the active PAGE is set to Margin Low, in VID format. |

TEXAS INSTRUMENTS

7.5.8.3 (25h) VOUT_MARGIN_HIGH

The VOUT_MARGIN_HIGH command loads the unit with the voltage to which the output is to be changed when the OPERATION command is set to "Margin High".

VOUT_MARGIN_HIGH is a VID format command. The VOUT_MARGIN_HIGH command must be accessed through Read Word/Write Word transactions.

VOUT_MARGIN_HIGH is a paged register. In order to access VOUT_MARGIN_HIGH for channel A, PAGE must be set to 00h. In order to access the VOUT_MARGIN_HIGH register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | |
|----|----------------|----|----|----|----|----|----|--|
| R | R | R | R | R | R | R | R | |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| RW | RW | RW | RW | RW | RW | RW | RW | |
| | VOUT_MARGH_VID | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

VOUT_MARGIN_HIGH

Table 27. VOUT_MARGIN_HIGH Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|----------------|------|-------|--|
| 7:0 | VOUT_MARGH_VID | RW | 00h | Used to set the output voltage to be loaded when the active PAGE is set to Margin High, in VID format. |



7.5.9 Loop Compensation

The TPS53681 provides several options for tuning the output voltage feedback and response to transients. These may be configured by programming the MFR_SPECIFIC_07, VOUT_DROOP, and MFR_SPECIFIC_14. Several such parameters may be configured through these commands:

- DC Load Line Selects the DC shift in output voltage corresponding to increased output current. The DC load line affects both the final value the output voltage settles to, as well as the settling time. Use the VOUT DROOP command to select the DC load line.
- Integration Time Constant In order to maintain DC accuracy, the control loop includes an integration stage. Use MFR_SPECIFIC_07 to select the integration time constant.
- Integration Path Gain The gain of the integration and AC paths may be selected independently. The AC and DC gains both affect the small-signal bandwidth of the converter. Use MFR SPECIFIC 07 to select the integration path gain.
- AC Load Line Selects the AC response to output voltage error. The AC load line affects the settling and response time following a load transient event. MFR_SPECIFIC_07 Use the MFR_SPECIFIC_07 command to select the AC load line.
- AC Path Gain The gain of the integration and AC paths may be selected independently. The AC and DC gains both affect the small-signal bandwidth of the converter. Use MFR SPECIFIC 07 to select the AC path gain.
- Ramp Amplitude Smaller ramp settings result in faster response, but may also lead to increased frequency jitter. Likewise, large ramp settings result in lower frequency jitter, but may be slightly slower to respond to changing conditions. The ramp setting also affects the small-signal bandwidth of the converter. Use MFR SPECIFIC 14 to select the ramp heigh setting.

7.5.9.1 (D7h) MFR SPECIFIC 07

The MFR SPECIFIC 07 command is used to configure the internal loop compensation for both channels. The MFR SPECIFIC 07 command must be accessed through Write Word/Read Word transactions.

MFR_SPECIFIC_07 is a paged register. In order to access MFR_SPECIFIC_07 command for channel A, PAGE must be set to 00h. In order to access the MFR_SPECIFIC_07 register for channel B, PAGE must be set to 01h.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | |
|-----|------|------|------|--------|----|----|----|--|
| R | R | RW | RW | RW | RW | RW | RW | |
| 0 | 0 | INT_ | GAIN | INT_TC | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| RW | RW | RW | RW | RW | RW | RW | RW | |
| AC_ | GAIN | | | AC | LL | | | |

LEGEND: R/W = Read/Write; R = Read only

MFR SPECIFIC 07

Table 28, MFR SPECIFIC 07 Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|----------|------|-------|--|
| 15:14 | Not used | R | 0 | Not used and set to 0. |
| 13:12 | INT_GAIN | RW | NVM | Integration path gain. See Table 29. |
| 11:8 | INT_TC | RW | NVM | Integration time constant. See Table 30. |
| 7:6 | AC_GAIN | RW | NVM | AC path gain. See Table 31. |
| 5:0 | ACLL | RW | NVM | AC Load Line. See Table 32. |

Table 29. Integration path gain settings

| INT_GAIN (binary) | Integration path gain (V/V) |
|-------------------|-----------------------------|
| 00b | 2 × AC_GAIN |
| 01b | 1 × AC_GAIN |
| 10b | 0.66 × AC_GAIN |

Table 29. Integration path gain settings (continued)

| INT_GAIN (binary) | Integration path gain (V/V) |
|-------------------|-----------------------------|
| 11b | 0.5 × AC_GAIN |

Table 30. Integration time constant settings

| INT_TC (binary) | Time constant (µs) |
|-----------------|--------------------|
| 0000b | 5 |
| 0001b | 10 |
| 0010b | 15 |
| 0011b | 20 |
| 0100b | 25 |
| 0101b | 30 |
| 0110b | 35 |
| 0111b | 40 |
| 1000b | 1 |
| 1001b | 2 |
| 1010b | 3 |
| 1011b | 4 |
| 1100b | 5 |
| 1101b | 6 |
| 1110b | 7 |
| 1111b | 8 |

Table 31. AC path gain settings

| AC_GAIN (binary) | AC path gain (V/V) |
|------------------|--------------------|
| 00b | 1 |
| 01b | 1.5 |
| 10b | 2 |
| 11b | 0.5 |

Table 32. AC Load line settings

| Bin | ACLL (hex) | AC Load line (mΩ) |
|-----|------------|-------------------|
| 0 | 00h | 0.0000 |
| 1 | 01h | 0.1250 |
| 2 | 02h | 0.2500 |
| 3 | 03h | 0.3125 |
| 4 | 04h | 0.3750 |
| 5 | 05h | 0.4375 |
| 6 | 06h | 0.5000 |
| 7 | 07h | 0.5625 |
| 8 | 08h | 0.6250 |
| 9 | 09h | 0.7500 |
| 10 | 0Ah | 0.7969 |
| 11 | 0Bh | 0.8125 |
| 12 | 0Ch | 0.8281 |
| 13 | 0Dh | 0.8438 |
| 14 | 0Eh | 0.8594 |
| 15 | 0Fh | 0.8750 |
| 16 | 10h | 0.8906 |



Table 32. AC Load line settings (continued)

| | Table 32. AC LOad line Settin | |
|-----|-------------------------------|-------------------|
| Bin | ACLL (hex) | AC Load line (mΩ) |
| 17 | 11h | 0.9063 |
| 18 | 12h | 0.9219 |
| 19 | 13h | 0.9375 |
| 20 | 14h | 0.9531 |
| 21 | 15h | 0.9688 |
| 22 | 16h | 0.9844 |
| 23 | 17h | 1.000 |
| 24 | 18h | 1.0156 |
| 25 | 19h | 1.0313 |
| 26 | 1Ah | 1.0469 |
| 27 | 1Bh | 1.0625 |
| 28 | 1Ch | 1.1250 |
| 29 | 1Dh | 1.2500 |
| 30 | 1Eh | 1.3750 |
| 31 | 1Fh | 1.5000 |
| 32 | 20h | 1.6250 |
| 33 | 21h | 1.7500 |
| 34 | 22h | 1.8750 |
| 35 | 23h | 1.9375 |
| 36 | 24h | 2.000 |
| 37 | 25h | 2.0625 |
| 38 | 26h | 2.1250 |
| 39 | 27h | 2.1875 |
| 40 | 28h | 2.2500 |
| 41 | 29h | 2.375 |
| 42 | 2Ah | 2.4218 |
| 43 | 2Bh | 2.4375 |
| 44 | 2Ch | 2.4531 |
| 45 | 2Dh | 2.4687 |
| 46 | 2Eh | 2.4843 |
| 47 | 2Fh | 2.4043 |
| 48 | | |
| | 30h | 2.5156 |
| 49 | 31h | 2.5312 |
| 50 | 32h | 2.5468 |
| 51 | 33h | 2.5625 |
| 52 | 34h | 2.5781 |
| 53 | 35h | 2.5937 |
| 54 | 36h | 2.609 |
| 55 | 37h | 2.625 |
| 56 | 38h | 2.6406 |
| 57 | 39h | 2.6562 |
| 58 | 3Ah | 2.6718 |
| 59 | 3Bh | 2.6875 |
| 60 | 3Ch | 2.750 |
| 61 | 3Dh | 2.875 |
| 62 | 3Eh | 3.000 |
| 63 | 3Fh | 3.125 |

TEXAS INSTRUMENTS

7.5.9.2 (28h) VOUT_DROOP

The VOUT_DROOP command sets the rate, in mV/A ($m\Omega$) at which the output voltage decreases (or increases) with increasing (or decreasing) output current for use with adaptive voltage positioning. This is also referred to as the DC Load Line (DCLL).

VOUT_DROOP is a linear format command. The VOUT_DROOP command must be accessed through Read Word/Write Word transactions.

VOUT_DROOP is a paged register. In order to access VOUT_DROOP for channel A, PAGE must be set to 00h. In order to access the VOUT_DROOP register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|---------|---------|------------|------------|----|----|----|----|
| R | R | R | R | R | RW | RW | RW |
| | | VDROOP_EXP | VDROOP_MAN | | | | |
| | | | | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| 7 RW | 6 RW | 5 RW | RW | RW | RW | RW | RW |

LEGEND: R/W = Read/Write; R = Read only

VOUT_DROOP

Table 33. VOUT DROOP Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|------------|------|--------|--|
| 15:11 | VDROOP_EXP | R | 11010b | Linear two's complement fixed exponent, -6. LSB = 0.015625 $\mathrm{m}\Omega$ |
| 10:0 | VDROOP_MAN | RW | NVM | Linear two's complement mantissa. See table of acceptable values below, note that Channel A and Channel B support different acceptable values of VOUT_DROOP. |

The table below summarizes the acceptable values of VOUT_DROOP for channel A and channel B. Attempts to write any value other than those specified below will be treated as invalid data - invalid data will be ignored, the appropriate flags in STATUS_CML and STATUS_WORD will be set, and the PMB_ALERT will be asserted to notify the system host of an invalid transaction.

Table 34. Acceptable VOUT_DROOP Values

| Bin | VOUT_DROOP (hex) | Supported by Channel A | Supported by Channel B | DC Load Line (mΩ) |
|-----|---------------------|---------------------------|---------------------------|----------------------|
| 0 | D000h | Yes | Yes | 0 |
| 1 | D008h | Yes | Yes | 0.125 |
| 2 | D010h | Yes | Yes | 0.25 |
| 3 | D014h | Yes | Yes | 0.3125 |
| 4 | D018h | Yes | Yes | 0.375 |
| 5 | D01Ch | Yes | Yes | 0.4375 |
| 6 | D020h | Yes | Yes | 0.5 |
| 7 | D024h | Yes | Yes | 0.5625 |
| 8 | D028h | Yes | Yes | 0.625 |
| 9 | D030h | Yes | Yes | 0.7031 |
| 10 | D033h | Yes | Yes | 0.7969 |
| 11 | D034h | Yes | Yes | 0.8125 |
| 12 | D035h | Yes | Yes | 0.8281 |
| 13 | D036h | Yes | Yes | 0.8438 |
| 14 | D037h | Yes | Yes | 0.8594 |
| 15 | D038h | Yes | Yes | 0.875 |
| 16 | D039h | Yes | No | 0.8906 |

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Table 34. Acceptable VOUT_DROOP Values (continued)

| | T. | | ` | , |
|-----|---------------------|---------------------------|---|--------------------------|
| Bin | VOUT_DROOP (hex) | Supported by Channel A | Supported by Channel B | DC Load Line $(m\Omega)$ |
| 17 | D03Ah | Yes | No | 0.9063 |
| 18 | D03Bh | Yes | No | 0.9219 |
| 19 | D03Ch | Yes | No | 0.9375 |
| 20 | D03Dh | Yes | No | 0.9531 |
| 21 | D03Eh | Yes | No | 0.9688 |
| 22 | D03Fh | Yes | No | 0.9844 |
| 23 | D040h | Yes | No | 1 |
| 24 | D041h | Yes | No | 1.0156 |
| 25 | D042h | Yes | No | 1.0313 |
| 26 | D043h | Yes | No | 1.0469 |
| 27 | D044h | Yes | No | 1.0625 |
| 28 | D048h | Yes | No | 1.125 |
| 29 | D050h | Yes | No | 1.25 |
| 30 | D058h | Yes | No | 1.375 |
| 31 | D060h | Yes | No | 1.5 |
| 32 | D068h | Yes | No | 1.625 |
| 33 | D070h | Yes | No | 1.75 |
| 34 | D078h | Yes | No | 1.875 |
| 35 | D07Ch | Yes | No | 1.9375 |
| 36 | D080h | Yes | No | 2 |
| 37 | D084h | Yes | No | 2.0625 |
| 38 | D088h | Yes | No | 2.125 |
| 39 | D08Ch | Yes | No | 2.1875 |
| 40 | D090h | Yes | No | 2.25 |
| 41 | D098h | Yes | No | 2.328 |
| 42 | D09Bh | Yes | No | 2.4218 |
| 43 | D09Ch | Yes | No | 2.4375 |
| 44 | D09Dh | Yes | No | 2.4531 |
| 45 | D09Eh | Yes | No | 2.4687 |
| 46 | D09Fh | Yes | No | 2.4843 |
| 47 | D0A0h | Yes | No | 2.5 |
| 48 | D0A1h | Yes | No | 2.5156 |
| 49 | D0A2h | Yes | No | 2.5312 |
| 50 | D0A3h | Yes | No | 2.5468 |
| 51 | D0A4h | Yes | No | 2.5625 |
| 52 | D0A5h | Yes | No | 2.5781 |
| 53 | D0A6h | Yes | No | 2.5937 |
| 54 | D0A7h | Yes | No | 2.609 |
| 55 | D0A8h | Yes | No | 2.625 |
| 56 | D0A9h | Yes | No | 2.6406 |
| 57 | D0AAh | Yes | No | 2.6562 |
| 58 | D0ABh | Yes | No | 2.6718 |
| 59 | D0ACh | Yes | No | 2.6875 |
| 60 | D0B0h | Yes | No | 2.75 |
| 61 | D0B8h | Yes | No | 2.875 |
| 62 | D0C0h | Yes | No | 3 |
| 63 | D0C8h | Yes | No | 3.125 |
| | | | | |

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7.5.10 Converter Protection and Response

The TPS53681 supports a variety of power supply protection features. The table below summarizes these protection features, and their related PMBus registers. See the following sections for more details.

Table 35. TPS53681 Protection and Response

| | Threshol | d | Response | |
|-----------------------------------|--|----------------------------------|------------------------|-----------------------------|
| | Command Name | Default Value | Command Name | Default Value |
| Output Voltage | | | | |
| Over-Voltage Protection | VOUT_OV_FAULT_LIMIT | 1.520 V (Ch A) 1.520 V (Ch B) | VOUT_OV_FAULT_RESPONSE | Shutdown, do not restart |
| Maximum Allowed Output Voltage | VOUT_MAX | 1.520 V (Ch A) 1.520 V (Ch B) | Refer to Register Des | cription |
| Under-Voltage Protection | VOUT_UV_FAULT_LIMIT | 0.000 V (Ch A) 0.000 V (Ch B) | VOUT_UV_FAULT_RESPONSE | Shutdown, do not restart |
| Minimum Allowed Output Voltage | VOUT_MIN | 0.000 V (Ch A) 0.000 V (Ch B) | Refer to Register Des | cription |
| Output Current | | | | |
| Over-Current Protection | IOUT_OC_FAULT_LIMIT MFR_SPECIFIC_10 | 382 A (Ch A) 135 A (Ch B) | IOUT_OC_FAULT_RESPONSE | Shutdown, do not restart |
| Over-Current Warning | IOUT_OC_WARN_LIMIT | 255 A (Ch A) 90 A (Ch B) | N/A. Warning On | ly. |
| Input Voltage | | | | |
| Turn-On Threshold | VIN_ON | 10.25 V | N/A | |
| Over-Voltage Protection | VIN_OV_FAULT_LIMIT | 17.000 V | VIN_OV_FAULT_RESPONSE | Continue Uninterrupted |
| Under-Voltage Protection | VIN_UV_FAULT_LIMIT | 9.500 V | VIN_UV_FAULT_RESPONSE | Shutdown, do not restart |
| Input Current | | | | |
| Over-Current Protection | IIN_OC_FAULT_LIMIT | 63.5 A | IIN_OC_FAULT_RESPONSE | Shutdown, do not restart |
| Over-Current Warning | IIN_OC_WARN_LIMIT | 56.0 A | N/A. Warning On | ly |
| Temperature | | | | |
| Over-Temperature Protection | OT_FAULT_LIMIT | 115 °C (Ch A) 115 °C (Ch B) | OT_FAULT_RESPONSE | Shutdown, do not restart |
| Over-Temperature Warning | OT_WARN_LIMIT | 105 °C (Ch A) 105 °C (Ch B) | N/A. Warning On | ly. |

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7.5.11 Output Overvoltage Protection and Response

The output overvoltage thresholds track the configured maximum output voltage, VOUT MAX, with a fixed offset, and may be read back in VID format via the read-only VOUT_OV_FAULT_LIMIT command. The converter response to an overvoltage fault is configured by the read-only VOUT OV FAULT RESPONSE command.

7.5.11.1 (40h) VOUT OV FAULT LIMIT

The VOUT OV FAULT LIMIT is used to read back the value of the output voltage measured at the sense or output pins that causes an output overvoltage fault in VID format. VOUT_OV_FAULT_LIMIT is a VID format command, and must be accessed through Read Word/Write Word transactions. VOUT OV FAULT LIMIT is a paged register. In order to access VOUT OV FAULT LIMIT for channel A, PAGE must be set to 00h. In order to access the VOUT OV FAULT LIMIT register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B. the PAGE command must be set to FFh.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | | | |
|----|------------|----|----|----|----|---|---|--|--|--|--|
| R | R | R | R | R | R | R | R | | | | |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | | |
| R | R | R | R | R | R | R | R | | | | |
| | VO_OVF_VID | | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

VOUT_OV_FAULT_LIMIT

Table 36. VOUT OV FAULT LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|------------|------|---------------|---|
| 7:0 | VO_OVF_VID | R | See below. | Read-only overvoltage fault limit, in VID format. |

When the 5-mV DAC mode VID table is selected via MFR_SPECIFIC_13, the VOUT_OV_FAULT_LIMIT register will be set to FFh. When the 10-mV DAC mode VID table is enabled, the VOUT OV FAULT LIMIT is determined according to the value of VOUT MAX, with a fixed offset applied.

7.5.11.2 (41h) VOUT OV FAULT RESPONSE

The VOUT_OV_FAULT_RESPONSE instructs the device on what action to take in response to an output overvoltage fault. The VOUT_OV_FAULT_RESPONSE command must be accessed through Read Byte transactions. The VOUT OV FAULT RESPONSE command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

Upon triggering the over-voltage fault, the controller is latched off, and the following actions are taken:

- Set the VOUT OV FAULT bit in the STATUS BYTE
- Set the VOUT bit in the STATUS WORD
- Set the VOUT OV FAULT bit in the STATUS VOUT register
- The device notifies the host (asserts PMB ALERT, if the corresponding mask bit in SMBALERT MASK is not set)

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | |
|---|------------|---|---|---|---|---|---|--|--|
| R | R | R | R | R | R | R | R | | |
| | VO_OV_RESP | | | | | | | | |

LEGEND: R/W = Read/Write: R = Read only

VOUT_OV_FAULT_RESPONSE

Table 37. VOUT_OV_FAULT_RESPONSE Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|------------|------|-------|---|
| 7:0 | VO_OV_RESP | R | 80h | 80h: Latch-off and do not restart. To clear a shutdown event due to a fault event, the user must toggle the AVR_EN/BEN pin and/or the ON bit in OPERATION, per the settings in ON_OFF_CONFIG, or power cycle the bias power to the V3P3 pin of the controller device. |

7.5.12 Maximum Allowed Output Voltage Setting

The VOUT_MAX command sets an upper limit on the output voltage that the unit may be commanded to, regardless of an other commands or combinations. The intent of this command is to provide a safeguard against a user accidentally setting the output voltage to a possibly destructive level.

7.5.12.1 (24h) VOUT_MAX

The VOUT_MAX command sets an upper limit on the output voltage that the unit may be commanded to, regardless of an other commands or combinations. The intent of this command is to provide a safeguard against a user accidentally setting the output voltage to a possibly destructive level. VOUT_MAX is a VID format command, and must be accessed through Read Word/Write Word transactions. VOUT_MAX is a paged register. In order to access VOUT_MAX for channel A, PAGE must be set to 00h. In order to access the VOUT_COMMAND register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

The device detects that an attempt has been made to program the output to a voltage greater than the value set by the VOUT_MAX command. Attempts to program the output voltage greater than VOUT_MAX can include VOUT_COMMAND attempts, and margin events while the VOUT_MARGIN_HIGH/VOUT_MARGIN_LOW values exceed the value of VOUT_MAX. These events will be treated warning conditions and not as fault conditions. If an attempt is made to program the output voltage higher than the limit set by the VOUT_MAX command, the device will respond as follows:

- The commanded output voltage will be clamped to VOUT_MAX,
- The OTHER bit will be set in the STATUS BYTE,
- The VOUT bit will be set in the STATUS WORD,
- The VOUT_MAX warning bit will be set in the STATUS_VOUT register, and
- The device notifies the host (asserts PMB_ALERT, if the corresponding mask bit in SMBALERT_MASK is not set).

This register should be programmed by the user depending upon the maximum output voltage the converter can support.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | | |
|----|--------------|----|----|----|----|----|----|--|--|--|
| R | R | R | R | R | R | R | R | | | |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | |
| RW | RW | RW | RW | RW | RW | RW | RW | | | |
| | VOUT_MAX_VID | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

VOUT MAX

Table 38. VOUT_MAX Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|--------------|------|-------|---|
| 7:0 | VOUT_MAX_VID | RW | NVM | Used to set the maximum VOUT of the device in VID format. |



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7.5.13 Output Undervoltage Protection and Response

The output undervoltage protection threshold is configured based on commanded output voltage, VOUT_COMMAND, including the shift due to the DC load line, and a fixed offset. The undervoltage threshold may be read back in VID format via the read-only VOUT_UV_FAULT_LIMIT command. The converter response to an overvoltage fault is configured by the read-only VOUT_UV_FAULT_RESPONSE command.

7.5.13.1 (44h) VOUT UV FAULT LIMIT

The VOUT_UV_FAULT_LIMIT is used to read back the value of the output voltage measured at the sense or output pins that causes an output undervoltage fault in VID format. VOUT_UV_FAULT_LIMIT is a VID format command, and must be accessed through Read Word transactions. VOUT_UV_FAULT_LIMIT is a paged register. In order to access VOUT_UV_FAULT_LIMIT for channel A, PAGE must be set to 00h. In order to access the VOUT_UV_FAULT_LIMIT register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | | | |
|----|------------|----|----|----|----|---|---|--|--|--|--|
| R | R | R | R | R | R | R | R | | | | |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | | |
| R | R | R | R | R | R | R | R | | | | |
| | VO_UVF_VID | | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

VOUT_UV_FAULT_LIMIT

Table 39. VOUT_UV_FAULT_LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|------------|------|---------------|--|
| 7:0 | VO_UVF_VID | R | See below. | Read-only undervoltage fault limit, in VID format. |

7.5.13.2 (45h) VOUT_UV_FAULT_RESPONSE

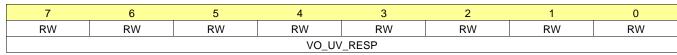
The VOUT_UV_FAULT_RESPONSE instructs the device on what action to take in response to an output undervoltage fault.

Upon triggering the undervoltage fault, the following actions are taken:

- Set the OTHER bit in the STATUS_BYTE
- Set the VOUT bit in the STATUS_WORD
- Set the VOUT_UV_FAULT bit in the STATUS_VOUT register
- The device notifies the host (asserts PMB_ALERT, if the corresponding mask bit in SMBALERT_MASK is not set)

The VOUT UV FAULT RESPONSE command must be accessed through Read Byte/Write Byte transactions.

The VOUT_UV_FAULT_RESPONSE command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.



LEGEND: R/W = Read/Write; R = Read only

VOUT_UV_FAULT_RESPONSE

Table 40. VOUT UV FAULT RESPONSE Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|------------|------|-------|---|
| | | | | 00h: Ignore. The controller will set the appropriate status bits, and alert the host, but continue converting power. |
| 7:0 | VO_UV_RESP | RW | NVM | BAh: Shutdown and restart. The controller will shutdown the channel on which the fault occurred, and attempt to restart 20ms later. This will occur continuously until the condition causing the fault has disappeared, or the controller has been disabled. |
| | | | | 80h: Latch-off and do not restart. To clear a shutdown event due to a fault event, the user must toggle the AVR_EN/BEN pin and/or the ON bit in OPERATION, per the settings in ON_OFF_CONFIG, or power cycle the bias power to the V3P3 pin of the controller device. |

7.5.14 Minimum Allowed Output Voltage Setting

The VOUT_MIN command sets a lower bound on the output voltage to which the unit can be commanded, regardless of any other commands or combinations. The intent of this command is to provide a safeguard against a user accidentally setting the output voltage to a possibly destructive level rather than to be the primary output under voltage protection.

7.5.14.1 (2Bh) VOUT_MIN

The VOUT_MIN command sets a lower bound on the output voltage to which the unit can be commanded, regardless of any other commands or combinations. The intent of this command is to provide a safeguard against a user accidentally setting the output voltage to a possibly destructive level rather than to be the primary output under voltage protection. VOUT_MIN is a VID format command, and must be accessed through Read Word/Write Word transactions. VOUT_MIN is a paged register. In order to access VOUT_MIN for channel A, PAGE must be set to 00h. In order to access the VOUT_MIN register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

If an attempt is made to program the output voltage lower than the limit set by this command, the device will respond as follows:

- The commanded output voltage will be clamped to VOUT_MIN
- The OTHER bit will be set in the STATUS BYTE
- The VOUT bit will be set in the STATUS_WORD
- The VOUT MAX MIN Warning bit will be set in the STATUS VOUT register
- The device notifies the host (asserts PMB_ALERT, if the corresponding mask bit in SMBALERT_MASK is not set).

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | | | |
|----|--------------|----|----|----|----|----|----|--|--|--|--|
| R | R | R | R | R | R | R | R | | | | |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | | |
| RW | RW | RW | RW | RW | RW | RW | RW | | | | |
| | VOUT_MIN_VID | | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

VOUT_MIN

Table 41. VOUT_MIN Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|--------------|------|--------|--|
| 7:0 | VOUT_MIN_VID | RW | INVIVI | Used to set a lower bound for output voltage programming for the active PAGE, is set to in VID format. |



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7.5.15 Output Overcurrent Protection and Response

Overcurrent thresholds are configured using the IOUT_OC_FAULT_LIMIT. When the overcurrent fault threshold is reached, the converter will respond according to the settings in IOUT_OC_FAULT_RESPONSE. The IOUT_OC_WARN_LIMIT may also be used to configure an information-only overcurrent warning, which triggers prior to an overcurrent fault. Note, that the MFR SPECIFIC 00 command, not listed below, also contains settings for per-phase overcurrent limits. Refer to the device *Technical Reference Manual* for more information.

7.5.15.1 (46h) IOUT OC FAULT LIMIT

The IOUT OC FAULT LIMIT command sets the value of the total output current, in amperes, that causes the over-current detector to indicate an over-current fault condition. The command has two data bytes and the data format is Linear as shown in the table below. The units are amperes. IOUT_OC_FAULT_LIMIT is a linear format command, and must be accessed through Read Word/Write Word transactions. IOUT_OC_FAULT_LIMIT is a paged register. In order to access IOUT_OC_FAULT_LIMIT command for channel A, PAGE must be set to 00h. In order to access IOUT_OC_FAULT_LIMIT register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | |
|------|-----------|-----------|----|----|----|-----------|----|--|
| R | R | R | R | R | RW | RW | RW | |
| | | IOOCF_EXP | | | | IOOCF_MAN | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| RW | RW | RW | RW | RW | RW | RW | RW | |
| 1744 | IOOCF_MAN | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

IOUT_OC_FAULT_LIMIT

Table 42. IOUT_OC_FAULT_LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-----------|------|---------------|--|
| 15:11 | IOOCF_EXP | R | 00000b | Linear two's complement exponent, 0. LSB = 1.0 A |
| 10:0 | IOOCF_MAN | RW | See below. | Linear two's complement mantissa |

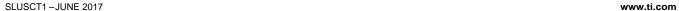
At power-on, or after a RESTORE_DEFAULT_ALL operation, the IOUT_OC_FAULT_LIMIT command will be loaded with the value of IOUT_MAX \times 1.50. The IOUT_MAX bits for each channel are stored in MFR_SPECIFIC_10 (PAGE 0 for channel A, PAGE 1 for channel B). IOUT_OC_FAULT_LIMIT may be changed during operation, but returns to this value on reset.

7.5.15.2 (4Ah) IOUT_OC_WARN_LIMIT

The IOUT OC WARN LIMIT command sets the value of the output current, in amperes, that causes the overcurrent detector to indicate an over-current warning condition. IOUT_OC_WARN_LIMIT is a linear format command, and must be accessed through Read Word/Write Word transactions. IOUT OC WARN LIMIT is a paged register. In order to access IOUT OC WARN LIMIT command for channel A, PAGE must be set to 00h. In order to access IOUT_OC_WARN_LIMIT register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

Upon triggering the overcurrent warning, the following actions are taken:

- Set the OTHER bit in the STATUS BYTE
- Set the IOUT bit in the STATUS WORD
- Set the IOUT Over current Warning bit in the STATUS_IOUT register
- The device notifies the host (asserts PMB ALERT, if the corresponding mask bit in SMBALERT MASK is not set)



| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|----|----|-----------|----|----|----|-----------|----|
| R | R | R | R | R | RW | RW | RW |
| | | IOOCW_EXP | | | | IOOCW_MAN | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| RW | RW | RW | RW | RW | RW | RW | RW |

LEGEND: R/W = Read/Write; R = Read only

IOUT_OC_WARN_LIMIT

IOOCW MAN

Table 43. IOUT_OC_WARN_LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-----------|------|---------------|--|
| 15:11 | IOOCW_EXP | R | 00000b | Linear two's complement exponent, 0. LSB = 1.0 A |
| 10:0 | IOOCW_MAN | RW | See below. | Linear two's complement mantissa. |

At power-on, or after a RESTORE_DEFAULT_ALL operation, the IOUT_OC_WARN_LIMIT command will be loaded with the value of IOUT_MAX. The IOUT_MAX bits for each channel are stored in MFR_SPECIFIC_10 (PAGE 0 for channel A, PAGE 1 for channel B). IOUT_OC_WARN_LIMIT may be changed during operation, but will return to this value on reset.

7.5.15.3 (47h) IOUT_OC_FAULT_RESPONSE

The IOUT_OC_FAULT_RESPONSE instructs the device on what action to take in response to an output overcurrent fault. The IOUT_OC_FAULT_RESPONSE command must be accessed through Read Byte/Write Byte transactions. The IOUT_OC_FAULT_RESPONSE command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

NOTE

IOUT_OC_WARN_LIMIT maximum default value is 255A. In case, Application maximum load current is greater than 255A, IOUT_OC_WARN_LIMIT needs to change as max load current value each time after power-on or RESTORE DEFAULT ALL operation.

Upon triggering the over-current fault, the controller is latched off, and the following actions are taken:

- Set the IOUT OC FAULT bit in the STATUS BYTE
- · Set the IOUT bit in the STATUS WORD
- Set the IOUT OC FAULT bit in the STATUS IOUT register
- The device notifies the host (asserts PMB_ALERT, if the corresponding mask bit in SMBALERT_MASK is not set)

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|-------|-------|----|----|----|
| RW | RW | RW | RW | RW | RW | RW | RW |
| | | | IO_OC | _RESP | | | |

LEGEND: R/W = Read/Write; R = Read only

IOUT_OC_FAULT_RESPONSE

Product Folder Links: TPS53681

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Table 44. IOUT_OC_FAULT_RESPONSE Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|------------|------|-------|---|
| 7:0 | IO_OC_RESP | RW | NVM | C0h: Latch-off and do not restart. To clear a shutdown event due to a fault event, the user must toggle the AVR_EN/BEN pin and/or the ON bit in OPERATION, per the settings in ON_OFF_CONFIG, or power cycle the bias power to the V3P3 pin of the controller device. |
| | | | | FAh: Shutdown and restart. The controller will shutdown the channel on which the fault occurred, and attempt to restart 20ms later. This will occur continuously until the condition causing the fault has disappeared, or the controller has been disabled. |

7.5.16 Input Under-Voltage Lockout (UVLO)

The TPS53681 may not start converting power, until the power stage input voltage reaches the level specified by VIN ON.

7.5.16.1 (35h) VIN_ON

The VIN_ON command sets the value of the input voltage, in Volts, at which the unit should start power conversion. This command has two data bytes encoded in linear data format, and must be accessed through Read Word/Write Word transactions. The VIN_ON command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command. The supported range for VIN_ON is from 4.0 V volts to 11.25 Volts.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|----|----|-----------|----|----|----|-----------|----|
| R | R | R | R | R | RW | RW | RW |
| | | VINON_EXP | | | | VINON_MAN | |
| 7 | C | _ | 1 | 2 | 2 | 1 | ^ |
| 1 | О | 5 | 4 | 3 | 2 | l l | U |
| RW | RW | RW | RW | RW | RW | RW | RW |

LEGEND: R/W = Read/Write; R = Read only

VIN_ON

Table 45. VIN_ON Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-----------|------|--------|---|
| 15:11 | VINON_EXP | R | 11110b | Linear two's complement exponent, −2. LSB = 0.25 V |
| 10:0 | VINON_MAN | RW | NVM | Linear two's complement mantissa. See the table of acceptable values below. |

Table 46. Acceptable Values of VIN_ON

| VIN_ON (hex) | Turn-On Voltage (V) |
|--------------|---------------------|
| F010h | 4.0 |
| F015h | 5.25 |
| F019h | 6.25 |
| F01Dh | 7.25 |
| F021h | 8.25 |
| F025h | 9.25 |
| F029h | 10.25 |
| F02Dh | 11.25 |

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7.5.17 Input Over-Voltage Protection and Response

The TPS53681 provides protection from input transients via the VIN_OV_FAULT_LIMIT and VIN_OV_FAULT_RESPONSE commands.

7.5.17.1 (55h) VIN OV FAULT LIMIT

The VIN_OV_FAULT_LIMIT command sets the value of the input voltage that causes an input overvoltage fault. VIN_OV_FAULT_LIMIT is a linear format command, and must be accessed through Read Word/Write Word transactions. The VIN_OV_FAULT_LIMIT command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|---------|---------|-------------|---------|----|----|-------------|----|
| R | R | R | R | R | RW | RW | RW |
| | | VIN_OVF_EXP | | | | VIN_OVF_MAN | |
| | | | | | _ | | _ |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| 7 RW | 6 RW | 5 RW | 4 RW | RW | RW | RW | RW |

LEGEND: R/W = Read/Write; R = Read only

VIN_OV_FAULT_LIMIT

Table 47. VIN_OV_FAULT_LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-------------|------|--------|--|
| 15:11 | VIN_OVF_EXP | R | 00000b | Linear two's complement exponent, 0. LSB = 1 V |
| 10:0 | VIN_OVF_MAN | RW | NVM | Linear two's complement mantissa. Valid values of the mantissa range from 0d to 31d. |

7.5.17.2 (56h) VIN_OV_FAULT_RESPONSE

The VIN_OV_FAULT_RESPONSE command instructs the device on what action to take in response to an input overvoltage fault. The VIN_OV_FAULT_RESPONSE command must be accessed through Read Byte transactions. The VIN_OV_FAULT_RESPONSE command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

In response to the VIN_OV_LIMIT being exceeded, the device will:

- Set the OTHER bit in the STATUS_BYTE
- Set the INPUT bit in the upper byte of the STATUS_WORD
- Sets the VIN OV FAULT bit in the STATUS INPUT register
- Notify the host (assert the PMB_ALERT signal, if the corresponding mask bit in SMBALERT_MASK is not set)

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|--------|-------|---|---|---|
| R | R | R | R | R | R | R | R |
| | | | VI_OVF | _RESP | | | |

LEGEND: R/W = Read/Write; R = Read only

VIN_OV_FAULT_RESPONSE

Table 48. VIN_OV_FAULT_RESPONSE Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|-------------|------|-------|--|
| 7:0 | VI_OVF_RESP | R | 00h | 00h: Ignore. The controller will set the appropriate status bits, and alert the host, but continue converting power. |



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7.5.18 Input Undervoltage Protection and Response

from input transients via the VIN UV FAULT LIMIT TPS53681 provides protection VIN_UV_FAULT_RESPONSE commands.

7.5.18.1 (59h) VIN UV FAULT LIMIT

The VIN UV FAULT LIMIT command sets the value of the input voltage that causes an Input Under voltage Fault. This fault is masked until the input exceeds the value set by the VIN ON command for the first time, and the unit has been enabled. VIN_UV_FAULT_LIMIT is a linear format command, and must be accessed through Read Word/Write Word transactions. The VIN_UV_FAULT_LIMIT command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|---------|---------|-------------|---------|---------|-------------|---------|---------|
| RW | RW | RW | RW | RW | RW | RW | RW |
| | | VIN_UVF_EXP | | | VIN_UVF_MAN | | |
| | | | | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| 7 RW | 6 RW | 5 RW | 4 RW | 3 RW | 2 RW | 1 RW | 0 RW |

LEGEND: R/W = Read/Write; R = Read only

VIN_UV_FAULT_LIMIT

Table 49. VIN_UV_FAULT_LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-------------|------|-------|---|
| 15:11 | VIN_UVF_EXP | RW | NVM | Linear two's complement exponent. See the table of acceptable values below. |
| 10:0 | VIN_UVF_MAN | RW | NVM | Linear two's complement mantissa. See the table of acceptable values below. |

Table 50. Acceptable Values of VIN UV FAULT LIMIT

| VIN_UV_FAULT_LIMIT (hex) | VIN UVF Limit (V) |
|--------------------------|-------------------|
| F011h | 4.25 |
| F80Bh | 5.5 |
| F80Dh | 6.5 |
| F80Fh | 7.5 |
| F811h | 8.5 |
| F813h | 9.5 |
| F815h | 10.5 |
| F817h | 11.5 |

7.5.18.2 (5Ah) VIN_UV_FAULT_RESPONSE

The VIN UV FAULT RESPONSE command instructs the device on what action to take in response to an input overvoltage fault. The VIN UV FAULT RESPONSE command must be accessed through Read Byte transactions. The VIN UV FAULT RESPONSE command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

In response to the VIN UV LIMIT being exceeded, the device will:

- Set the OTHER bit in the STATUS BYTE
- Set the INPUT bit in the upper byte of the STATUS_WORD
- Set the VIN UV FAULT bit in the STATUS INPUT register
- The device notifies the host (asserts PMB ALERT, if the corresponding mask bit in SMBALERT MASK is not set)



| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | | |
|---|-------------|---|---|---|---|---|---|--|--|--|--|
| R | R | R | R | R | R | R | R | | | | |
| | VI UVF RESP | | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

VIN_UV_FAULT_RESPONSE

Table 51. VIN_UV_FAULT_RESPONSE Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|-------------|------|-------|--|
| 7:0 | VI_UVF_RESP | R | COII | C0h: Shutdown and restart when the fault condition is no longer present. |

7.5.19 Input Overcurrent Protection and Response

Input overcurrent protection is configured via the IIN_OC_FAULT_LIMIT, IIN_OC_WARN_LIMIT and IIN_OC_FAULT_RESPONSE commands.

7.5.19.1 (5Bh) IIN_OC_FAULT_LIMIT

The IIN_OC_FAULT_LIMIT command sets the value of the input current, in amperes, that causes the input over current fault condition. IIN_OC_FAULT_LIMIT is a linear format command, and must be accessed through Read Word/Write Word transactions. The IIN_OC_FAULT_LIMIT command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | |
|-------------|----|-------------|----|----|-------------|----|----|--|--|
| R | R | R | R | R | RW | RW | RW | | |
| | | IIN_OCF_EXP | | | IIN_OCF_MAN | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | |
| RW | RW | RW | RW | RW | RW | RW | RW | | |
| IIN_OCF_MAN | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

IIN OC FAULT LIMIT

Table 52. IIN_OC_FAULT_LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-------------|------|---------------|--|
| 15:11 | IIN_OCF_EXP | R | 11111b | Linear two's complement format exponent, -1. LSB = 0.5 A. |
| 10:0 | IIN_OCF_MAN | RW | See below. | Linear two's complement format mantissa. Acceptable values range from 0d (0 A) to 127d (63.5 A). |

During operation, the IIN_OC_FAULT_LIMIT may be changed to any valid value, as specified above. The IIN_OC_FAULT_LIMIT command has only limited NVM backup. The table below summarizes the values that IIN_OC_FAULT_LIMIT may be restored to following a reset, or RESTORE_DEFAULT_ALL operation.

Table 53. IIN_OC_FAULT_LIMIT reset values

| Hex Value | IIN_OC_FAULT_LIMIT during NVM store operation | IIN_OC_FAULT_LIMIT following Reset/Restore Operation | | |
|-----------|---|---|--|--|
| F810h | 8 A | 8 A | | |
| F820h | 16 A | 16 A | | |
| F830h | 24 A | 24 A | | |
| F840h | 32 A | 32 A | | |
| F850h | 40 A | 40 A | | |
| F860h | 48 A | 48 A | | |
| F870h | 56 A | 56 A | | |

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Table 53. IIN_OC_FAULT_LIMIT reset values (continued)

| Hex Value | IIN_OC_FAULT_LIMIT during NVM store operation | IIN_OC_FAULT_LIMIT following Reset/Restore Operation |
|----------------------|---|---|
| F87Fh | 63.5 A | 63.5 A |
| Any other valid data | Any other valid data | 63.5 A |

7.5.19.2 (5Dh) IIN_OC_WARN_LIMIT

The IIN_OC_WARN_LIMIT command sets the value of the input current, in amperes, that causes the input overcurrent warning condition. The IIN OC WARN LIMIT command must be accessed through Read Word/Write Word transactions. The IIN OC WARN LIMIT command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

Upon triggering the over-current warning, the following actions are taken:

- Set the OTHER bit in the STATUS BYTE
- Set the INPUT bit in the STATUS WORD
- Set the IIN Over-current Warning bit in the STATUS_INPUT register
- The device notifies the host (asserts PMB ALERT, if the corresponding mask bit in SMBALERT MASK is not set)

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | | | |
|----|-------------|-------------|----|----|-------------|----|----|--|--|--|
| R | R | R | R | R | R | R | R | | | |
| | | IIN_OCW_EXP | | | IIN_OCW_MAN | | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | |
| R | RW | RW | RW | RW | RW | RW | RW | | | |
| | IIN OCW MAN | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

IIN OC WARN LIMIT

Table 54. IIN_OC_FAULT_LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|-------------|------|---------------|--|
| 15:11 | IIN_OCW_EXP | R | 11111b | Linear two's complement format exponent, -1. LSB = 0.5 A. |
| 10:0 | IIN_OCW_MAN | RW | See below. | Linear two's complement format mantissa. Acceptable values range from 0d (0 A) to 127d (63.5 A). |

During operation, the IIN_OC_FAULT_LIMIT may be changed to any valid value, as specified above. The IIN_OC_FAULT_LIMIT command has only limited NVM backup. The table below summarizes the values that IIN OC FAULT LIMIT may be restored to following a reset, or RESTORE DEFAULT ALL operation.

Table 55. IIN OC WARN LIMIT reset values

| Hex Value | IIN_OC_WARN_LIMIT during NVM store operation | IIN_OC_WARN_LIMIT following Reset/Restore Operation |
|----------------------|--|--|
| F810h | 8 A | 8 A |
| F820h | 16 A | 16 A |
| F830h | 24 A | 24 A |
| F840h | 32 A | 32 A |
| F850h | 40 A | 40 A |
| F860h | 48 A | 48 A |
| F870h | 56 A | 56 A |
| F87Fh | 63.5 A | 63.5 A |
| Any other valid data | Any other valid data | 63.5 A |





7.5.19.3 (5Ch) IIN OC FAULT RESPONSE

The IIN_OC_FAULT_RESPONSE command instructs the device on what action to take in response to an input over-current fault. IIN_OC_FAULT_RESPONSE command must be accessed through Read Byte transactions. The IIN_OC_FAULT_RESPONSE command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

Upon triggering the input over-current fault, the controller is latched off, and the following actions are taken:

- Set the OTHER bit in the STATUS BYTE
- · Set the INPUT bit in the STATUS WORD
- Set the IIN OC FAULT bit in the STATUS INPUT register
- The device notifies the host (asserts PMB_ALERT and VR_FAULT, if the corresponding mask bit in SMBALERT_MASK is not set)

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | | |
|---|-------------|---|---|---|---|---|---|--|--|--|--|
| R | R | R | R | R | R | R | R | | | | |
| | IIN_OC_RESP | | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

IIN OC FAULT RESPONSE

Table 56. IIN OC FAULT LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|-------------|------|-------|---|
| 7:0 | IIN_OC_RESP | R | C0h | C0h: Latch-off and do not restart. To clear a shutdown event due to a fault event, the user must toggle the AVR_EN/BEN pin and/or the ON bit in OPERATION, per the settings in ON_OFF_CONFIG, or power cycle the bias power to the V3P3 pin of the controller device. |

7.5.20 Over-Temperature Protection and Response

Overtemperature protection is configured via the OT_FAULT_LIMIT, OT_WARN_LIMIT and OT_FAULT_RESPONSE commands.

7.5.20.1 (4Fh) OT_FAULT_LIMIT

The OT_FAULT_LIMIT command sets the value of the temperature limit, in degrees Celsius, that causes an overtemperature fault condition when the sensed temperature from the external sensor exceeds this limit. The default value is selected inMFR_SPECIFIC_13, using the OTF_DFLT bit. Refer to the device *Technical Reference Manual* for more information. OT_FAULT_LIMIT is a linear format command, and must be accessed through Read Word/Write Word transactions. OT_FAULT_LIMIT is a paged register. In order to access OT_FAULT_LIMIT command for channel A, PAGE must be set to 00h. In order to access OT_FAULT_LIMIT register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | |
|---------|----|---------|----|----|----|---------|----|--|
| R | R | R | R | R | RW | RW | RW | |
| | | OTF_EXP | | | | OTF_MAN | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| RW | RW | RW | RW | RW | RW | RW | RW | |
| OTF_MAN | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

OT_FAULT_LIMIT

Table 57. OT FAULT LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description | | |
|-------|---------|------|--------|---|--|--|
| 15:11 | OTF_EXP | R | 00000b | Linear two's complement exponent, 0. LSB = 1 °C | | |
| 10:0 | OTF_MAN | RW | NVM | Linear two's complement mantissa. The default OT_FAULT_LIMIT is set by the OTF_DFLT bit in MFR_SPECIFIC_13. | | |

7.5.20.2 (51h) OT_WARN_LIMIT

The OT WARN LIMIT command sets the temperature, in degrees Celsius, of the unit at which it should indicate an Over-temperature Warning event. OT_WARN_LIMIT is a linear format command, and must be accessed through Read Word/Write Word transactions. OT_WARN_LIMIT is a paged register. In order to access OT WARN LIMIT command for channel A, PAGE must be set to 00h. In order to access OT WARN LIMIT register for channel B, PAGE must be set to 01h. For simultaneous access of channels A and B, the PAGE command must be set to FFh.

In response to the OT WARN LIMIT being exceeded, the device will:

- Set the TEMPERATURE bit in the STATUS_BYTE
- Set the Over-temperature Warning bit in the STATUS_TEMPERATURE register
- Notify the host (asserts PMB_ALERT, if the corresponding mask bit in SMBALERT_MASK is not set)

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|----|-----------|---------|----|----|----|---------|----|
| R | R | R | R | R | RW | RW | RW |
| | | OTW_EXP | | • | | OTW_MAN | • |
| 7 | 7 6 5 4 3 | | | | | 4 | 0 |
| , | б | 5 | 4 | 3 | 2 | 1 | U |
| RW | RW | RW | RW | RW | RW | RW | RW |

LEGEND: R/W = Read/Write; R = Read only

OT_WARN_LIMIT

Table 58. OT WARN LIMIT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|---------|------|--------|--|
| 15:11 | OTF_EXP | R | 00000b | Linear two's complement exponent, 0. LSB = 1 °C |
| 10:0 | OTF_MAN | RW | 105d | Linear two's complement mantissa. Default = 105 °C |

7.5.20.3 (50h) OT_FAULT_RESPONSE

The OT_FAULT_RESPONSE instructs the device on what action to take in response to an output overtemperature fault. The OT_FAULT_RESPONSE command must be accessed through Read Byte/Write Byte transactions. The OT_FAULT_RESPONSE command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

Upon triggering the over-temperature fault, the controller is latched off, and the following actions are taken:

- Set the TEMPERATURE bit in the STATUS BYTE
- Set the OT_FAULT bit in the STATUS_TEMPERATURE register
- The device notifies the host (asserts PMB ALERT, if the corresponding mask bit in SMBALERT MASK is not set).

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----|----|----|------|------|----|----|----|
| RW | RW | RW | RW | RW | RW | RW | RW |
| | | | OTF_ | RESP | | | |

LEGEND: R/W = Read/Write; R = Read only



OT_FAULT_RESPONSE

Table 59. OT_FAULT_RESPONSE Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|----------|------|-------|---|
| 7:0 | OTF_RESP | RW | NVM | 80h: Latch-off and do not restart. To clear a shutdown event due to a fault event, the user must toggle the AVR_EN/BEN pin and/or the ON bit in OPERATION, per the settings in ON_OFF_CONFIG, or power cycle the bias power to the V3P3 pin of the controller device. C0h: Shutdown and restart when the fault condition is no longer present. |



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7.5.21 Dynamic Phase Shedding (DPS)

The dynamic phase shedding (DPS) feature allows the TPS53681 to dynamically select the number of operational phases for each channel, based on the total output current. This increases the total converter efficiency by reducing unnecessary switching losses when the output current is low enough to be supported by a fewer number of phases, than are available in hardware. The MFR_SPECIFIC_14 and MFR_SPECIFIC_15 commands may be used to configure dynamic phase shedding behavior and thresholds.

The DPS_EN bit in MFR_SPECIFIC_14 may be used to enable or disable dynamic phase shedding. Un-setting (writing to 0b) this bit forces each channel to use the maximum number of available phases, regardless of the output current.

The phase add/drop thresholds, at which phases are added or dropped are configured based on the peak efficiency point per phase. For a given switching frequency/duty cycle, the efficiency of an individual power stage has a "peak" point, at which switching losses become less significant and conduction losses begin to dominate. For a multiphase converter, the optimum efficiency is achieved when all of the power stages operate as close as possible to their peak efficiency point. For example, consider a 4-phase design, with power stages that have a peak efficiency point of 12 A per phase. When the total output current is 25 A, if all four phases were active, each phase would be supplying 6.25 A, and hence would be operating far away from their peak efficiency point. With only two phases active, however, each phase supplies 12.5A, meaning that each power stage is operating close to its peak efficiency point, therefore the total converter efficiency is higher overall.

In order to maintain regulation during severe load transient events, phases may be added immediately whenever the total peak current reaches phase addition thresholds. To prevent chattering, phases are dropped when the total average current falls below phase drop thresholds, after a delay of 85 µs typically. Phases are always added/dropped, in numerical order. For example, phase 3 is added after phase 2, and dropped after phase 4.

The DPS_COURSE_TH bits in MFR_SPECIFIC_15 select the peak efficiency point per phase. Refer to the power stage datasheet to determine the peak efficiency point per phase.

Phase adding thresholds are configured based on the peak efficiency point per phase. Each phase transition has a configurable threshold of 6 A to 12 A above the peak efficiency point. For example, the threshold at which the converter transitions from 2 phases to 3 phases is determined by the DPS_2TO3_FINE_ADD bits in MFR_SPECIFIC_15. When 8 A is selected, the total peak current which causes the third phase to be added is 2 \times I_{FFF(PFAK)} + 8 A. See the register descriptions below for more detailed information.

Likewise, phase drop thresholds are configured based on the peak efficiency point per phase. Each phase transition has a configurable threshold of 2A below A to 4 A above the peak efficiency point. For example, the threshold at which the converter transitions from 3 phases to 2 phases is determined by the DPS_3TO2_FINE_DROP bits in MFR_SPECIFIC_14. When 0 A is selected, the total average current which causes the third phase to be dropped is 2 \times I_{EFF(PEAK)}. See the register descriptions below for more detailed information.

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7.5.21.1 (DEh) MFR_SPECIFIC_14

The MFR_SPECIFIC_14 command is used to configure dynamic phase shedding, and compensation ramp amplitude, and dynamic ramp amplitude during USR, and different power states. The MFR_SPECIFIC_14 command must be accessed through Write Word/Read Word transactions.

MFR_SPECIFIC_14 is a paged register. In order to access MFR_SPECIFIC_14 command for channel A, PAGE must be set to 00h. In order to access the MFR_SPECIFIC_14 register for channel B, PAGE must be set to 01h.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|--------|----------------------|----|----------------------|-------------------------------------|----|--------------------|----|
| RW | RW | RW | RW | RW | RW | RW | RW |
| | FINE_DROP 0 only) | | FINE_DROP 0 only) | DPS_4TO3_FINE_DROP (PAGE 0 only) | | DPS_3TO2_FINE_DROP | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| RW | RW | RW | RW | RW | RW | RW | RW |
| DPS_EN | DPS_EN DYN_RAMP_USR | | DYN_RAMP_2 PH | DYN_RAMP_1 PH | | RAMP | |

LEGEND: R/W = Read/Write; R = Read only

MFR_SPECIFIC_14

Table 60. MFR SPECIFIC 14 Register Field Descriptions

| | | _ | | Register Field Descriptions |
|-------|-------------------------------------|------|-------|--|
| Bit | Field | Туре | Reset | Description |
| 15:14 | DPS_6TO5_FINE_DROP (PAGE 0 only) | RW | NVM | Dynamic phase drop threshold, fine adjustment, 6 phases to 5 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases drop when average phase current reaches the stated threshold. $I_{EFF(PEAK)}$ refers to the value selected by DPS_COURSE_TH in MFR_SPECIFIC_15. 00b: Threshold = $5 \times I_{EFF(PEAK)} - 2 \text{ A}$ 01b: Threshold = $5 \times I_{EFF(PEAK)} + 2 \text{ A}$ 11b: Threshold = $5 \times I_{EFF(PEAK)} + 4 \text{ A}$ |
| 13:12 | DPS_5TO4_FINE_DROP (PAGE 0 only) | RW | NVM | Dynamic phase drop threshold, fine adjustment, 5 phases to 4 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases drop when average phase current reaches the stated threshold. I _{EFF(PEAK)} refers to the value selected by DPS_COURSE_TH in MFR_SPECIFIC_15. 00b: Threshold = 4 × I _{EFF(PEAK)} - 2 A 01b: Threshold = 4 × I _{EFF(PEAK)} + 2 A 11b: Threshold = 4 × I _{EFF(PEAK)} + 4 A |
| 11:10 | DPS_4TO3_FINE_DROP (PAGE 0 only) | RW | NVM | Dynamic phase drop threshold, fine adjustment, 4 phases to 3 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases drop when average phase current reaches the stated threshold. $I_{EFF(PEAK)}$ refers to the value selected by DPS_COURSE_TH in MFR_SPECIFIC_15. 00b: Threshold = $3 \times I_{EFF(PEAK)} - 2$ A 01b: Threshold = $3 \times I_{EFF(PEAK)}$ + 2 A 11b: Threshold = $3 \times I_{EFF(PEAK)} + 4$ A |
| 9:8 | DPS_3TO2_FINE_DROP | RW | NVM | Dynamic phase drop threshold, fine adjustment, 3 phases to 2 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases drop when average phase current reaches the stated threshold. $I_{EFF(PEAK)}$ refers to the value selected by DPS_COURSE_TH in MFR_SPECIFIC_15. 00b: Threshold = $2 \times I_{EFF(PEAK)} - 2 \text{ A}$ 01b: Threshold = $2 \times I_{EFF(PEAK)} + 2 \text{ A}$ 11b: Threshold = $2 \times I_{EFF(PEAK)} + 4 \text{ A}$ |

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Table 60. MFR_SPECIFIC_14 Register Field Descriptions (continued)

| Bit | Field | Туре | Reset | Description |
|-----|--------------|------|-------|---|
| 7 | DPS_EN | RW | NVM | Enable or Disable Dynamic Phase Shedding Ob: Disable dynamic phase shedding 1b: Enable dynamic phase shedding |
| 6:5 | DYN_RAMP_USR | RW | NVM | Dynamic ramp amplitude setting during USR operation. Only applies to USR Level 1. 00b: Equal to the settings in the RAMP bits 01b: 40 mV 10b: 80 mV 11b: 120 mV |
| 4 | DYN_RAMP_2PH | RW | NVM | Dynamic ramp amplitude setting during 2 phase operation. 0b: Equal to the settings in the RAMP bits 1b: 120 mV |
| 3 | DYN_RAMP_1PH | RW | NVM | Dynamic ramp amplitude setting during 1 phase operation. 0b: Equal to the settings in the RAMP bits 1b: 80 mV |
| 2:0 | RAMP | RW | NVM | Ramp amplitude settings. See Table 61. |

Table 61. Ramp Amplitude Settings

| RAMP (binary) | Ramp Amplitude Setting (mV) |
|---------------|-----------------------------|
| 000b | 40 |
| 001b | 80 |
| 010b | 120 |
| 011b | 160 |
| 100b | 200 |
| 101b | 240 |
| 110b | 280 |
| 111b | 320 |

7.5.21.2 (DFh) MFR_SPECIFIC_15

The MFR_SPECIFIC_15 command is used to configure dynamic phase shedding. The MFR_SPECIFIC_15 command must be accessed through Write Word/Read Word transactions.

MFR_SPECIFIC_15 is a paged register. In order to access MFR_SPECIFIC_15 command for channel A, PAGE must be set to 00h. In order to access the MFR_SPECIFIC_15 register for channel B, PAGE must be set to 01h.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|--|-----------|-----------|----------|----------------------|--------------------|--|---------|
| RW | RW | RW | RW | RW | RW | RW | RW |
| DPS_DCM | DPS_2TO1_ | FINE_DROP | | _FINE_ADD 0 only) | DPS_4TO5_ (PAGE | DPS_3TO4_FI NE_ADD (PAGE 0 only) | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| RW | RW | RW | RW | RW | RW | RW | RW |
| DPS_3TO4_FI NE_ADD (PAGE 0 only) | DPS_2TO3 | _FINE_ADD | DPS_1TO2 | _FINE_ADD | 2TO1_PH_EN | DPS_CO | URSE_TH |

LEGEND: R/W = Read/Write; R = Read only

MFR_SPECIFIC_15



Table 62. MFR_SPECIFIC_15 Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-------|---------------------------------|------|-------|---|
| 15 | DPS_DCM | RW | NVM | Enable DCM mode during 1 phase operation, when higher order phases are dropped due to dynamic phase shedding. 0b: Disable DCM operation during 1 phase operation 1b: Enable DCM operation during 1 phase operation |
| 14:13 | DPS_2TO1_FINE_DROP | RW | NVM | Dynamic phase drop threshold, fine adjustment, 2 phases to 1 phase. Set as an offset from peak efficiency point per phase in Amperes. Phases drop when average phase current reaches the stated threshold. $I_{EFF(PEAK)}$ refers to the value selected by DPS_COURSE_TH below. 00b: Threshold = $1 \times I_{EFF(PEAK)} - 2 \text{ A}$ 01b: Threshold = $1 \times I_{EFF(PEAK)} + 2 \text{ A}$ 11b: Threshold = $1 \times I_{EFF(PEAK)} + 2 \text{ A}$ 11b: Threshold = $1 \times I_{EFF(PEAK)} + 4 \text{ A}$ |
| 12:11 | DPS_5TO6_FINE_ADD (PAGE 0 only) | RW | NVM | Dynamic phase add threshold, fine adjustment, 5 phases to 6 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases add when peak phase current reaches the stated threshold. $I_{EFF(PEAK)}$ refers to the value selected by DPS_COURSE_TH below. 00b: Threshold = $5 \times I_{EFF(PEAK)} + 6A$ 01b: Threshold = $5 \times I_{EFF(PEAK)} + 8 A$ 10b: Threshold = $5 \times I_{EFF(PEAK)} + 10 A$ 11b: Threshold = $5 \times I_{EFF(PEAK)} + 12 A$ |
| 10:9 | DPS_4TO5_FINE_ADD (PAGE 0 only) | RW | NVM | Dynamic phase add threshold, fine adjustment, 4 phases to 5 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases add when peak phase current reaches the stated threshold. I _{EFF(PEAK)} refers to the value selected by DPS_COURSE_TH below 00b: Threshold = 4 × I _{EFF(PEAK)} + 6A 01b: Threshold = 4 × I _{EFF(PEAK)} + 8 A 10b: Threshold = 4 × I _{EFF(PEAK)} + 10 A 11b: Threshold = 4 × I _{EFF(PEAK)} + 12 A |
| 8:7 | DPS_3TO4_FINE_ADD (PAGE 0 only) | RW | NVM | Dynamic phase add threshold, fine adjustment, 3 phases to 4 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases add when peak phase current reaches the stated threshold. $I_{\text{EFF}(\text{PEAK})}$ refers to the value selected by DPS_COURSE_TH below 00b: Threshold = $3 \times I_{\text{EFF}(\text{PEAK})} + 6A$ 01b: Threshold = $3 \times I_{\text{EFF}(\text{PEAK})} + 8$ A 10b: Threshold = $3 \times I_{\text{EFF}(\text{PEAK})} + 10$ A 11b: Threshold = $3 \times I_{\text{EFF}(\text{PEAK})} + 12$ A |
| 6:5 | DPS_2TO3_FINE_ADD | RW | NVM | Dynamic phase add threshold, fine adjustment, 2 phases to 3 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases add when peak phase current reaches the stated threshold. $I_{\text{EFF}(\text{PEAK})}$ refers to the value selected by DPS_COURSE_TH below 00b: Threshold = $2 \times I_{\text{EFF}(\text{PEAK})} + 6A$ 01b: Threshold = $2 \times I_{\text{EFF}(\text{PEAK})} + 8$ A 10b: Threshold = $2 \times I_{\text{EFF}(\text{PEAK})} + 10$ A 11b: Threshold = $2 \times I_{\text{EFF}(\text{PEAK})} + 12$ A |



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Table 62. MFR_SPECIFIC_15 Register Field Descriptions (continued)

| Bit | Field | Туре | Reset | Description |
|-----|---------------------|------|--------|--|
| 5:4 | DPS 1TO2 FINE ADD | RW | NVM | Dynamic phase add threshold, fine adjustment, 1 phase to 2 phases. Set as an offset from peak efficiency point per phase in Amperes. Phases add when peak phase current reaches the stated threshold. I _{EFF(PEAK)} refers to the value selected by DPS_COURSE_TH below |
| 3.4 | DI 3_1102_1 INC_ADD | IXVV | INVIVI | 00b: Threshold = $1 \times I_{EFF(PEAK)} + 6A$ |
| | | | | 01b: Threshold = $1 \times I_{EFF(PEAK)} + 8 A$ |
| | | | | 10b: Threshold = $1 \times I_{EFF(PEAK)} + 10 A$ |
| | | | | 11b: Threshold = $1 \times I_{EFF(PEAK)} + 12 A$ |
| | | | | Enable phase dropping from 2 phases to 1 phase operation. |
| 3 | 2TO1_PH_EN | RW | NVM | 0b: Disable phase shedding to 1 phase |
| | | | | 1b: Enable phase shedding to 1 phase |
| | | | | Sets the peak efficiency point per phase. This is used to determine phase add/drop thresholds. |
| 2:0 | DPS COURSE TH | RW | NVM | 00b: I _{EFF(PEAK)} = 12 A |
| 2.0 | DF3_COUNSE_IFI | KVV | INVIVI | 01b: I _{EFF(PEAK)} = 14 A |
| | | | | 10b: I _{EFF(PEAK)} = 16 A |
| | | | | 11b: I _{EFF(PEAK)} = 18 A |

TEXAS INSTRUMENTS

7.5.22 NVM Programming

The USER_DATA_00 - USER_DATA_12 commands are provided to streamline NVM programming. These 6-byte block commands are mapped internally to all of the user-configurable parameters the TPS53681 supports. The MFR_SERIAL command also provides a checksum, to streamline verification of desired programming values.

The generalized procedure for programming the TPS53681 is summarized below.

Configure User-Programmable Parameters

- 1. First, configure all of the user-accessible parameters via the standard PMBus, and Manufacturer Specific commands. TI provides the Fusion Digital Power Designer graphical interface software to streamline this step. The user can also refer to the *Technical Reference Manual* for a full set of register maps for these commands.
- 2. Once the device is configured as desired, issue the STORE_DEFAULT_ALL command to commit these values to NVM, and update the checksum value. Wait approximately 100 ms after issuing STORE_DEFAULT_ALL before communicating with the device again.
- 3. Write PAGE to 00h
- 4. Read-back and Record the value of IC DEVICE ID and IC DEVICE REV commands
- 5. Read-back and Record the value of the USER DATA 00 through USER DATA 12 commands
- 6. Read-back and Record the value of the MFR_SERIAL command
- 7. Read-back and Record the value of VOUT_MAX
- 8. Write PAGE to 01h
- 9. Read-back and Record the value of VOUT MAX

Program and Verify NVM (repeat for each device)

- 1. Power the device by supplying +3.3V to the V3P3 pin. Power conversion should be disabled for NVM programming.
- 2. Read-back and verify that IC_DEVICE_ID and IC_DEVICE_REV values match those recorded previously. This ensures that user-parameters being programmed correspond to the same device/revision as previously configured.
- 3. Write PAGE to 00h.
- 4. Write the USER_DATA_00 through USER_DATA_12 commands, with the values recorded previously.
- 5. Write VOUT_MAX (Page 0) with the value recorded previously.
- 6. Write PAGE to 01h
- 7. Write VOUT_MAX (Page 1) with the value recorded previously.
- 8. Issue STORE_DEFAULT_ALL. Wait appx 100 ms after issuing STORE_DEFAULT_ALL before communicating with the device again.
- 9. Read-back the MFR_SERIAL command, and compare the value to that recorded previously. If the new MFR SERIAL matches the value recorded previously, NVM programming was successful.

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7.5.23 NVM Security

The MFR_SPECIFIC_42 command can be optionally used to set a password for NVM programming. To prevent a hacker from simply sending the password command with all possible passwords, the TPS53681 goes into a special extra-secure state when an incorrect password is received. In this state, all passwords are rejected, even the valid one. The device must be power cycled to clear this state so that another password attempt may be made. When NVM security is enabled, the TPS53681 will not accept writes to any command other than PAGE and PHASE, which are necessary for reading certain parameters.

Enabling NVM Security

- 1. Set the NVM password. Write MFR_SPECIFIC_42 to a value other than FFFFh.
- 2. Issue STORE DEFAULT ALL
- 3. Wait 100ms for the NVM store to complete
- 4. Power cycle V3P3. NVM Security will be enabled at the next power-up.

Disabling NVM Security

To disable NVM security, use the following procedure:

1. Write the password to MFR_SPECIFIC_42 to disable NVM security. Once the correct password has been given, NVM security will be disabled, and the device will once again accept write transactions to configuration registers.

NVM security will be re-enabled at the next power-on, unless MFR_SPECIFIC_42 is set to FFFFh (NVM Security Disabled), and an NVM store operation (issue STORE_DEFAULT_ALL and wait 100 ms) is performed.

Determining Whether NVM Security is Active

Reads to the MFR_SPECIFIC_42 command returns one of three values:

- 0000h = NVM Security is Disabled
- 0001h = NVM Security is Enabled
- 0002h = MFR_SPECIFIC_42 is locked due to incorrect password entry

7.5.23.1 (FAh) MFR_SPECIFIC_42

MFR_SPECIFIC_42 is used for NVM Security. The MFR_SPECIFIC_42 command must be accessed through Read Word/Write Word transactions.

MFR_SPECIFIC_42 is a shared register. Write transactions to this register will apply to both channels, and read transactions to this register returns the same data regardless of the current PAGE.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | |
|----|------------------|----|----|----|----|----|----|--|
| RW | RW | RW | RW | RW | RW | RW | RW | |
| | NVM_SECURITY_KEY | | | | | | | |
| 7 | 6 | 5 | 4 | 3 | 1 | 0 | | |
| | | | | | | | | |
| RW | RW | RW | RW | RW | RW | RW | RW | |

LEGEND: R/W = Read/Write; R = Read only

MFR SPECIFIC 42

Table 63. MFR SPECIFIC 42 Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|------------------|------|-------|-----------------------------------|
| 7:0 | NVM_SECURITY_KEY | RW | NVM | 16 bit code for NVM security key. |

TEXAS INSTRUMENTS

7.5.24 Black Box Recording

The TPS53681 provides a "black box" feature to aid in system-level debugging. According to the PMBus specification, status bits are latched whenever the condition causing them occurs, regardless of whether or not other status bits are already set. This, however, makes it difficult for the system designer to understand which fault condition occurred first, in the case that one fault condition causes others to trigger. The MFR_SPECIFIC_08 command provides a "snapshot" of the first faults to occur chronologically, for each channel, which may be stored to NVM, for future debugging. Only the most catastrophic fault conditions are logged, such as the over-voltage fault, over-current fault, and power stage failure. The black box command may also be reset, or cleared by writing 00h to the register, and storing to NVM if the NVM value must also be cleared.

Resetting the Black Box Record

Resetting the record allows the user to determine which faults occur first, *after* the register is cleared. To clear the record, write 00h to MFR_SPECIFIC_08, and issue STORE_DEFAULT_ALL.

Triggering Black Box Recording

Black box recording is always active, whether or not the TPS53681 is converting power. Note however many of the critical faults summarized in MFR_SPECIFIC_08 are only possible to trigger during power conversion. Whenever any of the following catastrophic faults occur, the MFR_SPECIFIC_08 register will be updated according to the register description below, but only if the black box record has been cleared since the last catastrophic faults occurred. Faults logged include:

- Overvoltage Fault (Device was Converting Power)
- Overvoltage Fault (Device was not Converting Power)
- Input Overcurrent Fault
- Output Overcurrent Fault
- Power Stage Fault
- Input Over-Power Fault

Retrieving the Black Box Record

Reading the MFR_SPECIFIC_08 returns the current value of the Black Box record. If the register reads 00h, no catastrophic faults have occurred since the record was last cleared. If any value other than 00h is stored in the register, then de-code the value according to the register description below. In order to read-back the black box record following a power-down, the STORE_DEFAULT_ALL command must be issued, to store the contents of the black box record to NVM.

7.5.24.1 (D8h) MFR SPECIFIC 08

The MFR_SPECIFIC_08 command is used to identify catastrophic faults which occur first, and store this information to NVM. See the product datasheet for more information. The MFR_SPECIFIC_08 command must be accessed through Write Byte/Read Byte transactions. MFR_SPECIFIC_08 is a shared register. Transactions to this register do not require specific PAGE settings. However, note that channels A and B have independent bit fields within the command.

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|----|--------|----|----|--------|----|
| R | R | RW | RW | RW | RW | RW | RW |
| 0 | 0 | | CF_CHA | | | CF_CHB | |

LEGEND: R/W = Read/Write; R = Read only

MFR_SPECIFIC_08

Table 64. MFR_SPECIFIC_08 Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|----------|------|-------|--|
| 7:6 | Not used | R | 0 | Not used and set to 0. |
| 5:3 | CF_CHA | RW | NVM | Catastrophic fault record for channel A. |
| 2:0 | CF_CHB | RW | NVM | Catastrophic fault record for channel B. |



Whenever a catastrophic fault occurs, the first event detected will trigger the MFR_SPECIFIC_08 command to update according to the tables below. This recording happens independently for channel A and channel B. If the PMBus host issues a STORE_DEFAULT_ALL, this information will be committed to NVM, and may be retrieved at a later time. In order to clear the record for either channel, the PMBus host must write the corresponding bits (CF_CHA for channel A, CF_CHB for channel B) to 000b, and issue STORE_DEFAULT_ALL.

Attempts to write any non-zero value to this command will be treated as invalid data - data will be ignored, the appropriate flags in STATUS_CML, and STATUS_WORD, will be set, and the PMB_ALERT pin will be asserted to notify the host of the invalid transaction.

| • | |
|--------------------------|---|
| CF_CHA / CF_CHB (binary) | Interpretation |
| 000b | No fault occurred |
| 001b | OVF occurred, power conversion was disabled |
| 010b | OVF occurred, power conversion was enabled |
| 011b | IIN Overcurrent fault occurred |
| 100b | IOUT Overcurrent fault occurred |
| 101b | Overtemperature fault occurred |
| 110b | Power stage fault occurred |
| 111b | Input overpower warning occurred |

Table 65. Catastrophic Fault Recording Interpretation

7.5.25 Board Identification and Inventory Tracking

The TPS53681 provides several bytes of arbitrarily programmable NVM-backed memory to allow for inventory management and board identification. By default, these values reflect information about the date/revision of the TPS53681 device being used itself. However, they may be re-programmed by the user, at the board level during manufacturing. This provides a convenient and easy to use method of tracking boards, revisions and manufacturing dates. The following commands are provided for this purpose:

- MFR ID 16 bits of NVM for end-users to track the PCB/power supply supplier name
- MFR_MODEL 16 bits of NVM for tracking the manufacturer model number
- MFR_REVISION 16 bits of NVM for tracking PCB/power supply revision code
- MFR_DATE 16 bits of NVM for tracking PCB manufacturing date code

7.5.25.1 (9Ah) MFR MODEL

The MFR MODEL command is used to either set or read the manufacturer's model number.

The MFR_MODEL command must be accessed through Block Write/Block Read transactions.

The MFR_MODEL command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | |
|---------|-----------|---------|---------|---------|---------|---------|---------|--|
| RW | RW | RW | RW | RW | RW | RW | RW | |
| | MFR_MODEL | | | | | | | |
| | | | | | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| 7 RW | 6 RW | 5 RW | 4 RW | 3 RW | 2 RW | 1 RW | 0 RW | |

LEGEND: R/W = Read/Write; R = Read only

MFR MODEL

Table 66. MFR_MODEL Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|------|-----------|------|-------|---|
| 15:0 | MFR_MODEL | RW | NVM | Arbitrary 16 bits with NVM backup for Model number identification |

TEXAS INSTRUMENTS

7.5.25.2 (9Bh) MFR_REVISION

The MFR_REVISION command is used to either set or read the manufacturer's revision number

The MFR_REVISION command must be accessed through Block Write/Block Read transactions.

The MFR_REVISION command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|---------|---------|---------|---------|---------|---------|---------|---------|
| RW |
| | | | MFR. | _REV | | | |
| | | | | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| 7 RW | 6 RW | 5 RW | 4 RW | 3 RW | 2 RW | 1 RW | 0 RW |

LEGEND: R/W = Read/Write; R = Read only

MFR_REVISION

Table 67. MFR_REVISION Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|------|---------|------|-------|--|
| 15:0 | MFR_REV | RW | NVM | Arbitrary 16 bits with NVM backup for revision number identification |

7.5.25.3 (9Dh) MFR_DATE

The MFR_DATE command is used to either set or read the manufacturing date.

The MFR DATE command must be accessed through Block Write/Block Read transactions.

The MFR_DATE command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|---------|---------|---------|---------|---------|---------|---------|---------|
| RW |
| | | | MFR_ | DATE | | | |
| | | | | | | | |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| 7 RW | 6 RW | 5 RW | 4 RW | 3 RW | 2 RW | 1 RW | 0 RW |

LEGEND: R/W = Read/Write; R = Read only

MFR_DATE

Table 68. MFR_DATE Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|------|----------|------|-------|---|
| 15:0 | MFR_DATE | RW | NVM | Arbitrary 16 bits with NVM backup for manufacture date identification |



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7.5.26 Status Reporting

The TPS53681 provides several registers containing status information. The flags in these registers are latched whenever their corresponding condition occurs, and are not cleared until either the CLEAR_FAULTS command is issued, or the host writes a value of 1b to that bit location. Register maps for the all of the supported status registers are shown in the following sections.

7.5.26.1 (78h) STATUS BYTE

The STATUS_BYTE command returns one byte of information with a summary of the most critical faults, such as over-voltage, overcurrent, over-temperature, etc.

The STATUS_BYTE command must be accessed through Read Byte transactions. STATUS_BYTE is a paged register. In order to access STATUS_WORD command for channel A, PAGE must be set to 00h. In order to access STATUS_WORD register for channel B, PAGE must be set to 01h. If PAGE is set FFh, the device return value will reflect the status of Channel A.

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------|-----|---------|---------|--------|------|-----|-------|
| 0 | R | R | R | R | R | R | R |
| BUSY | OFF | VOUT_OV | IOUT_OC | VIN_UV | TEMP | CML | OTHER |

Figure 15. STATUS_BYTE

Table 69. STATUS_BYTE Register Field Descriptions

| | Tuble 60. OTAT 66_BTTL Register Field Descriptions | | | | | | |
|-----|--|------|-------------------|---|--|--|--|
| Bit | Field | Type | Reset | Description | | | |
| 7 | BUSY | R | 0 | Not supported and always set to 0. | | | |
| 6 | OFF | R | Current Status | This bit is asserted if the unit is not providing power to the output, regardless of the reason, including simply not being enabled. 0: Raw status indicating the IC is providing power to VOUT. 1: Raw status indicating the IC is not providing power to VOUT. | | | |
| 5 | VOUT_OV | R | Current Status | Output Over-Voltage Fault Condition 0: Latched flag indicating no VOUT OV fault has occurred. 1: Latched flag indicating a VOUT OV fault occurred | | | |
| 4 | IOUT_OC | R | Current Status | Output Over-Current Fault Condition 0: Latched flag indicating no IOUT OC fault has occurred. 1: Latched flag indicating an IOUT OC fault has occurred. | | | |
| 3 | VIN_UV | R | Current Status | Input Under-Voltage Fault Condition 0: Latched flag indicating VIN is above the UVLO threshold. 1: Latched flag indicating VIN is below the UVLO threshold. | | | |
| 2 | ТЕМР | R | Current Status | Over-Temperature Fault/Warning 0: Latched flag indicating no OT fault or warning has occurred. 1: Latched flag indicating an OT fault or warning has occurred. | | | |
| 1 | CML | R | Current Status | Communications, Memory or Logic Fault 0: Latched flag indicating no communication, memory, or logic fault has occurred. 1: Latched flag indicating a communication, memory, or logic fault has occurred. | | | |
| 0 | OTHER | R | Current Status | Other Fault (None of the Above) This bit is used to flag faults not covered with the other bit faults. In this case, UVF or OCW faults are examples of other faults not covered by the bits [7:1] in this register. 0: No fault has occurred 1: A fault or warning not listed in bits [7:1] has occurred. | | | |

Per the description in the PMBus 1.3 specification, part II, TPS53681 does support clearing of status bits by writing to STATUS registers. However, the bits in the STATUS_BYTE are summary bits only and reflect the status of corresponding bits in STATUS_VOUT, STATUS_IOUT, etc... To clear these bits individually, the user must clear them by writing to the corresponding STATUS_X register. For example: the output overcurrent fault sets the IOUT_OC bit in STATUS_BYTE, and the IOUT_OC_FLT bit in STATUS_IOUT. Writing a 1 to the IOUT_OC_FLT bit in STATUS_IOUT clears the fault in both STATUS_BYTE and STATUS_IOUT. Writes to STATUS_BYTE itself will be treated as invalid transactions.



7.5.26.2 (79h) STATUS_WORD

The STATUS_WORD command returns two bytes of information with a summary of critical faults, such as overvoltage, overcurrent, over-temperature, etc..

The STATUS_WORD command must be accessed through Read Word transactions. STATUS_WORD is a paged register. In order to access STATUS_WORD command for channel A, PAGE must be set to 00h. In order to access STATUS_WORD register for channel B, PAGE must be set to 01h. If PAGE is set FFh, the device return value will reflect the status of Channel A.

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |
|------|------|---------|---------|--------|------|-------|---------|
| R | R | R | R | R | R | R | R |
| VOUT | IOUT | INPUT | MFR | PGOOD | FANS | OTHER | UNKNOWN |
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R | R | R |
| BUSY | OFF | VOUT_OV | IOUT_OC | VIN_UV | TEMP | CML | OTHER |

Figure 16. STATUS_WORD

Table 70. STATUS_WORD Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|---------|------|-------------------|---|
| 15 | VOUT | R | Current Status | Output Voltage Fault/Warning. Refer to STATUS_VOUT for more information. 0: Latched flag indicating no VOUT fault or warning has occurred. 1: Latched flag indicating a VOUT fault or warning has occurred. |
| 14 | IOUT | R | Current Status | Output Current Fault/Warning. Refer to STATUS_IOUT for more information. 0: Latched flag indicating no IOUT fault or warning has occurred. 1: Latched flag indicating an IOUT fault or warning has occurred. |
| 13 | INPUT | R | Current Status | Input Voltage/Current Fault/Warning. Refer to STATUS_INPUT for more information. 0: Latched flag indicating no VIN or IIN fault or warning has occurred. 1: Latched flag indicating a VIN or IIN fault or warning has occurred. |
| 12 | MFR | R | Current Status | MFR_SPECIFIC Fault. Refer to STATUS_MFR for more information. 0: Latched flag indicating no MFR_SPECIFIC fault has occurred. 1: Latched flag indicating a MFR_SPECIFIC fault has occurred. |
| 11 | PGOOD | R | Current Status | Power Good Status. Note: Per the PMBus specification, the PGOOD bit is not latched, always reflecting the current status of the AVR_RDY/BVR_RDY pin. 0: Raw status indicating AVR_RDY/BVR_RDY pin is at logic high. 1: Raw status indicating AVR_RDY/BVR_RDY pin is at logic low. |
| 10 | FANS | R | 0 | Not supported and always set to 0. |
| 9 | OTHER | R | 0 | Not supported and always set to 0. |
| 8 | UNKNOWN | R | 0 | Not supported and always set to 0. |
| 7 | BUSY | R | 0 | Not supported and always set to 0. |
| 6 | OFF | R | Current Status | This bit is asserted if the unit is not providing power to the output, regardless of the reason, including simply not being enabled. 0: Raw status indicating the IC is providing power to VOUT. 1: Raw status indicating the IC is not providing power to VOUT. |
| 5 | VOUT_OV | R | Current Status | Output Over-Voltage Fault Condition 0: Latched flag indicating no VOUT OV fault has occurred. 1: Latched flag indicating a VOUT OV fault occurred |
| 4 | IOUT_OC | R | Current Status | Output Over-Current Fault Condition 0: Latched flag indicating no IOUT OC fault has occurred. 1: Latched flag indicating an IOUT OC fault has occurred. |



Table 70. STATUS_WORD Register Field Descriptions (continued)

| Bit | Field | Туре | Reset | Description |
|-----|--------|------|-------------------|---|
| 3 | VIN_UV | R | Current Status | Input Under-Voltage Fault Condition 0: Latched flag indicating VIN is above the UVLO threshold. 1: Latched flag indicating VIN is below the UVLO threshold. |
| 2 | TEMP | R | Current Status | Over-Temperature Fault/Warning 0: Latched flag indicating no OT fault or warning has occurred. 1: Latched flag indicating an OT fault or warning has occurred. |
| 1 | CML | R | Current Status | Communications, Memory or Logic Fault 0: Latched flag indicating no communication, memory, or logic fault has occurred. 1: Latched flag indicating a communication, memory, or logic fault has occurred. |
| 0 | OTHER | R | Current Status | Other Fault (None of the Above) This bit is used to flag faults not covered with the other bit faults. In this case, UVF or OCW faults are examples of other faults not covered by the bits [7:1] in this register. 0: No fault has occurred 1: A fault or warning not listed in bits [7:1] has occurred. |

Per the description in the PMBus 1.3 specification, part II, TPS53681 does support clearing of status bits by writing to STATUS registers. However, the bits in the STATUS_WORD are summary bits only and reflect the status of corresponding bits in STATUS_VOUT, STATUS_IOUT, etc... To clear these bits individually, the user must clear them by writing to the corresponding STATUS_X register. For example: the output overcurrent fault sets the IOUT OC bit in STATUS WORD, and the IOUT OC FLT bit in STATUS IOUT. Writing a 1 to the IOUT_OC_FLT bit in STATUS_IOUT clears the fault in both STATUS_WORD and STATUS_IOUT. Writes to STATUS WORD will be treated as invalid transactions.

7.5.26.3 (7Ah) STATUS_VOUT

The STATUS VOUT command returns one byte of information relating to the status of the converter's output voltage related faults.

The STATUS_VOUT command must be accessed through Read Byte/Write Byte transactions. STATUS_VOUT is a paged register. In order to access STATUS_VOUT command for channel A, PAGE must be set to 00h. In order to access STATUS_VOUT register for channel B, PAGE must be set to 01h. If PAGE is set FFh, the device return value will reflect the status of Channel A.

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|----------|----------|----------|------------------|---------|----------|------------|
| RW | 0 | 0 | RW | RW | 0 | 0 | 0 |
| VOUT_OVF | VOUT_OVW | VOUT_UVW | VOUT_UVF | VOUT_MIN_M AX | TON_MAX | TOFF_MAX | VOUT_TRACK |

Figure 17. STATUS_VOUT

Table 71. STATUS VOUT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|----------|------|-------------------|---|
| 7 | VOUT_OVF | RW | Current Status | Output Over-Voltage Fault 0: Latched flag indicating no VOUT OV fault has occurred. 1: Latched flag indicating a VOUT OV fault has occurred. |
| 6 | VOUT_OVW | R | 0 | Not supported and always set to 0. |
| 5 | VOUT_UVW | R | 0 | Not supported and always set to 0. |
| 4 | VOUT_UVF | RW | Current Status | Output Under-Voltage Fault 0: Latched flag indicating no VOUT UV fault has occurred. 1: Latched flag indicating a VOUT UV fault has occurred. |



Table 71. STATUS_VOUT Register Field Descriptions (continued)

| Bit | Field | Туре | Reset | Description |
|-----|--------------|------|-------------------|---|
| 3 | VOUT_MIN_MAX | RW | Current Status | Output Voltage Max/Min Exceeded Warning 0: Latched flag indicating no VOUT_MAX/VOUT_MIN warning has occurred. 1: Latched flag indicating that an attempt has been made to set the output voltage to a value higher than allowed by the VOUT_MAX/VOUT_MIN command. |
| 2 | TON_MAX | R | 0 | Not supported and always set to 0. |
| 1 | TOFF_MAX | R | 0 | Not supported and always set to 0. |
| 0 | VOUT_TRACK | R | 0 | Not supported and always set to 0. |

Per the description in the PMBus 1.3 specification, part II, TPS53681 does support clearing of status bits by writing to STATUS registers. Writing a 1 to any supported bit in this register will attempt to clear it as a fault condition.

7.5.26.4 (7Bh) STATUS_IOUT

The STATUS_IOUT command returns one byte of information relating to the status of the converter's output current related faults.

The STATUS_IOUT command must be accessed through Read Byte/Write Byte transactions. STATUS_IOUT is a paged register. In order to access STATUS_IOUT command for channel A, PAGE must be set to 00h. In order to access STATUS_IOUT register for channel B, PAGE must be set to 01h. If PAGE is set FFh, the device return value will reflect the status of Channel A.

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|------------|----------|----------|------------|-----------|----------|----------|
| RW | 0 | RW | 0 | RW | 0 | 0 | 0 |
| IOUT_OCF | IOUT_OCUVF | IOUT_OCW | IOUT_UCF | CUR_SHAREF | POW_LIMIT | POUT_OPF | POUT_OPW |

Figure 18. STATUS_IOUT

Table 72. STATUS_IOUT Register Field Descriptions

| Bit | Field | Туре | Reset | Description | | | | |
|-----|------------|------|-------------------|---|--|--|--|--|
| 7 | IOUT_OCF | RW | Current Status | Output Over-Current Fault 0: Latched flag indicating no IOUT OC fault has occurred. 1: Latched flag indicating a IOUT OC fault has occurred . | | | | |
| 6 | IOUT_OCUVF | R | 0 | Not supported and always set to 0. | | | | |
| 5 | IOUT_OCW | RW | Current Status | Catched flag indicating no IOUT OC warning has occurred Latched flag indicating a IOUT OC warning has occurred | | | | |
| 4 | IOUT_UCF | R | 0 | Not supported and always set to 0. | | | | |
| 3 | CUR_SHAREF | RW | Current Status | O: Latched flag indicating no current sharing fault has occurred 1: Latched flag indicating a current sharing fault has occurred | | | | |
| 2 | POW_LIMIT | R | 0 | Not supported and always set to 0. | | | | |
| 1 | POUT_OPF | R | 0 | Not supported and always set to 0. | | | | |
| 0 | POUT_OPW | R | 0 | Not supported and always set to 0. | | | | |

Per the description in the PMBus 1.3 specification, part II, TPS53681 does support clearing of status bits by writing to STATUS registers. Writing a 1 to any supported bit in this register will attempt to clear it as a fault condition.

7.5.26.5 (7Ch) STATUS_INPUT

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The STATUS_INPUT command returns one byte of information relating to the status of the converter's input voltage and current related faults.

The STATUS_INPUT command must be accessed through Read Byte/Write Byte transactions. The STATUS_INPUT command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.





| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---------|---------|---------|---------|---------|---------|---------|---------|
| RW | 0 | 0 | RW | RW | RW | RW | RW |
| VIN_OVF | VIN_OVW | VIN_UVW | VIN_UVF | LOW_VIN | IIN_OCF | IIN_OCW | PIN_OPW |

Figure 19. STATUS_INPUT Register

Table 73. STATUS_INPUT Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|---------|------|-------------------|---|
| 7 | VIN_OVF | R | Current Status | Input Over-Voltage Fault 0: Latched flag indicating no VIN OV fault has occurred. 1: Latched flag indicating a VIN OV fault has occurred. |
| 6 | VIN_OVW | R | 0 | Not supported and always set to 0. |
| 5 | VIN_UVW | R | 0 | Not supported and always set to 0. |
| 4 | VIN_UVF | R | Current Status | Input Under-Voltage Fault 0: Latched flag indicating no VIN UV fault has occurred. 1: Latched flag indicating a VIN UV fault has occurred. |
| 3 | LOW_VIN | R | Current Status | Unit Off for insufficient input voltage 0: Latched flag indicating no LOW_VIN fault has occurred. 1: Latched flag indicating a LOW_VIN fault has occurred |
| 2 | IIN_OCF | R | Current Status | Input Over-Current Fault 0: Latched flag indicating no IIN OC fault has occurred. 1: Latched flag indicating a IIN OC fault has occurred. |
| 1 | IIN_OCW | R | Current Status | Input Over-Current Warning 0: Latched flag indicating no IIN OC warning has occurred. 1: Latched flag indicating a IIN OC warning has occurred. |
| 0 | PIN_OPW | R | Current Status | Input Over-Power Warning 0: Latched flag indicating no input over-power warning has occurred. 1: Latched flag indicating a input over-power warning has occurred. |

Per the description in the PMBus 1.3 specification, part II, TPS53681 does support clearing of status bits by writing to STATUS registers. Writing a 1 to any supported bit in this register will attempt to clear it as a fault condition.

7.5.26.6 (7Dh) STATUS_TEMPERATURE

The STATUS TEMPERATURE command returns one byte of information relating to the status of the converter's temperature related faults.

The STATUS_TEMPERATURE command must be accessed through Read Byte/Write Byte transactions. STATUS_TEMPERATURE is a paged register. In order to access STATUS_TEMPERATURE command for channel A, PAGE must be set to 00h. In order to access STATUS_TEMPERATURE register for channel B, PAGE must be set to 01h. If PAGE is set FFh, the device return value will reflect the status of Channel A.

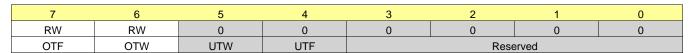


Figure 20. STATUS_TEMPERATURE Register

Table 74. STATUS_TEMPERATURE Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|-------|------|-------------------|--|
| 7 | OTF | RW | Current Status | Over-Temperature Fault 0: (Default) A temperature fault has not occurred. 1: A temperature fault has occurred. |
| 6 | OTW | RW | Current Status | Over-Temperature Warning 0: (Default) A temperature warning has not occurred. 1: A temperature warning has occurred. |

Table 74. STATUS_TEMPERATURE Register Field Descriptions (continued)

| Bit | Field | Туре | Reset | Description |
|-----|----------|------|-------|------------------------------------|
| 5 | UTW | R | 0 | Not supported and always set to 0. |
| 4 | UTF | R | 0 | Not supported and always set to 0. |
| 3-0 | Reserved | R | 0000 | Always set to 0. |

Per the description in the PMBus 1.3 specification, part II, TPS53681 does support clearing of status bits by writing to STATUS registers. Writing a 1 to any supported bit in this register will attempt to clear it as a fault condition.

7.5.26.7 (7Eh) STATUS CML

The STATUS CML command returns one byte with contents regarding communication, logic, or memory conditions.

The STATUS CML command must be accessed through Read Byte/Write Byte transactions. The STATUS CML command is shared between Channel A and Channel B. All transactions to this command will affect both channels regardless of the PAGE command.

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------|---------|----------|-----|-----------|----------|----------|-----------|
| RW | RW | RW | RW | 0 | 0 | RW | 0 |
| IV_CMD | IV_DATA | PEC_FAIL | MEM | PRO_FAULT | Reserved | COM_FAIL | CML_OTHER |

Figure 21. STATUS_CML Register

Table 75. STATUS_CML Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|-----|-----------|------|-------------------|---|
| DIT | rieid | Туре | Reset | Description |
| 7 | IV_CMD | RW | Current Status | Invalid or Unsupported Command Received 0: Latched flag indicating no invalid or unsupported command has been received. 1: Latched flag indicating an invalid or unsupported command has been received. |
| 6 | IV_DATA | RW | Current Status | Invalid or Unsupported Data Received 0: Latched flag indicating no invalid or unsupported data has been received. 1: Latched flag indicating an invalid or unsupported data has been received. |
| 5 | PEC_FAIL | RW | Current Status | Packet Error Check Failed 0: Latched flag indicating no packet error check has failed 1: Latched flag indicating a packet error check has failed |
| 4 | Reserved | R | 0 | Always set to 0. |
| 3 | MEM | RW | Current Status | Memory/NVM Error 0: Latched flag indicating no memory error has occurred 1: Latched flag indicating a memory error has occurred |
| 2 | Reserved | R | 0 | Always set to 0. |
| 1 | COM_FAIL | RW | Current Status | Other Communication Faults 0: Latched flag indicating no communication fault other than the ones listed in this table has occurred. 1: Latched flag indicating a communication fault other than the ones listed in this table has occurred. |
| 0 | CML_OTHER | R | 0 | Not supported and always set to 0. |

Per the description in the PMBus 1.3 specification, part II, TPS53681 does support clearing of status bits by writing to STATUS registers. Writing a 1 to any bit in this register will attempt to clear it as a fault condition.

7.5.26.8 (80h) STATUS MFR SPECIFIC

The STATUS MFR SPECIFIC command returns one byte containing manufacturer-defined faults or warnings.

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The STATUS_MFR_SPECIFIC command must be accessed through Read Byte/Write Byte transactions. STATUS_MFR_SPECIFIC is a paged register. In order to access STATUS_MFR_SPECIFIC command for

channel A, PAGE must be set to 00h. In order to access STATUS_MFR_SPECIFIC register for channel B, PAGE must be set to 01h. If PAGE is set FFh, the device return value will reflect the status of Channel A.

Figure 22. STATUS_MFR_SPECIFIC Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------|-----------|-----------------|----------|---------------------|------|-------|-------|
| RW | RW | RW | RW | RW | 0 | 0 | RW |
| FLT_PS | VSNS_OPEN | MAX_PH_WAR N | TSNS_LOW | RST_VID (Page 0) | Rese | erved | PHFLT |

Table 76. STATUS_MFR_SPECIFIC Register Field Descriptions

| Bit | Field | Туре | Reset | Description |
|-----|------------------|------|-------------------|--|
| 7 | MFR_FAULT_PS | RW | Current Status | Power Stage Fault 0b: Latched flag indicating no fault from TI power stage has occurred. 1b: Latched flag indicating a fault from TI power stage has occurred. |
| 6 | VSNS_OPEN | RW | Current Status | VSNS pin open 0b: Latched flag indicating VSNS pin was not open at power-up. 1b: Latched flag indicating VSNS pin was open at power-up. |
| 5 | MAX_PH_WARN | RW | Current Status | Maximum Phase Warning If the selected operational phase number is larger than the maximum available phase number specified by the hardware, then MAX_PH_WARN is set, and the operational phase number is changed to the maximum available phase number. Ob: Latched flag indicating no maximum phase warning has occurred. 1b: Latched flag indicating a maximum phase warning has occurred. |
| 4 | TSNS_LOW | RW | Current Status | 0b: Latched flag indicating that TSEN < 150 mV before soft- start. 1b: Latched flag indicating that TSEN ≥ 150 mV before soft-start. |
| 3 | RST_VID (Page 0) | RW | Current Status | RST_VID (Page 0 only) 0b: A VID reset operation has NOT occurred 1b: A VID reset operation has occurred |
| 2:1 | Reserved | R | 00b | Always set to 0. |
| 0 | PHFLT | RW | Current Status | Phase current share fault. The PHFLT bit is set if any phase has current imbalance warnings occurring repetitively for 7 detection cycles (-500 µs continuously). Phases with current imbalance warnings may be read back via MFR_SPECIFIC_03. 0b: No repetitive current share fault has occurred 1b: Repetitive current share fault has occurred |

Per the description in the PMBus 1.3 specification, part II, TPS53681 does support clearing of status bits by writing to STATUS registers. Writing a 1 to any supported bit in this register will attempt to clear it as a fault condition.



8 Applications, Implementation, and Layout

NOTE

Information in the following Applications section is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS53681 device has a very simple design procedure. All programmable parameters can be configured by PMBus and stored in NVM as the new default values to minimize external component count. This design describes a typical 6-phase, 0.9-V, 300-A application and 2-phase 0.8-V, 90-A application.

8.2 Typical Application

8.2.1 6-phase, 0.9-V, 300-A Application and 2-phase 0.8-V, 90-A Application

8.2.1.1 Schematic

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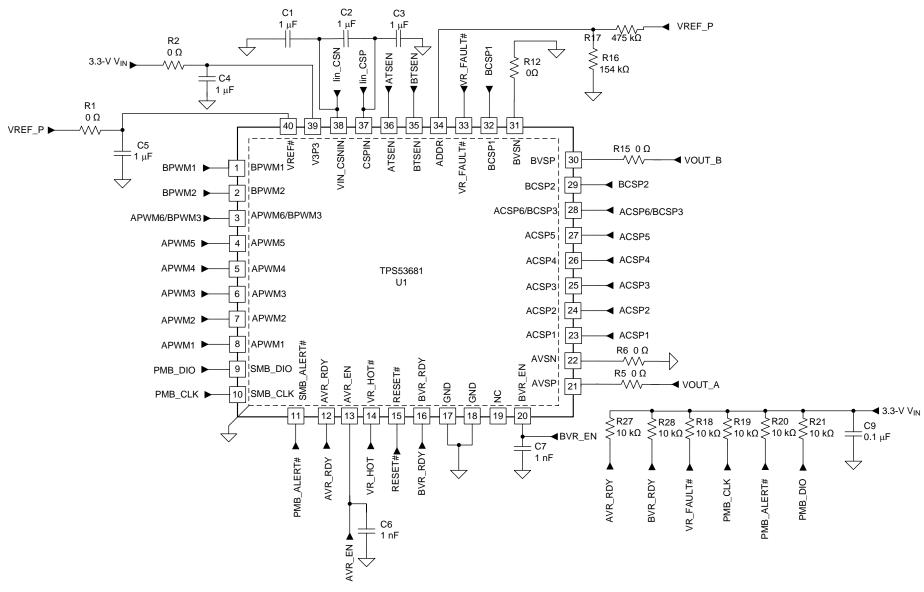


Figure 23. 6-Phase + 2-Phase Application

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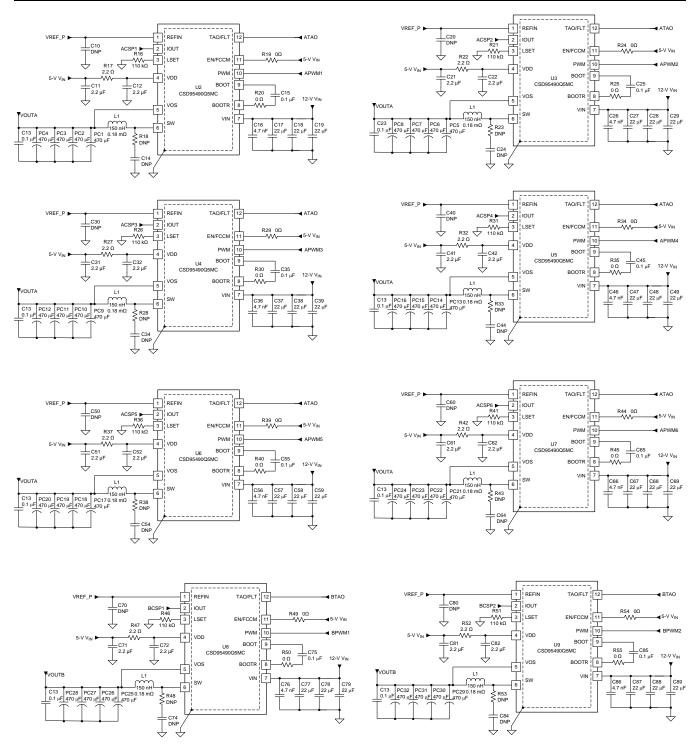


Figure 24. Power Stage

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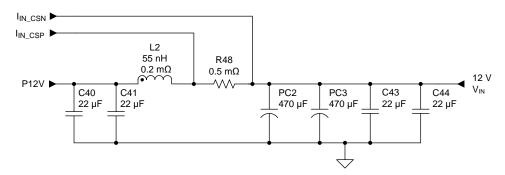


Figure 25. 12-V Input Filter

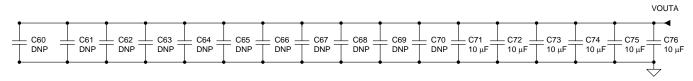


Figure 26. VOUTA Filter for a 6-Phase Application

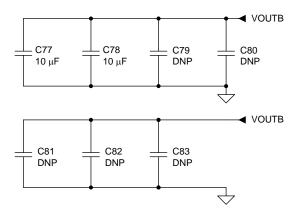


Figure 27. VOUTB Filter for a 2-Phase Application

8.2.1.2 Design Requirements

Table 77. Target Application Specifications

| | VOUTA | VOUTB | | |
|---------------------------------------|-----------------|----------|--|--|
| Number of phases | 6 | 2 | | |
| Input voltage range | 10.8 V – 13.2 V | | | |
| Output voltage | 0.9 V | 0.8 V | | |
| I _{OUT} | 300 A | 90 A | | |
| I _{DYN(max)} | 150 A | 45 A | | |
| Load-line | 0 mΩ | 0 mΩ | | |
| Fast slew rate (min) | 10 m | 10 mV/μs | | |
| Boot voltage, V _{BOOT} | 0.9 V | 0.8 V | | |
| Maximum temperature, T _{MAX} | 90°C | | | |
| PMBus Address | 1100000 (C0h) | | | |
| Switching frequeny (f _{SW}) | 500 kHz | | | |

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8.2.1.3 Detailed Design Procedure

For this design, the default setting inside controller is the optimal for the application. However, the following steps illustrate how to configure and fine-tune via PMBus and stored in NVM as the new default setting.

8.2.1.3.1 Choose Inductor

Smaller inductance values yield better transient performance, but also have a higher ripple and lower efficiency. Higher inductance values have the opposite characteristics. It is common practice to limit the ripple current to between 30% and 45% of the maximum per-phase current. In this design example, 30% of the maximum per-phase current is used.

$$I_{P-P} = \frac{I_{OUT}}{n} \times 30\% = \frac{300 \text{ A}}{6} \times 0.3 = 15 \text{ A}$$
 (4)

$$L \approx \frac{V_{\rm IN\,(max)} - V_{\rm OUT}}{I_{\rm P-P}} \times \frac{V_{\rm OUT}}{V_{\rm IN\,(max)}} \times \frac{1}{f_{\rm SW}} = \frac{13.2 \text{ V} - 0.9 \text{ V}}{15 \text{ A}} \times \frac{0.9 \text{ V}}{13.2 \text{ V}} \times \frac{1}{500 \text{ kHz}} = 0.112 \text{ }\mu\text{H} \tag{5}$$

A standard inductor value of 150 nH with 0.18 m Ω DCR is chosen. With the same design procedure, the inductor value for the Rail B (V_{OUTB}) of 150 nH is chosen.

8.2.1.3.2 Select the Per-Phase Valley Current Limit

Equation 6 shows the calculation of the per-phase, valley current limit based on the maximum processor current, the operating phase number and the per-phase current ripple I_{P-P}.

$$I_{OCL} = \left(k \times \frac{I_{OUT}}{n}\right) - \left(\frac{I_{P-P}}{2}\right) = 150\% \times \frac{300 \text{ A}}{6} - \left(\frac{15 \text{ A}}{2}\right) = 67.5 \text{A}$$

where

- · k is the maximum operating margin
- I_{OUT} is the maximum processor current
- I_{P-P} is the ripple current
- n is the number of phases (6)

The factor k of 150% is used to avoid reaching current limits during transients. For this design, a 70-A valley current limit is selected in PMBus GUI.

$$I_{SAT} = I_{OCL} + I_{P-P} = 70 \text{ A} + 15 \text{ A} = 85 \text{ A}$$
 (7)

Equation 7 indicates that the maximum saturation current for the inductor needs to be higher than 85 A. Using the same design procedure, the valley current limit for VCCSA is selected to be 80 A.

8.2.1.3.3 Set the Maximum Temperature Level (T_{MAX})

For this design, T_{MAX} is selected as 90°C. The temperature is sensed by the ATSENand BTSEN pins through its connection to the xTAO pins of each phase of the CSD95490Q5MC. The controller reports the highest temperature sensed by power stages of Rail A and Rail B.

8.2.1.3.4 Set USR Thresholds to Improve Load Transient Performance

There are two levels of undershoot reduction protection (USR) (USR1/USR2) selection. USR1 enables up to 3 or 4 phases and USR2 enables up to the maximum number of phases. The initial setting of the USR threshold is to start with USR1 and USR2 as OFF, and then to meet the load insertion transient requirement by lowering the threshold to enable pulse-overlap during the load transients.

For this design, VOUTA USR1 is selected as 240 mV and USR2 is selected as 300 mV. VOUTB USR1 and USR2 are selected as OFF.

8.2.1.4 Inductor DCR and Shunt Current Sensing Design for Input Power

This section describes designing the thermal compensation network. The NTC thermistor is used to compensate thermal variations in the resistance of the inductor winding. The winding is usually copper. And as such has a resistance coefficient of 3900 PPM/°C. Alternatively, the NTC thermistor characteristic is very non-linear and requires two or three resistors to linearize them over the range of interest. Figure 28 shows a typical DCR circuit.



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V_{IN} R_{DCR} To load

R_{SEQU} R_{NTC} R_{SERIES}

R_{PAR}

C_{SENSE}

Figure 28. Typical DCR Current Sensing Circuit

Equation 8 calculates the voltage across the C_{SENSE} capacitor when it exactly equals the voltage across R_{DCR}.

$$C_{SENSE} \times R_{EQ} = \frac{L}{R_{DCR}}$$

where

$$R_{EQ} = \frac{R_{P_N} \times R_{SEQU}}{R_{P_N} + R_{SEQU}}$$
(9)

$$R_{P_{-N}} = \frac{R_{PAR} \times (R_{NTC} + R_{SERIES})}{R_{PAR} + R_{NTC} + R_{SERIES}}$$
(10)

Ensure that C_{SENSE} is a capacitor type which is stable over temperature, use X7R or better dielectric (C0G preferred). Because calculating these values by hand can be time-consuming, TI offers a spreadsheet using the Excel Solver function available to provide calculation assistance. Contact your local TI representative to get a copy of the spreadsheet.

This example uses a simple design process to enable input shunt sensing, so no DCR network is needed. Insert a 0.5-m Ω shunt resistor in series between the input inductor and the input bulk capacitors.

8.2.1.4.1 Compensation Design

Figure 29 shows the compensation block diagram of the DCAP+ architecture.

I_{IN_CSN}

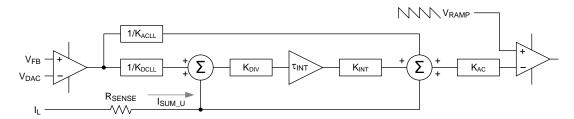


Figure 29. DCAP+ Compensation Block Diagram

- R_{SENSE}: typical 5 mΩ which is gain from power stage
- K_{DCLL}: DC load line which is adjustable from 0 mΩ to 3.125 mΩ
- K_{ACLL}: AC load line which is adjustable from 0.5 mΩ to 3.125 mΩ
- K_{DIV}: not be adjustable. Changing DCLL, this parameter changes automatically
- τ_{INT} : Integrator time constant which is adjustable from 01 μs to 08 μs (scale = 1 μs) and from 10 μs to 40 μs (scale = 5 μs)
- K_{INT}: Integrator time gain which can be adjustable from 0.5x, 0.66x, 1x, 2x
- K_{AC}: AC gain which is adjustable from 0.5x, 1x, 1.5x, 2x

For this design, Table 78 lists the default values that are preset into the PMBus GUI.

| Table 78. | . PMBus GU | l Default | Values |
|-----------|------------|-----------|--------|
|-----------|------------|-----------|--------|

| | VOUTA | VOUTB | | |
|----------|--------|-------|--|--|
| AC_gain | 2x | | | |
| AC_LL | 0.5 mΩ | | | |
| INT_Time | 01 µs | 10 µs | | |
| INTGAIN | 2× | | | |

8.2.1.4.2 Set PMBus Addresses

To communicate with other system controllers with the PMBus interfaces, use the values of R16 and R17 resistors to set the PMBus address.

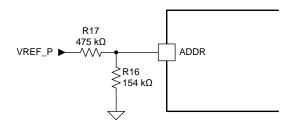


Figure 30. PMBus Address Setting

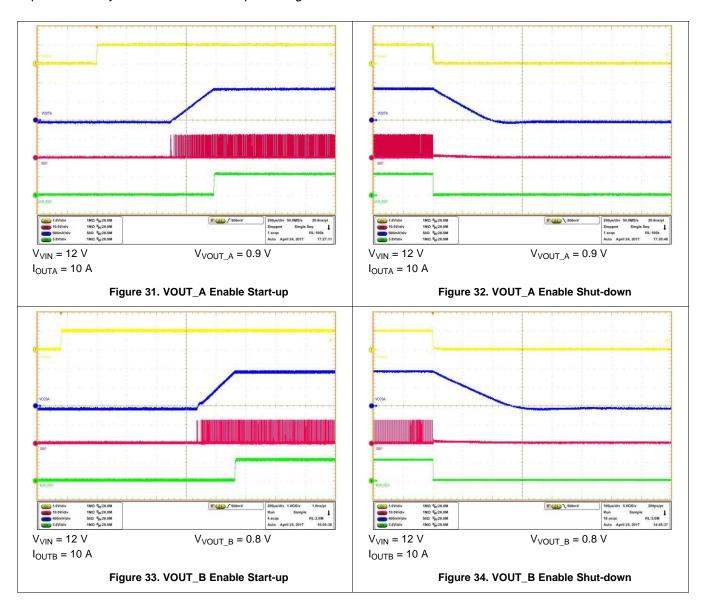
Contact your local Texas Instruments representative for a copy of PMBus address setting design tool spreadsheet.



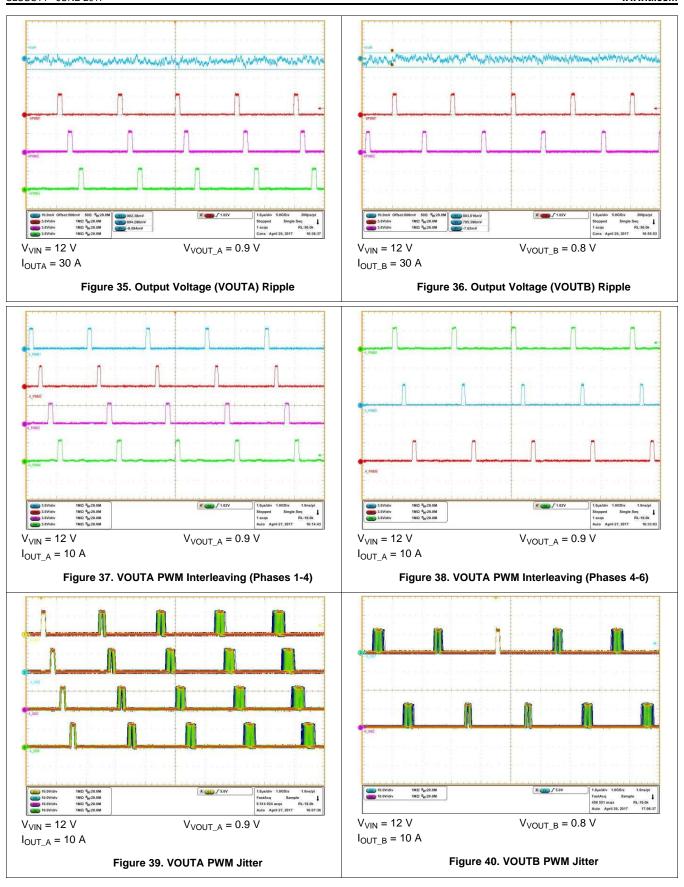
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8.2.1.5 Application Performance Plots

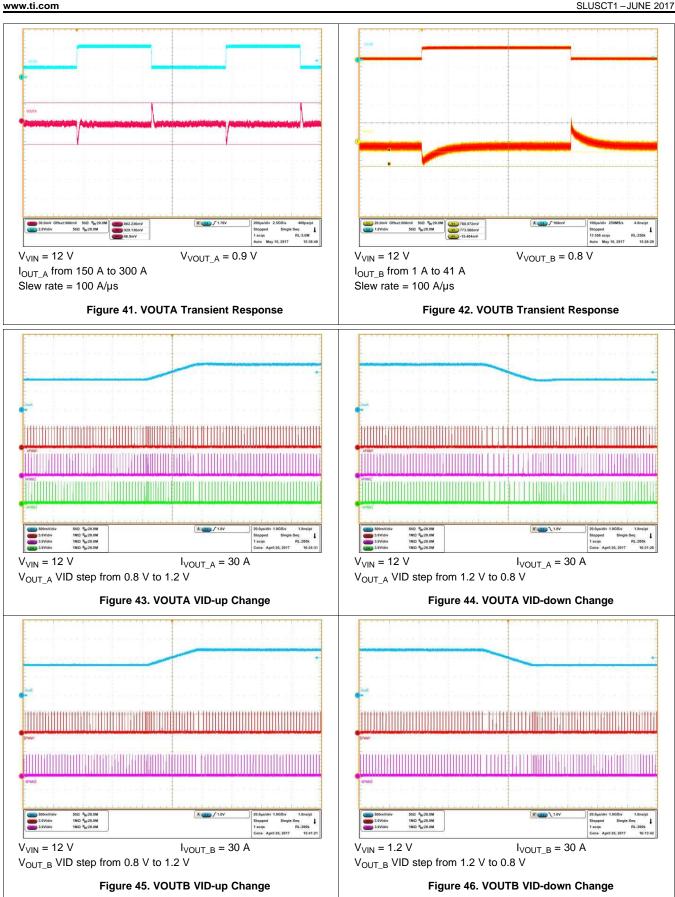
For this design, choose 500 kHz for the switching frequency. The frequency is an approximate frequency and is expected to vary based on load and input voltage.



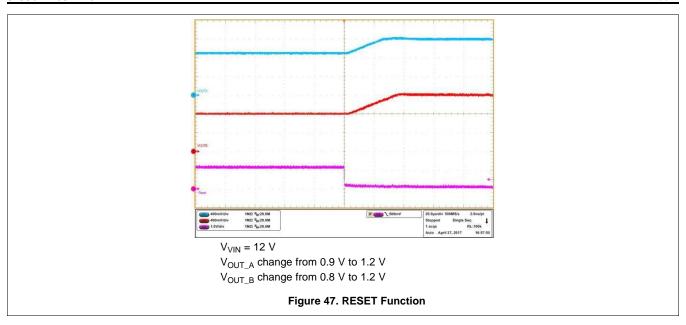


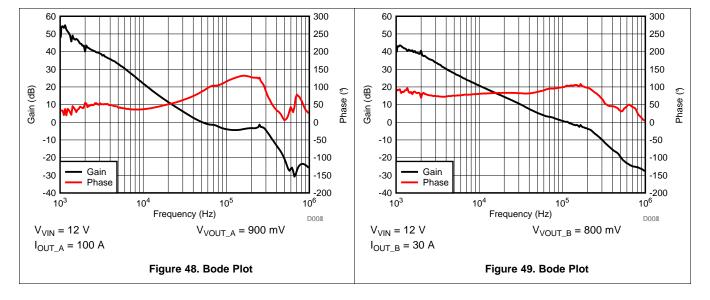














9 Power Supply Recommendations

The TPS53681 device operates from 3.3-V supply at the V3P3 pin (pin 39) and the 12-V supply from the VIN_CSNIN pin (pin 38). TI recommends the following power-up and power-down sequence in order for the controller to monitor the complete power-up and power-down procedure, fault protection and fault recording. The device provides pre-start up overvoltage protection when the controller and the power stage are enabled before the 12-V input is applied.

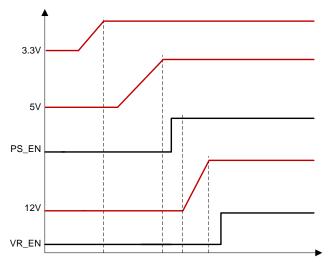


Figure 50. StartUp Waveforms

The recommended power-up sequence is:

- 1. 3.3 V
- 2. 5 V
- 3. PS_EN
- 4. 12 V
- 5. VR EN

The recommended power-down sequence is:

- 1. VR_EN
- 2. 12 V
- 3. PS_EN
- 4. 5 V
- 5. 3.3 V

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10 Layout

10.1 Layout Guidelines

Contact your local TI representative to get a copy of the schematic and PCB layout guide.

10.1.1 Device Guidelines

The TPS53681 device makes it easy to separate noisy driver interface lines from sensitive interface lines. Because the power stage is external to the device, all gate-drive and switch-node traces must be local to the inductor and power stages.

The device does not require special care in the layout of power chain components, because independent isolated current feedback is provided. Route the phases as symmetrically as possible. Current feedback from each phase must be free of noise and have equal amounts of effective current sense resistance.

MOST IMPORTANT LAYOUT SUGGESTION

Separate noisy driver interface lines from sensitive analog and PMBus interface lines.

10.1.2 Power Stage Guidelines

- Use the recommended land pattern including the via pattern for the power stage footprint.
- The input voltage bypass capacitors require a minimum of two vias per pad (for both VIN and GND).
- Place additional GND vias along the sides of the device as space allows.
- For multi-phase systems, ensure that the GND pour connects all phases.
- The VOS pin feedback point begins at the inner edge of the inductor output voltage pad.
- Place the VDD and PVDD bypass capacitors directly next to pins on the top layer of the board.



10.2 Layout Examples

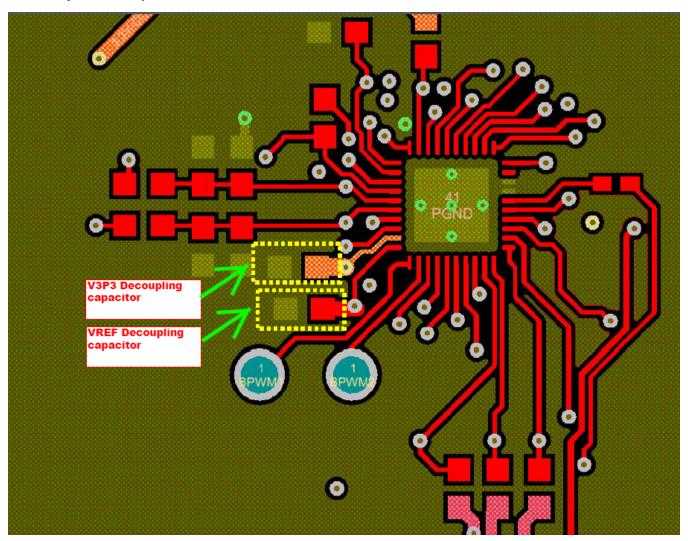


Figure 51. Controller Layout Example

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Layout Examples (continued)

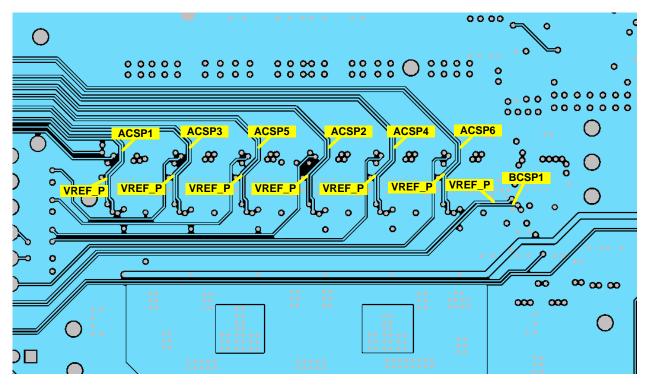


Figure 52. Power Stage Current Sense Differential Pairs Layout Example



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11 Device and Documentation Support

11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.2 Community Resources

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11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGE OPTION ADDENDUM

23-Jun-2017

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|---------|--------------|---------|------|---------|----------|------------------|---------------|--------------|----------------|---------|
| | (1) | | Drawing | | Qty | (2) | (6) | (3) | | (4/5) | |
| TPS53681RSBR | PREVIEW | WQFN | RSB | 40 | 3000 | TBD | Call TI | Call TI | -40 to 125 | | |
| TPS53681RSBT | PREVIEW | WQFN | RSB | 40 | 250 | TBD | Call TI | Call TI | -40 to 125 | | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

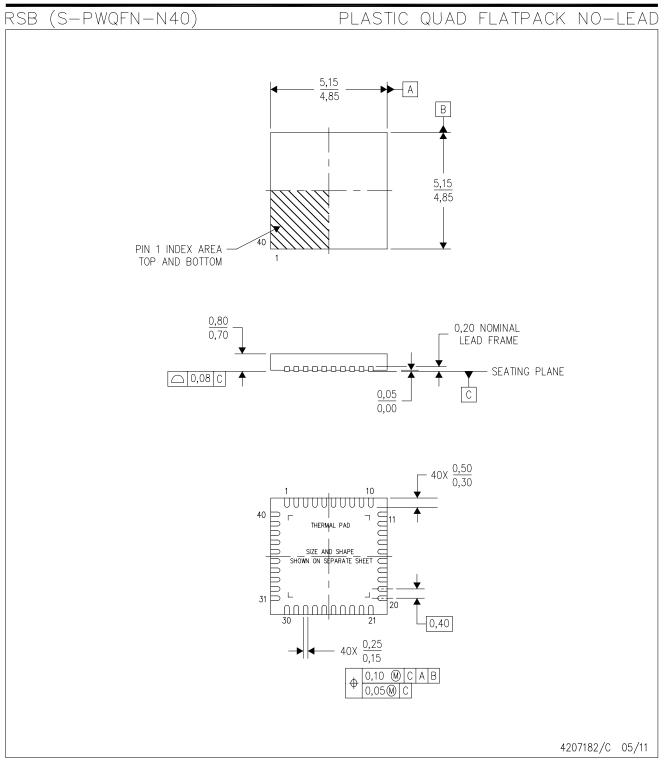
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) Package configuration.
 - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.



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